

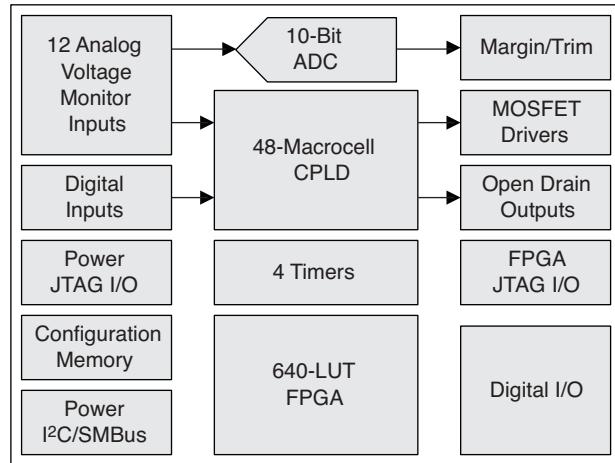
February 2012

Data Sheet DS1036

Features

- **Precision Voltage Monitoring Increases Reliability**
 - 12 independent analog monitor inputs
 - Differential inputs for remote ground sense
 - Two programmable threshold comparators per analog input
 - Hardware window comparison
 - 10-bit ADC for I²C monitoring
- **High-Voltage FET Drivers Enable Integration**
 - Power supply ramp up/down control
 - Programmable current and voltage output
 - Independently configurable for FET control or digital output
- **Power Supply Margin and Trim Functions**
 - Trim and margin up to eight power supplies
 - Dynamic voltage control through I²C
 - Independent Digital Closed-Loop Trim function for each output
- **Programmable Timers Increase Control Flexibility**
 - Four independent timers
 - 32 µs to 2 second intervals for timing sequences
- **PLD Resources Integrate Power and Digital Functions**
 - 48-macrocell CPLD
 - 640 LUT4s FPGA
 - Up to 107 digital I/Os
 - Up to 6.1 Kbits distributed RAM
- **Programmable sysIO™ Buffer Supports a Range of Interfaces**
 - LVCMOS 3.3/2.5/1.8/1.5/1.2
 - LVTTL
- **System-Level Support**
 - Single 3.3V supply operation
 - Industrial temperature range: -40°C to +85°C
- **In-System Programmability Reduces Risk**
 - Integrated non-volatile configuration memory
 - JTAG programming interface
- **Package Options**
 - 128-pin TQFP
 - 208-ball ftBGA
 - RoHS compliant and halogen-free

Block Diagram



Description

The Lattice Platform Manager integrates board power management (hot-swap, sequencing, monitoring, reset generation, trimming and margining) and digital board management functions (reset tree, non-volatile error logging, glue logic, board digital signal monitoring and control, system bus interface, etc.) into a single integrated solution.

The Platform Manager device provides 12 independent analog input channels to monitor up to 12 power supply test points. Up to 12 of these input channels can be monitored through differential inputs to support remote ground sensing. Each of the analog input channels is monitored through two independently programmable comparators to support both high/low and in-bounds/out-of-bounds (window-compare) monitor functions. Up to six general purpose 5V tolerant digital inputs are also provided for miscellaneous control functions.

There are 16 open-drain digital outputs that can be used for controlling DC-DC converters, low-drop-out regulators (LDOs) and opto-couplers, as well as for supervisory and general purpose logic interface functions. Four of these outputs (HVOOUT1-HVOOUT4) may be configured as high-voltage MOSFET drivers. In high-voltage mode these outputs can provide up to 12V for driving the gates of n-channel MOSFETs so that they can be used as high-side power switches controlling the supplies with a programmable ramp rate for both ramp up and ramp down.

The board power management function can be implemented using an internal 48-macrocell CPLD. The status of all of the comparators on the analog input channels as well as the general purpose digital inputs are used as inputs by the CPLD array, and all digital outputs (open-drain as well as HVOOUT) may be controlled by the CPLD.

Four independently programmable timers can create delays and time-outs ranging from 32 µs to 2 seconds.

The Platform Manager device incorporates up to eight DACs for generating trimming voltage to control the output voltage of a DC-DC converter. Additionally, each power supply output voltage can be maintained typically within 0.5% tolerance across various load conditions using the Digital Closed Loop Control mode.

The internal 10-bit A/D converter can both be used to monitor the VMON voltage through the I²C bus as well as for implementing digital closed loop mode for maintaining the output voltage of all power supplies controlled by the monitoring and trimming section of the Platform Manager device.

The FPGA section of the Platform Manager is optimized to meet the requirements of board management functions including reset distribution, boundary scan management, fault logging, FPGA load control, and system bus interface. The FPGA section uses look-up tables (LUTs) and distributed memories for flexible and efficient logic implementation. This instant-on capability enables the Platform Manager devices to integrate control functions that are required as soon as power is applied to the board.

Power management functions can be integrated into the CPLD and digital board management functions can be integrated into the FPGA using the LogiBuilder tool provided by PAC-Designer® software. In addition, the FPGA designs can also be implemented in VHDL or Verilog HDL through the isPLEVER® software design tool.

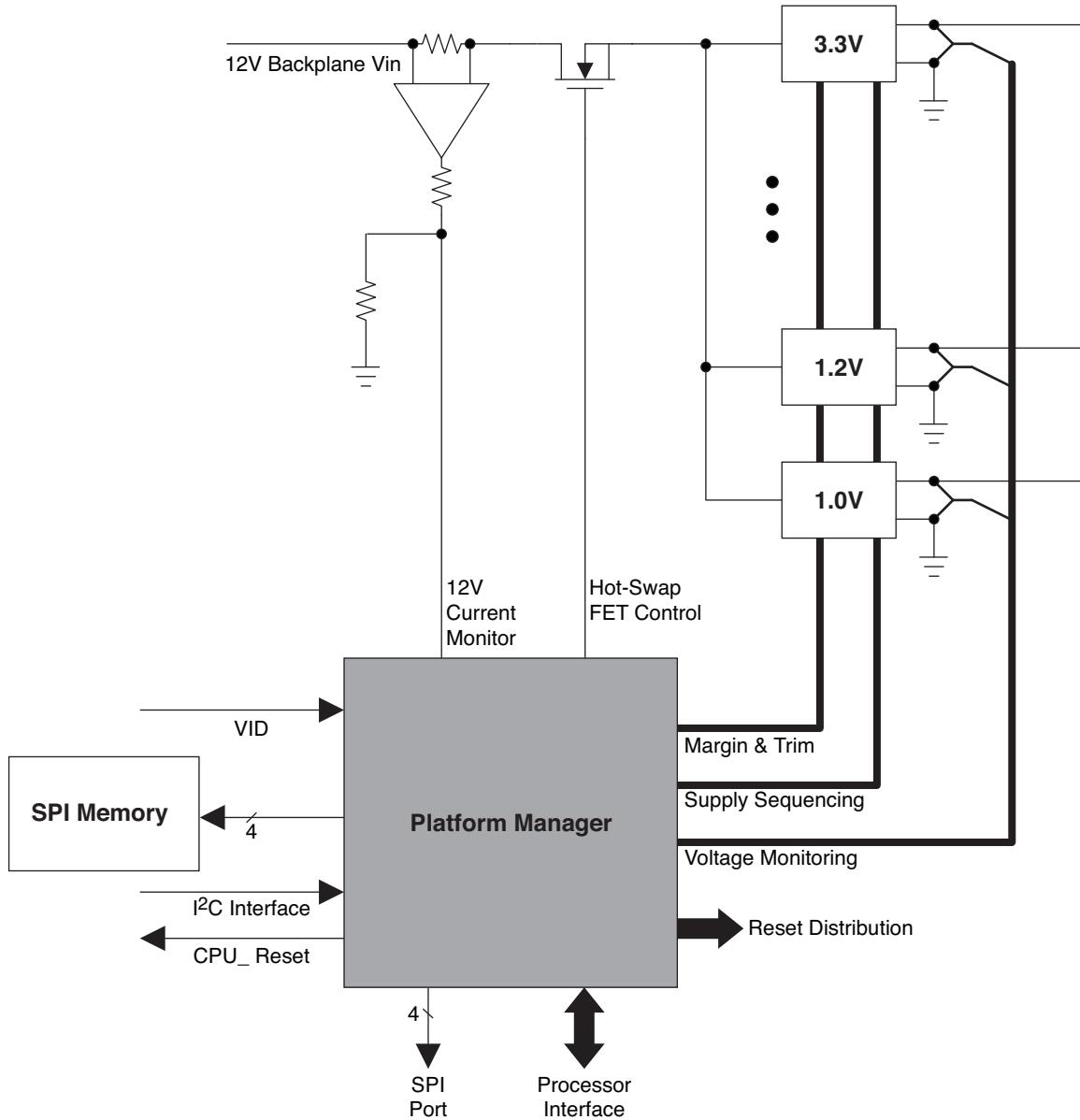
The Platform Manager IC supports a hardware I²C/SMBus slave interface that can be used to measure voltages through the Analog to Digital Converter or is used for trimming and margining using a microcontroller.

There are two JTAG ports integrated into the Platform Manager device: Power JTAG and FPGA JTAG. The Power JTAG interface is used to program the power section of the Platform Manager and the FPGA JTAG is used to configure the FPGA portion of the device. The FPGA configuration memory can be changed in-system without interrupting the operation of the board management section. However, the Power Management section of the platform Manager cannot be changed without interrupting the power management operation.

Table 1. Platform Manager Family Selection Table

Parameter	LPTM10-1247	LPTM10-12107
Analog Inputs	12	12
Margin and Trim	6	8
Total I/O	47	107
CPLD Macrocells	48	48
FPGA LUTs	640	640
Package	128-pin TQFP	208-ball ftBGA

Figure 1. Typical Platform Manager Application



Note: See reference design, IP documentation and application notes for more information on implementation of individual functions called out above.

Absolute Maximum Ratings^{1, 2, 3}

Power Management Core Supply PvCCD	-0.5 to 4.5V
Power Management Analog Supply PvCCA	-0.5 to 4.5V
Power Management Digital Input Supply PvCCA (IN[1:4]) PvCCINP	-0.5 to 6V
Power Management JTAG Logic Supply PvCCJ	-0.5 to 6V
Power Management Alternate E ² programming supply APS ⁴	-0.5 to 4V
Power Management Digital Input Voltage (All Digital I/O Pins) V _{IN}	-0.5 to 6V
VMON Input Voltage	-0.5 to 6V
VMON Input Voltage Ground Sense	-0.5 to 6V
Voltage Applied to Power Management Tri-stated Pins (HVOUT[1:4])	-0.5 to 13.3V
Voltage Applied to Power Management Tri-stated Pins (OUT[5:16])	-0.5 to 6V
Maximum Sink Current on Any Power Management Output23 mA
FPGA Supply Voltage V _{CC}	-0.5 to 3.75V
FPGA Supply Voltage V _{CCAUX}	-0.5 to 3.75V
FPGA Output Supply Voltage V _{CCIO}	-0.5 to 3.75V
FPGA I/O Tri-state Voltage Applied ⁵	-0.5 to 3.75V
FPGA Dedicated Input Voltage Applied ⁵	-0.5 to 4.25V
Device Storage Temperature	-65 to +150°C
Junction Temperature T _J	+125°C

1. Stress above those listed under the "Absolute Maximum Ratings" may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.
2. Compliance with the Lattice Thermal Management document is required.
3. All voltages referenced to GND (FPGA section) or GNDA/D (Power sections).
4. The APS pin MUST be left floating when PVCCD and PVCCA are powered.
5. Overshoot and undershoot of -2V to (V_{IHMAX} + 2) volts is permitted for a duration of <20 ns.

Recommended Operating Conditions

Symbol	Parameter	Conditions	Min.	Max.	Units
P _{VCCD} , P _{VCCA} ¹	Core supply voltage at pin		2.8	3.96	V
P _{VCCINP}	Digital input supply for IN[1:4] at pin		2.25	5.5	V
P _{VCCJ}	JTAG logic supply voltage at pin		2.25	3.6	V
APS	Alternate E ² programming supply at pin	P _{VCCD} and P _{VCCA} powered	No Connect Must Be Left Floating		
		P _{VCCD} and P _{VCCA} not powered	3.0	3.6	V
V _{IN}	Input voltage at digital input pins		-0.3	5.5	V
V _{MON}	Input voltage at V _{MON} pins		-0.3	5.9	V
V _{MONGS}	Input voltage at V _{MONGS} pins		-0.2	0.3	V
V _{OUT}	Open-drain output voltage	OUT[5:16] pins	-0.3	5.5	V
		HVOUT[1:4] pins in open-drain mode	-0.3	13.0	V
V _{CC} ²	FPGA Core Supply Voltage		3.135	3.465	V
V _{CCAUX} ²	FPGA Auxiliary Supply Voltage		3.135	3.465	V
V _{CCIO} ³	FPGA I/O Driver Supply Voltage	V _{CCIO0} , V _{CCIO1} , V _{CCIO3}	1.14	3.465	V
		V _{CCIO2}	2.25	3.6	V
t _{TJCOM}	Junction Temperature Commercial Operation	Power applied	0	+85	°C
t _{TJIND}	Junction Temperature Industrial Operation	Power applied	-40	+100	°C
t _{TFLASHCOM}	Junction Temperature, Flash Programming, Commercial		0	+85	°C
t _{TFLASHIND}	Junction Temperature, Flash Programming, Industrial		-40	+100	°C

1. P_{VCCD} and P_{VCCA} must always be tied together.

2. V_{CC} and V_{CCAUX} must always be tied together. Also, like power supplies must be tied together. For example, if V_{CCIO} and V_{CC} are both 3.3V, they must also be the same supply.

3. See recommended voltages by I/O standard in subsequent table.

Digital I/O Hot Socketing Specifications^{1, 2, 3}

Symbol	Parameter	Condition	Min.	Typ.	Max	Units
I _{DK}	Input or I/O leakage Current	0 ≤ V _{IN} ≤ V _{IH} (MAX)	—	—	+/-1000	µA

1. Assumes monotonic rise/fall rates for V_{CC}, V_{CCAUX}, and V_{CCIO}.

2. 0 ≤ V_{CC} ≤ V_{CC} (MAX), 0 ≤ V_{CCIO} ≤ V_{CCIO} (MAX) and 0 ≤ V_{CCAUX} ≤ V_{CCAUX} (MAX).

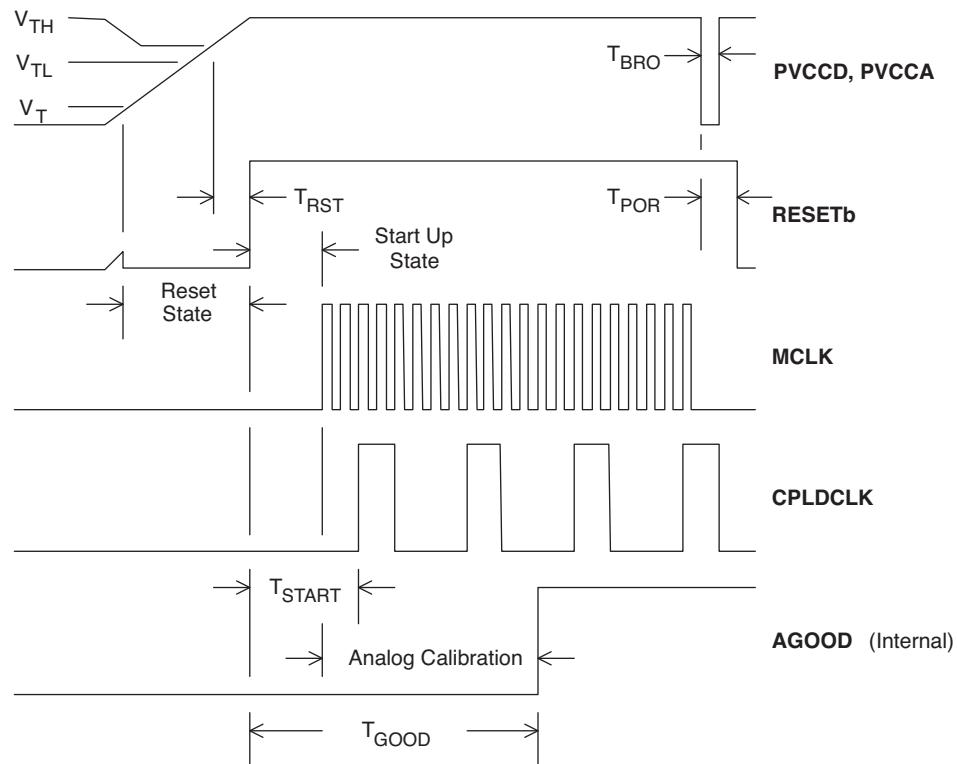
3. I_{DK} is additive to I_{PU}, I_{PD} or I_{BH}.

Power-On Reset – Power Management Section

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
T_{RST}	Delay from V_{TH} to start-up state				100	μs
T_{START}	Delay from RESETb HIGH to CPLDCLK rising edge			5	10	μs
T_{GOOD}	Power-on reset to valid VMON comparator output and AGOOD is true				2.5	ms
T_{BRO}	Minimum duration brown out required to trigger RESETb		1		5	μs
T_{POR}	Delay from brown out to reset state.				13	μs
V_{TL}	Threshold below which RESETb is LOW ¹				2.3	V
V_{TH}	Threshold above which RESETb is HIGH ¹		2.7			V
V_T	Threshold above which RESETb is valid ¹		0.8			V
C_L	Capacitive load on RESETb for master/slave operation				200	pF

1. Corresponds to PVCCA and PVCCD supply voltages.

Figure 2. Power Management Section Power-On Reset



ESD Performance

Pin Group	ESD Stress	Min.	Units
All pins	HBM	1500	V
	CDM	1000	V

DC Electrical Characteristics^{1, 2, 3, 4}

Symbol	Parameter	Conditions	Typ. ⁵	Max.	Units
P _{ICC}	Power Management section supply current	Normal operation		40	mA
P _{ICCPNP}	Power Management section supply current	Normal operation		5	mA
P _{ICCPJ}	Power Management section supply current	Normal operation		1	mA
I _{CC} ¹	FPGA Core Power Supply		8.7		mA
I _{CCAUX}	FPGA Auxiliary Power Supply V _{CCAUX} = 3.3V	During initialization (0MHz)	7		mA
I _{CCIO}	FPGA Bank Power Supply ⁶	During initialization (0MHz)	2.4		mA

1. For further information on FPGA section supply current, please see details of additional technical documentation at the end of this data sheet.
2. Assumes all FPGA section I/O pins are held at V_{CCIO} or GND.
3. FPGA Frequency = 0 MHz.
4. Typical FPGA user pattern.
5. T_J = 25°C, power supplies at nominal voltage.
6. Per bank, V_{CCIO} = 2.5V. Does not include pull-up/pull-down.

FPGA Supply Current (Sleep Mode)^{1, 2}

Symbol	Parameter	Conditions	Typ. ³	Max.	Units
I _{CC} ¹	FPGA Core Power Supply	Sleep Mode	12	25	µA
I _{CCAUX}	FPGA Auxiliary Power Supply		1	25	µA
I _{CCIO}	Bank Power Supply ⁴		2	30	µA

1. Assumes all inputs are configured as LVCMOS and held at the VCCIO or GND.
2. Frequency = 0MHz.
3. T_A = 25°C, power supplies at nominal voltage.
4. Per bank.

DC Electrical Characteristics – FPGA General Purpose I/O

Over Recommended Operating Conditions

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
$I_{IL}, I_{IH}^{1,4}$	Input or I/O Leakage	$0 \leq V_{IN} \leq (V_{CCIO} - 0.2V)$	—	—	10	μA
		$(V_{CCIO} - 0.2V) < V_{IN} \leq 3.6V$	—	—	40	μA
I_{PU}	I/O Active Pull-up Current	$0 \leq V_{IN} \leq 0.7 V_{CCIO}$	-30	—	-150	μA
I_{PD}	I/O Active Pull-down Current	$V_{IL} (\text{MAX}) \leq V_{IN} \leq V_{IH} (\text{MAX})$	30	—	150	μA
I_{BHLS}	Bus Hold Low sustaining current	$V_{IN} = V_{IL} (\text{MAX})$	30	—	—	μA
I_{BHHHS}	Bus Hold High sustaining current	$V_{IN} = 0.7V_{CCIO}$	-30	—	—	μA
I_{BHLO}	Bus Hold Low Overdrive current	$0 \leq V_{IN} \leq V_{IH} (\text{MAX})$	—	—	150	μA
I_{BHHO}	Bus Hold High Overdrive current	$0 \leq V_{IN} \leq V_{IH} (\text{MAX})$	—	—	-150	μA
V_{BHT}^3	Bus Hold trip Points	$0 \leq V_{IN} \leq V_{IH} (\text{MAX})$	$V_{IL} (\text{MAX})$	—	$V_{IH} (\text{MIN})$	V
C1	I/O Capacitance ²	$V_{CCIO} = 3.3V, 2.5V, 1.8V, 1.5V, 1.2V$, $V_{CC} = \text{Typ.}, V_{IO} = 0 \text{ to } V_{IH} (\text{MAX})$	—	8	—	pf
C2	Dedicated Input Capacitance ²	$V_{CCIO} = 3.3V, 2.5V, 1.8V, 1.5V, 1.2V$, $V_{CC} = \text{Typ.}, V_{IO} = 0 \text{ to } V_{IH} (\text{MAX})$	—	8	—	pf

1. Input or I/O leakage current is measured with the pin configured as an input or as an I/O with the output driver tri-stated. It is not measured with the output driver active. Bus maintenance circuits are disabled.
2. $T_A = 25^\circ C$, $f = 1.0\text{MHz}$
3. Please refer to V_{IL} and V_{IH} in the sysIO Single-Ended DC Electrical Characteristics table of this document.
4. When V_{IH} is higher than V_{CCIO} , a transient current typically of 30ns in duration or less with a peak current of 6mA can occur on the high-to-low transition.

Programming and Erase Supply Current^{1, 2, 3, 4}

Symbol	Parameter	Typ. ⁵	Max.	Units
I _{APS}	Power Management PvCCA/D Programming Current		40	mA
I _{CC}	FPGA Core Power Supply	11		mA
I _{CCAUX}	FPGA Auxiliary Power Supply V _{CCAUX} = 3.3V	10		mA
I _{CCIO}	FPGA Bank Power Supply ⁶	2		mA

1. For further information on supply current, please see details of additional technical documentation at the end of this data sheet.

2. Assumes all I/O pins are held at V_{CCIO} or GND.

3. Typical user pattern.

4. JTAG programming is at 25 MHz.

5. T_J = 25°C, power supplies at nominal voltage.

6. Per bank. V_{CCIO} = 2.5V. Does not include pull-up/pull-down.

Voltage Monitors

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
R _{IN}	Input resistance		55	65	75	kΩ
C _{IN}	Input capacitance			8		pF
V _{MON} Range	Programmable trip-point range		0.075		5.734	V
V _Z Sense	Near-ground sense threshold		70	75	80	mV
V _{MON} Accuracy	Absolute accuracy of any trip-point ¹			0.2	0.7	%
	Single-ended V _{MON} pins ^{2, 3}			0.3	0.9	%
HYST	Hysteresis of any trip-point (relative to setting)			1		%
CMR	Common mode rejection			60		dB
t _{PD16}	Propagation delay input to output glitch filter OFF			16		μs
t _{PD64}	Propagation delay input to output glitch filter ON			64		μs

1. Guaranteed by characterization across PvCCA range, operating temperature, process.

2. Single-ended V_{MON} inputs in 128-pin TQFP package only. Single-ended V_{MON} input pins include: 59 (V_{MON1}), 83 (V_{MON9}), 84 (V_{MON10}), 86 (V_{MON11}), 88 (V_{MON12}).

3. No adjacent digital I/O pin switching noise as described in the following table for single-ended V_{MON} trip point error.

Single-Ended Voltage Monitor Trip Point Error¹

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V _{MON} Error SE	Single-ended trip point error (with adjacent switching noise) ²	Pins 85, 87, 89 F _{SWITCH} = 10MHz		2		mV
	Single-ended trip point error (no adjacent switching noise) ²	Pins 85, 87, 89 F _{SWITCH} = 0Hz; All other digital I/O = 10MHz		1		mV

1. Single-ended V_{MON} inputs in 128-pin TQFP package only. Affected single-ended V_{MON} input pins only include: 83 (V_{MON9}), 84 (V_{MON10}), 86 (V_{MON11}), and 88 (V_{MON12}). Single-ended V_{MON} input pin 59 (V_{MON1}) is not affected by adjacent switching noise.

2. Defined as TQFP package option adjacent digital I/O pins 85 (PR4B), 87 (PR3D) and 89 (PR2D) configured as outputs switching (F_{SWITCH}) at 10MHz into a 33pF load capacitance.

High Voltage FET Drivers

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V _{PP}	Gate driver output voltage	12V setting	11.5	12	12.5	V
		10V setting	9.6	10	10.4	
		8V setting	7.7	8	8.3	
		6V setting	5.8	6	6.2	
I _{OUTSRC}	Gate driver source current (HIGH state)	Four settings in software		12.5		μA
				25		
				50		
				100		
I _{OUTSINK}	Gate driver sink current (LOW state)	FAST OFF mode	2000	3000		μA
		Controlled ramp settings		100		
				250		
				500		

Margin/Trim DAC Output Characteristics

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
	Resolution			8 (7+sign)		Bits
FSR	Full scale range			+/-320		mV
LSB	LSB step size			2.5		mV
I _{OUT}	Output source/sink current		-200		200	μA
BPZ	Bipolar zero output voltage (code=80h)	Offset 1		0.6		V
		Offset 2		0.8		
		Offset 3		1.0		
		Offset 4		1.25		
TS	TrimCell output voltage settling time ¹	DAC code changed from 80H to FFH or 80H to 00H			2.5	ms
		Single DAC code change		256		μs
C_LOAD	Maximum load capacitance				50	pF
T _{UPDATEM}	Update time through I ² C port ²	MCLK = 8 MHz		260		μs
TOSE	Total open loop supply voltage error ³	Full scale DAC corresponds to ±5% supply voltage variation	-1%		+1%	V/V

1. To 1% of set value with 50pf load connected to trim pins.

2. Total time required to update a single TRIMx output value by setting the associated DAC through the I²C port.

3. This is the total resultant error in the trimmed power supply output voltage referred to any DAC code due to the DAC's INL, DNL, gain, output impedance, offset error and bipolar offset error across the industrial temperature range and the Platform Manager operating P_{VCCA} and P_{VCCD} ranges.

ADC Characteristics

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
	ADC Resolution			10		Bits
T _{CONVERT}	Conversion Time	Time from I ² C Request			200	μs
V _{IN}	Input range Full Scale	Programmable Attenuator = 1	0		2.048	V
		Programmable Attenuator = 3	0		5.9 ¹	V
ADC Step Size	LSB	Programmable Attenuator = 1		2		mV
		Programmable Attenuator = 3		6		mV
Eattenuator	Error Due to Attenuator	Programmable Attenuator = 3		+/- 0.1		%

1. Maximum voltage is limited by V_{MONX} pin (theoretical maximum is 6.144V).

ADC Error Budget Across Entire Operating Temperature Range

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
TADC Error	Total Measurement Error at Any Voltage (Differential Analog Inputs) ¹	Measurement Range 600 mV - 2.048V, VMONxGS > -100mV, Attenuator =1	-8	+/-4	8	mV
		Measurement Range 600 mV - 2.048V, VMONxGS > -200mV, Attenuator =1		+/-6		mV
		Measurement Range 0 - 2.048V, VMONxGS > -200mV, Attenuator =1		+/-10		mV
	Total Measurement Error at Any Voltage (Single-Ended Analog Inputs) ²	Measurement Range 600 mV - 2.048V, Attenuator =1	-8	+/-4	8	mV

1. Total error, guaranteed by characterization, includes INL, DNL, Gain, Offset, and PSR specifications of the ADC.

2. Single-ended V_{MON} inputs in 128-pin TQFP package only. Single-ended V_{MON} input pins include: 59 (VMON1), 83 (VMON9), 84 (VMON10), 86 (VMON11), 88 (VMON12).

Digital Specifications – Power Management Section Dedicated Inputs

Over Recommended Operating Conditions

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
I_{IL}, I_{IH}	Input leakage, no pull-up/pull-down				+/-10	μA
I_{PU}	Input pull-up current (PTMS, PTDI, PTDISEL, PATDI, MCLK)			70		μA
V_{IL}	Voltage input, logic low ¹	PTDI, PTMS, PATDI, PTDISEL, 3.3V supply			0.8	V
		PTDI, PTMS, PATDI, PTDISEL, 2.5V supply			0.7	
		SCL, SDA			30% P_{VCCD}	
		IN[1:4]			30% P_{VCCINP}	
V_{IH}	Voltage input, logic high ¹	PTDI, PTMS, PATDI, PTDISEL, 3.3V supply	2.0			V
		PTDI, PTMS, PATDI, PTDISEL, 2.5V supply	1.7			
		SCL, SDA	70% P_{VCCD}		P_{VCCD}	
		IN[1:4]	70% P_{VCCINP}		P_{VCCINP}	

1. SCL, SDA referenced to P_{VCCD} ; IN[1:4] referenced to P_{VCCINP} ; PTDO, PTDI, PTMS, PATDI, PTDISEL referenced to P_{VCCJ} .

Digital Specifications – Power Management Section Dedicated Outputs

Over Recommended Operating Conditions

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
$I_{OH-HVOUT}$	Output leakage current	HVOUT[1:4] in open drain mode and pulled up to 12V		35	100	μA
V_{OL}	HVOUT[1:4] (open drain mode), OUT[5:16]	$I_{SINK} = 10mA$			0.8	V
		$I_{SINK} = 20mA$			0.8	
	PTDO, MCLK, CPLDCLK, SDA	$I_{SINK} = 4mA$			0.4	
V_{OH}	PTDO, MCLK, CPLDCLK	$I_{SRC} = 4mA$			$P_{VCCD} - 0.4$	V
$I_{SINKTOTAL}$	All digital outputs				130	mA

sysIO Recommended Operating Conditions

Standard	V_{CCIO} (V)		
	Min.	Typ.	Max.
LVC MOS 3.3	3.135	3.3	3.465
LVC MOS 2.5	2.375	2.5	2.625
LVC MOS 1.8	1.71	1.8	1.89
LVC MOS 1.5	1.425	1.5	1.575
LVC MOS 1.2	1.14	1.2	1.26
LV TTL	3.135	3.3	3.465

sysIO Single-Ended DC Electrical Characteristics

Input/Output Standard	V_{IL}		V_{IH}		V_{OL} Max. (V)	V_{OH} Min. (V)	I_{OL}^1 (mA)	I_{OH}^1 (mA)
	Min. (V)	Max. (V)	Min. (V)	Max. (V)				
LVC MOS 3.3	-0.3	0.8	2.0	3.6	0.4	V_{CCIO} - 0.4	16, 12, 8, 4	-14, -12, -8, -4
					0.2	V_{CCIO} - 0.2	0.1	-0.1
LV TTL	-0.3	0.8	2.0	3.6	0.4	2.4	16	-16
					0.4	V_{CCIO} - 0.4	12, 8, 4	-12, -8, -4
					0.2	V_{CCIO} - 0.2	0.1	-0.1
					0.4	V_{CCIO} - 0.4	16, 12, 8, 4	-14, -12, -8, -4
LVC MOS 2.5	-0.3	0.7	1.7	3.6	0.4	V_{CCIO} - 0.2	0.1	-0.1
					0.4	V_{CCIO} - 0.4	16, 12, 8, 4	-14, -12, -8, -4
					0.2	V_{CCIO} - 0.2	0.1	-0.1
					0.4	V_{CCIO} - 0.4	16, 12, 8, 4	-14, -12, -8, -4
LVC MOS 1.8 ²	-0.3	$0.35V_{CCIO}$	$0.65V_{CCIO}$	3.6	0.4	V_{CCIO} - 0.2	0.1	-0.1
					0.2	V_{CCIO} - 0.2	0.1	-0.1
LVC MOS 1.5 ²	-0.3	$0.35V_{CCIO}$	$0.65V_{CCIO}$	3.6	0.4	V_{CCIO} - 0.4	8, 4	-8, -4
					0.2	V_{CCIO} - 0.2	0.1	-0.1
LVC MOS 1.2 ²	-0.3	0.42	0.78	3.6	0.4	V_{CCIO} - 0.4	6, 2	-6, -2
					0.2	V_{CCIO} - 0.2	0.1	-0.1

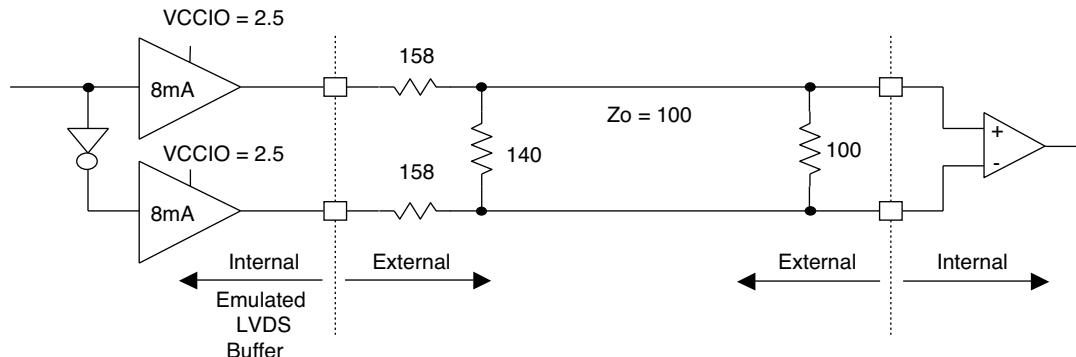
1. The average DC current drawn by I/Os between GND connections, or between the last GND in an I/O bank and the end of an I/O bank, as shown in the logic signal connections table shall not exceed $n * 8\text{mA}$. Where n is the number of I/Os between bank GND connections or between the last GND in a bank and the end of a bank.
2. Lower voltage operation not supported for VCCIO2 bank pins.

sysIO Differential Electrical Characteristics

LVDS Emulation

FPGA section outputs can support LVDS outputs via emulation (LVDS25E), in addition to the LVDS support that is available. The output is emulated using complementary LVCMOS outputs in conjunction with resistors across the driver outputs on all devices. The scheme shown in Figure 3 is one possible solution for LVDS standard implementation. Resistor values in Figure 3 are industry standard values for 1% resistors.

Figure 3. LVDS Using External Resistors (LVDS25E)

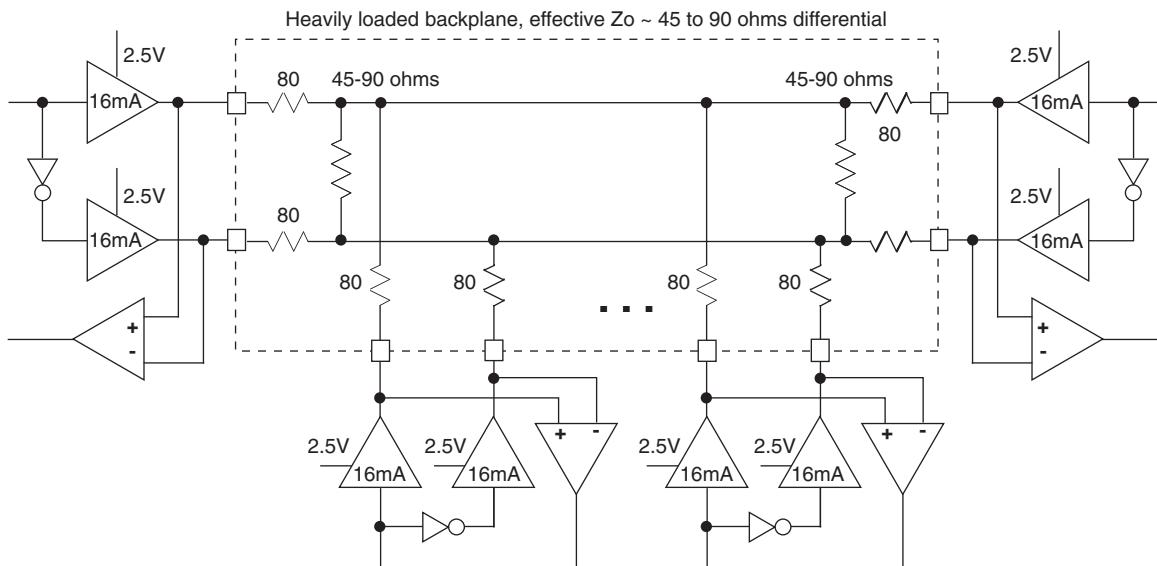


Note: All resistors are $\pm 1\%$.

BLVDS Emulation

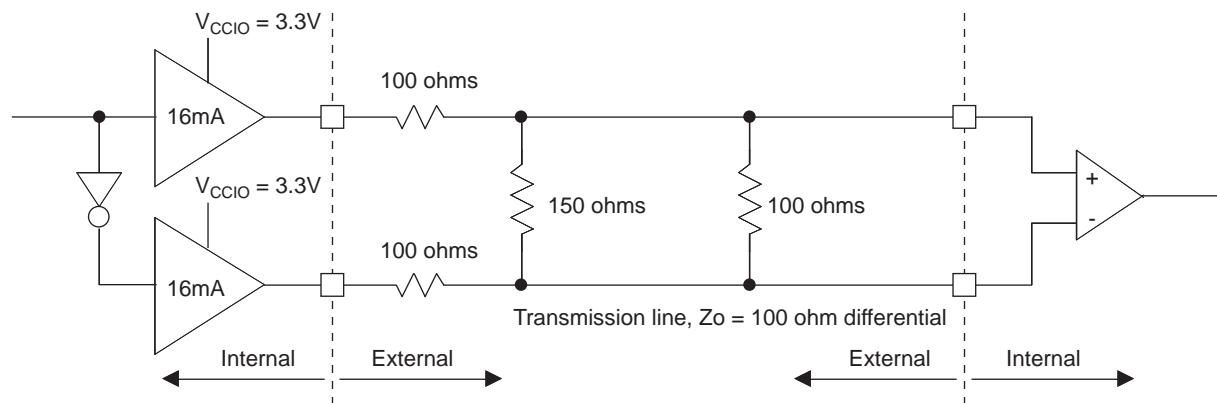
FPGA outputs support the BLVDS standard through emulation. The output is emulated using complementary LVC-MOS outputs in conjunction with a parallel external resistor across the driver outputs. BLVDS is intended for use when multi-drop and bi-directional multi-point differential signaling is required. The scheme shown in Figure 4 is one possible solution for bi-directional multi-point differential signals.

Figure 4. BLVDS Multi-point Output Example



LVPECL Emulation

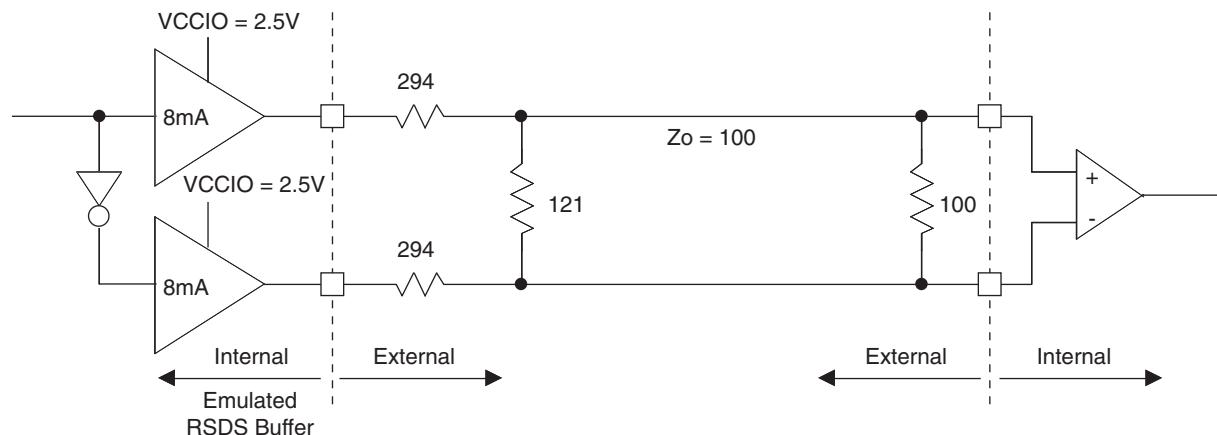
FPGA outputs support the differential LVPECL standard through emulation. This output standard is emulated using complementary LVCMSO outputs in conjunction with a parallel resistor across the driver outputs on all the devices. The scheme shown in Figure 5 is one possible solution for point-to-point signals.

Figure 5. Differential LVPECL


For further information on LVPECL, BLVDS and other differential interfaces please see details of additional technical documentation at the end of the data sheet.

RSDS Emulation

FPGA outputs support the differential RSDS standard. The output standard is emulated using complementary LVCMS outputs in conjunction with a parallel resistor across the driver outputs on all the devices. The scheme shown in Figure 6 is one possible solution for RSDS standard implementation. Use LVDS25E mode with suggested resistor values in Figure 6 are industry standard values for 1% resistors.

Figure 6. RSDS (Reduced Swing Differential Standard)


Oscillator Transient Characteristics

Over Recommended Operating Conditions

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
f_{CLK}	Power Management internal master clock frequency (MCLK)		7.6	8	8.4	MHz
f_{CLKEXT}	Power Management externally applied master clock (MCLK)		7.2		8.8	MHz
f_{PLDCLK}	CPLDCLK output frequency	$f_{CLK} = 8\text{MHz}$		250		kHz
$f_{FPGACLK}$	FPGA internal master clock frequency		18		26	MHz

Power Management CPLD Timer Transient Characteristics

Over Recommended Operating Conditions

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
Timeout Range	Range of programmable timers (128 steps)	$f_{CLK} = 8MHz$	0.032		1966	ms
Resolution	Spacing between available adjacent timer intervals				13	%
Accuracy	Timer accuracy	$f_{CLK} = 8MHz$	-6.67		-12.5	%

Power Management I²C Port Characteristics

Symbol	Definition	100KHz		400KHz		Units
		Min.	Max.	Min.	Max.	
F_{I^2C}	I ² C clock/data rate		100 ¹		400 ¹	KHz
$T_{SU;STA}$	After start	4.7		0.6		us
$T_{HD;STA}$	After start	4		0.6		us
$T_{SU;DAT}$	Data setup	250		100		ns
$T_{SU;STO}$	Stop setup	4		0.6		us
$T_{HD;DAT}$	Data hold; SCL= Vih_min = 2.1V	0.3	3.45	0.3	0.9	us
T_{LOW}	Clock low period	4.7		1.3		us
T_{HIGH}	Clock high period	4		0.6		us
T_F	Fall time; 2.25V to 0.65V		300		300	ns
T_R	Rise time; 0.65V to 2.25V		1000		300	ns
$T_{TIMEOUT}$	Detect clock low timeout	25	35	25	35	ms
T_{POR}	Device must be operational after power-on reset	500		500		ms
T_{BUF}	Bus free time between stop and start condition	4.7		1.3		us

- If F_{I^2C} is less than 50kHz, then the ADC DONE status bit is not guaranteed to be set after a valid conversion request is completed. In this case, waiting for the $T_{CONVERT}$ minimum time after a convert request is made is the only way to guarantee a valid conversion is ready for readout. When F_{I^2C} is greater than 50kHz, ADC conversion complete is ensured by waiting for the DONE status bit.

Timing for Power Management JTAG Operations

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
t_{ISPEN}	Program enable delay time		10	—	—	μs
t_{ISPDIS}	Program disable delay time		30	—	—	μs
t_{HVDIS}	High voltage discharge time, program		30	—	—	μs
t_{HVDIS}	High voltage discharge time, erase		200	—	—	μs
t_{CEN}	Falling edge of PTCK to PTDO active		—	—	15	ns
t_{CDIS}	Falling edge of PTCK to PTDO disable		—	—	15	ns
t_{SU1}	Setup time		5	—	—	ns
t_H	Hold time		10	—	—	ns
t_{CKH}	PTCK clock pulse width, high		20	—	—	ns
t_{CKL}	PTCK clock pulse width, low		20	—	—	ns
f_{MAX}	Maximum PTCK clock frequency		—	—	25	MHz
t_{CO}	Falling edge of PTCK to valid output		—	—	15	ns
t_{PWV}	Verify pulse width		30	—	—	μs
t_{PWP}	Programming pulse width		20	—	—	ms

Figure 7. Erase (User Erase or Erase All) Timing Diagram

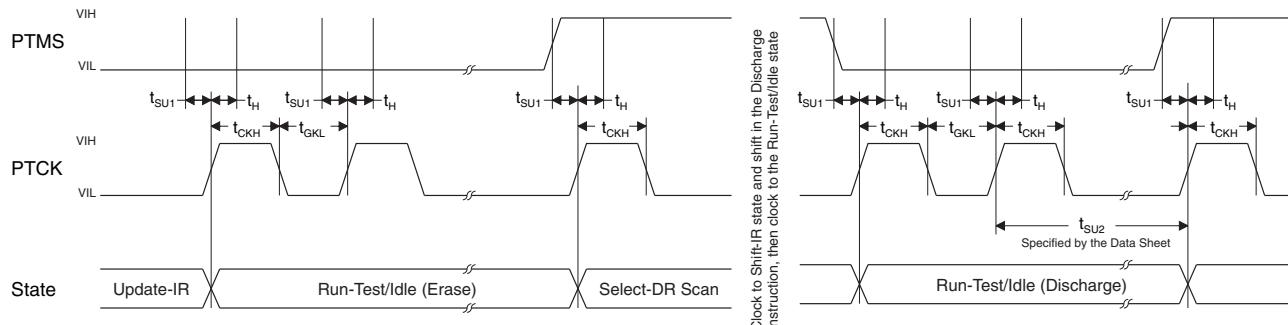


Figure 8. Programming Timing Diagram

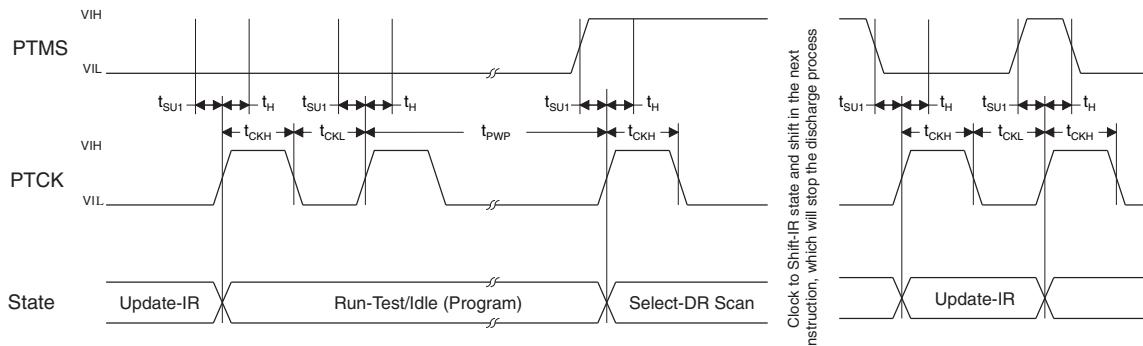
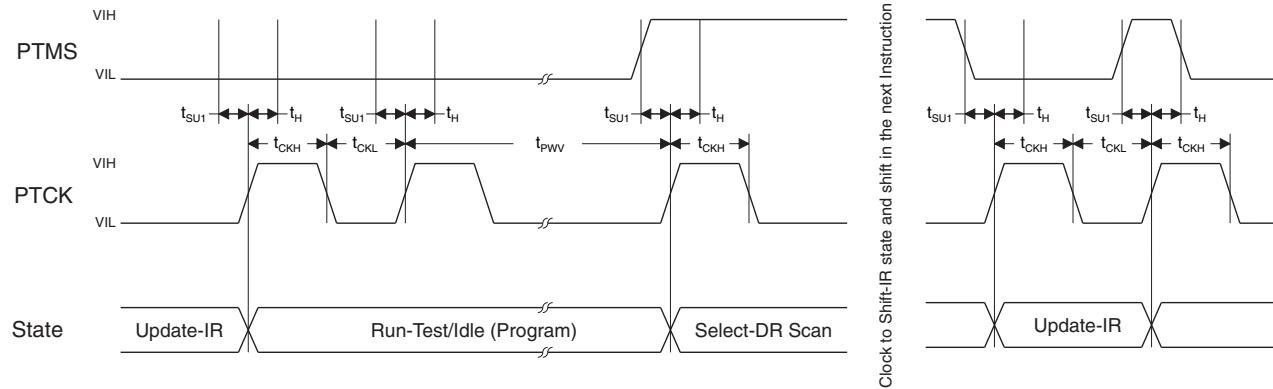
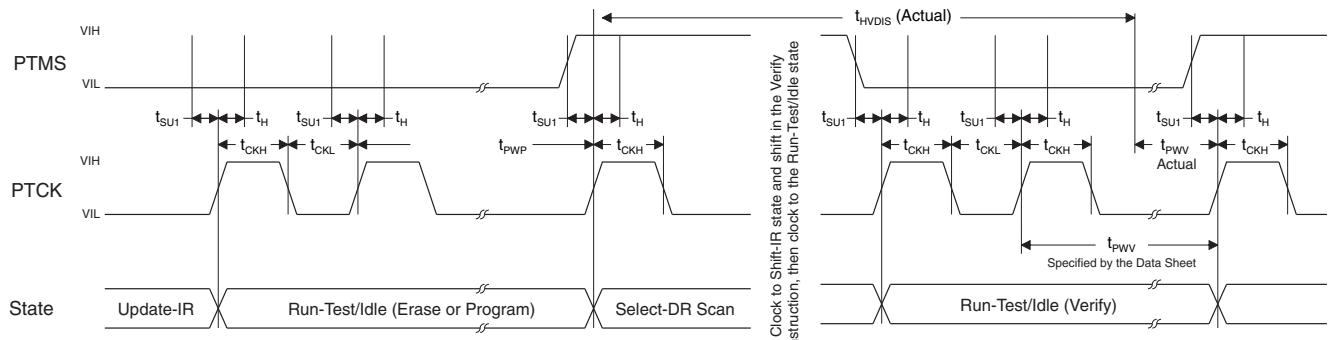


Figure 9. Verify Timing Diagram

Figure 10. Discharge Timing Diagram


Typical FPGA Building Block Function Performance¹

Pin-to-Pin Performance (LVCMOS25 12mA Drive)

Function	Timing	Units
Basic Functions		
16-bit decoder	6.7	ns
4:1 MUX	4.5	ns
16:1 MUX	5.1	ns

Register-to-Register Performance

Function	Timing	Units
Basic Functions		
16:1 MUX	487	MHz
16-bit adder	292	MHz
16-bit counter	388	MHz
64-bit counter	200	MHz
Distributed Memory Functions		
16x2 Single Port RAM	434	MHz
64x2 Single Port RAM	320	MHz
128x4 Single Port RAM	261	MHz
32x2 Pseudo-Dual Port RAM	314	MHz
64x4 Pseudo-Dual Port RAM	271	MHz

1. The above timing numbers are generated using the Platform Manager design tool. Exact performance may vary with device and tool version. The tool uses internal parameters that have been characterized but are not tested on every device.

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Derating Logic Timing

Logic Timing provided in the following sections of the data sheet and the Platform Manager design tool are worst case numbers in the operating range. Actual delays may be much faster. The Platform Manager design tool from Lattice can provide FPGA logic timing numbers at a particular temperature and voltage.

FPGA Section External Switching Characteristics¹

Over Recommended Operating Conditions

Parameter	Description	Min.	Max.	Units
General I/O Pin Parameters (Using Global Clock without PLL)¹				
t _{PD}	Best Case t _{PD} Through 1 LUT	—	4.9	ns
t _{CO}	Best Case Clock to Output - From PFU	—	5.7	ns
t _{SU}	Clock to Data Setup - To PFU	1.5	—	ns
t _H	Clock to Data Hold - To PFU	-0.1	—	ns
f _{MAX_IO}	Clock Frequency of I/O and PFU Register	—	500	MHz
t _{SKEW_PRI}	Global Clock Skew Across Device	—	240	ps

1. General timing numbers based on LVCMOS2.5V, 12 mA.

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FPGA Sleep Mode Timing

Parameter	Description	Min.	Max.	Units
t _{PWRDN}	SLEEPN Low to Power Down	—	400	ns
t _{PWRUP}	SLEEPN High to Power Up	—	600	μs
t _{WSLEEPN}	SLEEPN Pulse Width	400	—	ns
t _{WAWAKE}	SLEEPN Pulse Rejection	—	100	ns

FPGA Section Internal Timing Parameters¹

Over Recommended Operating Conditions

Parameter	Description	Min.	Max.	Units
PFU/PFF Logic Mode Timing				
t _{LUT4_PFU}	LUT4 delay (A to D inputs to F output)	—	0.39	ns
t _{LUT6_PFU}	LUT6 delay (A to D inputs to OFX output)	—	0.62	ns
t _{LSR_PFU}	Set/Reset to output of PFU	—	1.26	ns
t _{SUM_PFU}	Clock to Mux (M0,M1) input setup time	0.15	—	ns
t _{HM_PFU}	Clock to Mux (M0,M1) input hold time	-0.07	—	ns
t _{SUD_PFU}	Clock to D input setup time	0.18	—	ns
t _{HD_PFU}	Clock to D input hold time	-0.04	—	ns
t _{CK2Q_PFU}	Clock to Q delay, D-type register configuration	—	0.56	ns
t _{LE2Q_PFU}	Clock to Q delay latch configuration	—	0.74	ns
t _{LD2Q_PFU}	D to Q throughput delay when latch is enabled	—	0.77	ns
PFU Dual Port Memory Mode Timing				
t _{CORAM_PFU}	Clock to Output	—	0.56	ns
t _{SUDATA_PFU}	Data Setup Time	-0.25	—	ns
t _{HDATA_PFU}	Data Hold Time	0.39	—	ns
t _{SUADDR_PFU}	Address Setup Time	-0.65	—	ns
t _{HADDR_PFU}	Address Hold Time	0.99	—	ns
t _{SUWREN_PFU}	Write/Read Enable Setup Time	-0.30	—	ns
t _{HWREN_PFU}	Write/Read Enable Hold Time	0.47	—	ns
PIO Input/Output Buffer Timing				
t _{IN_PIO}	Input Buffer Delay	—	1.06	ns
t _{OUT_PIO}	Output Buffer Delay	—	1.80	ns

1. Internal parameters are characterized but not tested on every device.

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FPGA Section Timing Adders^{1, 2, 3}

Over Recommended Operating Conditions

Buffer Type	Description		Units
Input Adjusters			
LVTTL33	LVTTL	0.01	ns
LVCMOS33	LVCMOS 3.3	0.01	ns
LVCMOS25	LVCMOS 2.5	0.00	ns
LVCMOS18	LVCMOS 1.8	0.10	ns
LVCMOS15	LVCMOS 1.5	0.19	ns
LVCMOS12	LVCMOS 1.2	0.56	ns
Output Adjusters			
LVTTL33_4mA	LVTTL 4mA drive	0.05	ns
LVTTL33_8mA	LVTTL 8mA drive	0.08	ns
LVTTL33_12mA	LVTTL 12mA drive	-0.01	ns
LVTTL33_16mA	LVTTL 16mA drive	0.70	ns
LVCMOS33_4mA	LVCMOS 3.3 4mA drive	0.05	ns
LVCMOS33_8mA	LVCMOS 3.3 8mA drive	0.08	ns
LVCMOS33_12mA	LVCMOS 3.3 12mA drive	-0.01	ns
LVCMOS33_14mA	LVCMOS 3.3 14mA drive	0.70	ns
LVCMOS25_4mA	LVCMOS 2.5 4mA drive	0.07	ns
LVCMOS25_8mA	LVCMOS 2.5 8mA drive	0.13	ns
LVCMOS25_12mA	LVCMOS 2.5 12mA drive	0.00	ns
LVCMOS25_14mA	LVCMOS 2.5 14mA drive	0.47	ns
LVCMOS18_4mA	LVCMOS 1.8 4mA drive	0.15	ns
LVCMOS18_8mA	LVCMOS 1.8 8mA drive	0.06	ns
LVCMOS18_12mA	LVCMOS 1.8 12mA drive	-0.08	ns
LVCMOS18_14mA	LVCMOS 1.8 14mA drive	0.09	ns
LVCMOS15_4mA	LVCMOS 1.5 4mA drive	0.22	ns
LVCMOS15_8mA	LVCMOS 1.5 8mA drive	0.07	ns
LVCMOS12_2mA	LVCMOS 1.2 2mA drive	0.36	ns
LVCMOS12_6mA	LVCMOS 1.2 6mA drive	0.07	ns

1. Timing adders are characterized but not tested on every device.
2. LVCMOS timing is measured with the load specified in Switching Test Conditions table.
3. All other standards tested according to the appropriate specifications.

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Flash Download Time

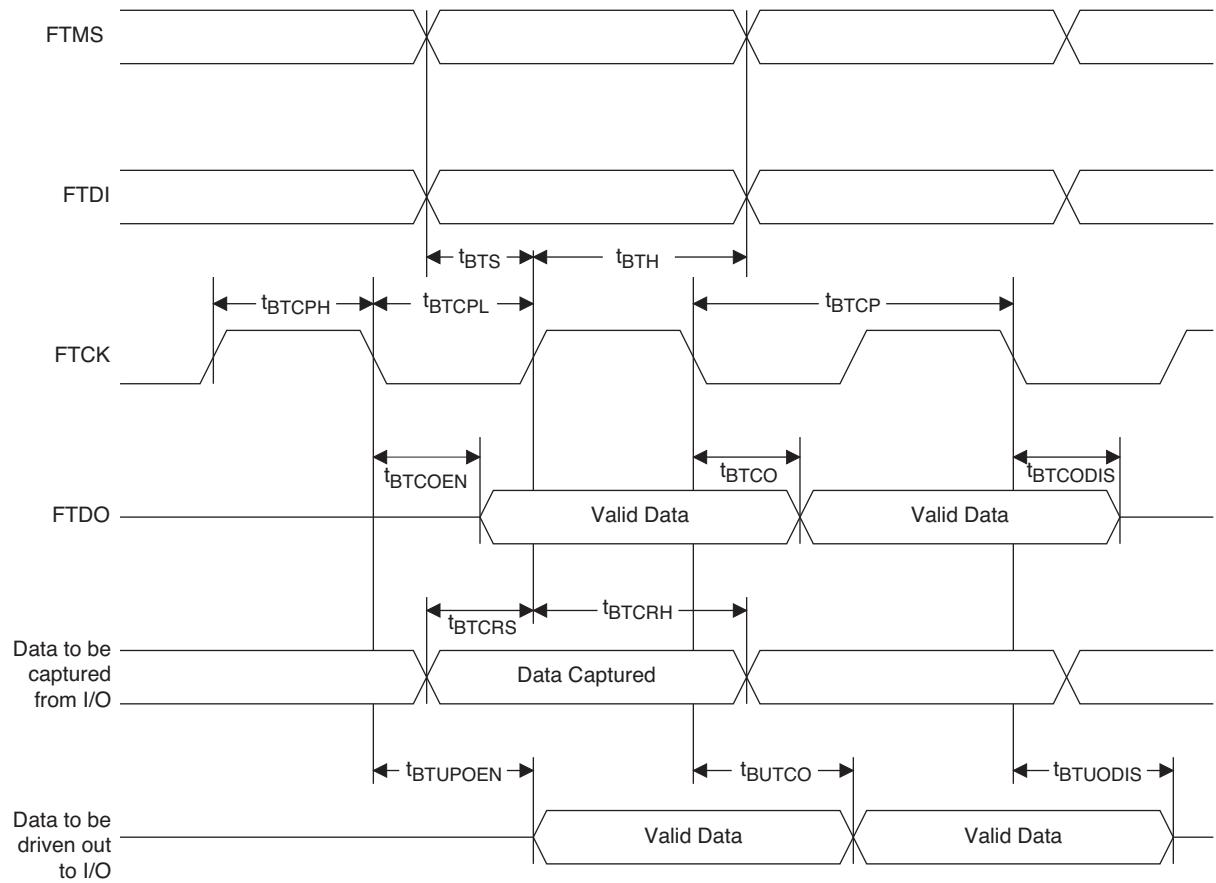
Symbol	Parameter	Min.	Typ.	Max.	Units
$t_{REFRESH}$	V_{CC} or V_{CCAUX} to Device I/O Active	—	—	0.6	ms

FPGA JTAG Port Timing Specifications

Symbol	Parameter	Min.	Max.	Units
f_{MAX}	FTCK [BSCAN] clock frequency	—	25	MHz
t_{BTCP}	FTCK [BSCAN] clock pulse width	40	—	ns
t_{BTCPH}	FTCK [BSCAN] clock pulse width high	20	—	ns
t_{BTCPL}	FTCK [BSCAN] clock pulse width low	20	—	ns
t_{BTS}	FTCK [BSCAN] setup time	8	—	ns
t_{BTH}	FTCK [BSCAN] hold time	10	—	ns
t_{BTRF}	FTCK [BSCAN] rise/fall time	50	—	mV/ns
t_{BTCO}	TAP controller falling edge of clock to output valid	—	10	ns
$t_{BTCODIS}$	TAP controller falling edge of clock to output disabled	—	10	ns
t_{BTCOEN}	TAP controller falling edge of clock to output enabled	—	10	ns
t_{BTCRS}	BSCAN test capture register setup time	8	—	ns
t_{TCRH}	BSCAN test capture register hold time	25	—	ns
t_{BUTCO}	BSCAN test update register, falling edge of clock to output valid	—	25	ns
$t_{BTUODIS}$	BSCAN test update register, falling edge of clock to output disabled	—	25	ns
$t_{BTUOPEN}$	BSCAN test update register, falling edge of clock to output enabled	—	25	ns

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Figure 11. FPGA JTAG Port Timing Waveforms



FPGA Output Switching Test Conditions

Figure 12 shows the output test load that is used for AC testing. The specific values for resistance, capacitance, voltage, and other test conditions are shown in Table 2.

Figure 12. Output Test Load, LVTTL and LVC MOS Standards

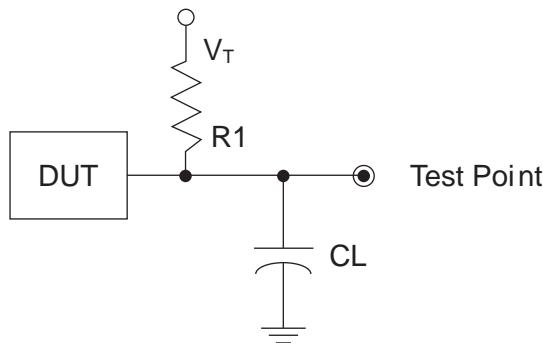


Table 2. Test Fixture Required Components, Non-Terminated Interfaces

Test Condition	R ₁	C _L	Timing Ref.	V _T
LVTTL and LVC MOS settings (L → H, H → L)	∞	0pF	LVTTL, LVC MOS 3.3 = 1.5V	—
			LVC MOS 2.5 = $V_{CCIO}/2$	—
			LVC MOS 1.8 = $V_{CCIO}/2$	—
			LVC MOS 1.5 = $V_{CCIO}/2$	—
			LVC MOS 1.2 = $V_{CCIO}/2$	—
LVTTL and LVC MOS 3.3 (Z → H)	188	0pF	1.5	V_{OL}
LVTTL and LVC MOS 3.3 (Z → L)				V_{OH}
Other LVC MOS (Z → H)			$V_{CCIO}/2$	V_{OL}
Other LVC MOS (Z → L)			$V_{CCIO}/2$	V_{OH}
LVTTL + LVC MOS (H → Z)			$V_{OH} - 0.15$	V_{OL}
LVTTL + LVC MOS (L → Z)			$V_{OL} - 0.15$	V_{OH}

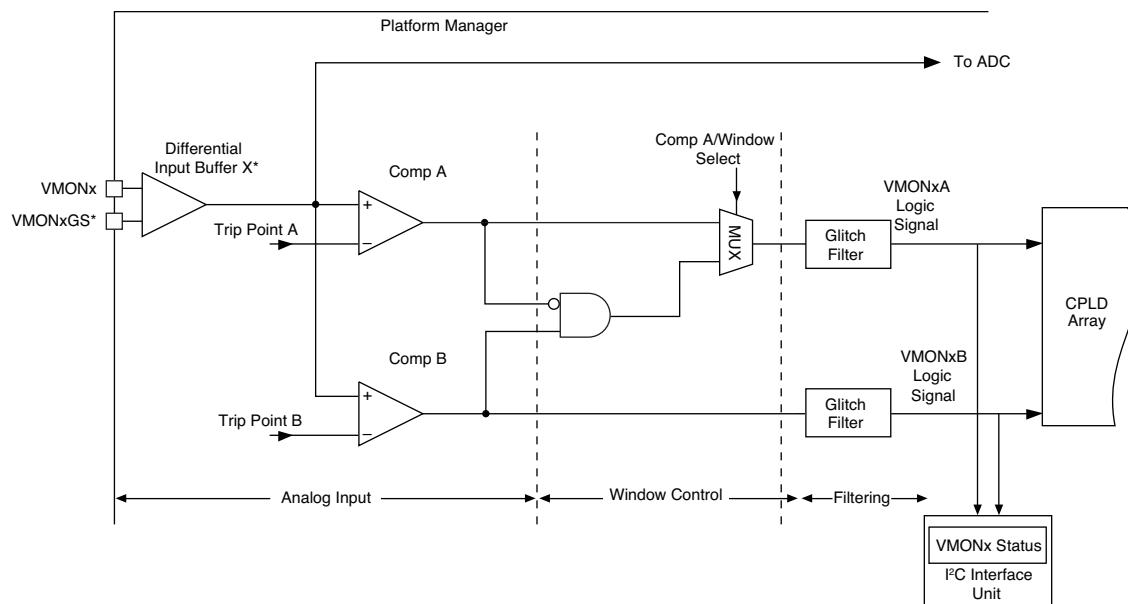
Note: Output test conditions for all other interfaces are determined by the respective standards.

Architecture Details

Analog Monitor Inputs

The Platform Manager provides 12 independently programmable voltage monitor input circuits as shown in Figure 13. Two individually programmable trip-point comparators are connected to an analog monitoring input. Each comparator reference has 368 programmable trip points over the range of 0.664V to 5.734V. Additionally, a 75mV ‘zero-detect’ threshold is selectable which allows the voltage monitors to determine if a monitored signal has dropped to ground level. This feature is especially useful for determining if a power supply’s output has decayed to a substantially inactive condition after it has been switched off.

Figure 13. Platform Manager Voltage Monitors



*Differential Input Buffer X and VMONxGS pins are not present for single-ended VMONx inputs in the 128-pin TQFP package option.

Figure 13 shows the functional block diagram of one of the 12 voltage monitor inputs - ‘x’ (where $x = 1\dots12$). Each voltage monitor can be divided into three sections: Analog Input, Window Control, and Filtering. The first section provides a differential input buffer to monitor the power supply voltage through VMONx+ (to sense the positive terminal of the supply) and VMONxGS (to sense the power supply ground). Differential voltage sensing minimizes inaccuracies in voltage measurement with ADC and monitor thresholds due to the potential difference between the Platform Manager device ground and the ground potential at the sensed node on the circuit board.

The voltage output of the differential input buffer is monitored by two individually programmable trip-point comparators, shown as CompA and CompB. Table 3 shows all 368 trip points spanning the range 0.664V to 5.734V to which a comparator’s threshold can be set. Note that for the 128-pin TQFP package option, the differential input buffer shown above is not present for any of the single-ended VMON input pins. Those pins are: 59 (VMON1), 83 (VMON9), 84 (VMON10), 86 (VMON11), 88 (VMON12).

Each comparator outputs a HIGH signal to the CPLD if the voltage at its positive terminal is greater than its programmed trip point setting, otherwise it outputs a LOW signal.

Hysteresis is provided by the comparators to reduce false triggering as a result of input noise. The hysteresis provided by the voltage monitor is a function of the input divider setting. Table 5 lists the typical hysteresis versus voltage monitor trip-point.

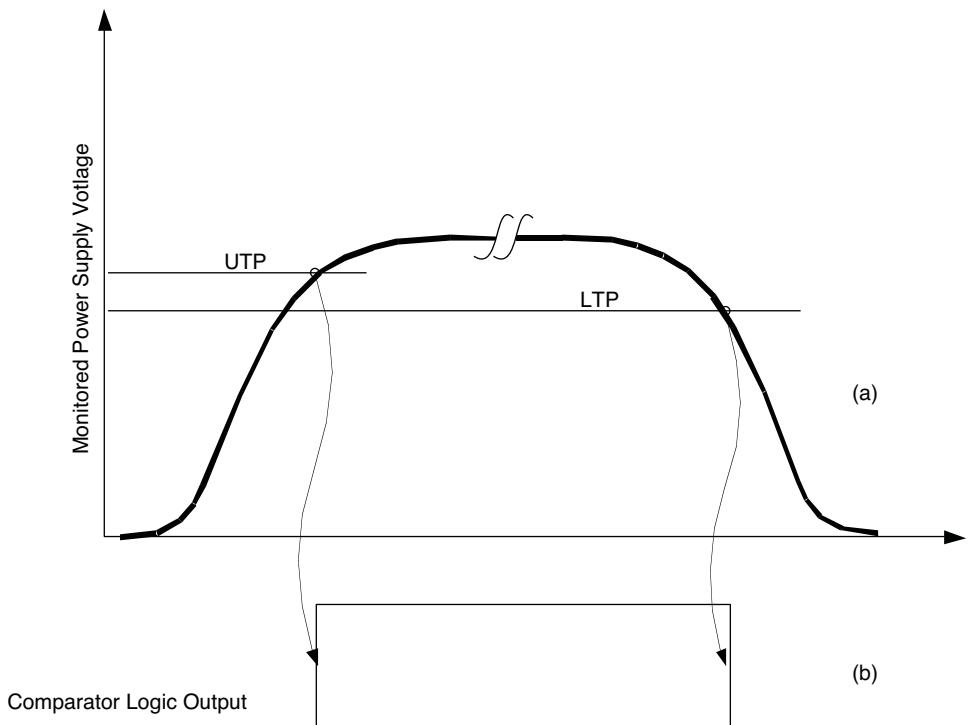
AGOOD Logic Signal

All the VMON comparators auto-calibrate immediately after a power-on reset event. During this time, the digital glitch filters are also initialized. This process completion is signalled by an internally generated logic signal: AGOOD. All logic using the VMON comparator logic signals must wait for the AGOOD signal to become active.

Programmable Over-Voltage and Under-Voltage Thresholds

Figure 14 (a) shows the power supply ramp-up and ramp-down voltage waveforms. Because of hysteresis, the comparator outputs change state at different thresholds depending on the direction of excursion of the monitored power supply.

Figure 14. (a) Power Supply Voltage Ramp-up and Ramp-down Waveform and the Resulting Comparator Output, (b) Corresponding to Upper and Lower Trip Points



During power supply ramp-up the comparator output changes from logic 0 to 1 when the power supply voltage crosses the upper trip point (UTP). During ramp down the comparator output changes from logic state 1 to 0 when the power supply voltage crosses the lower trip point (LTP). To monitor for over voltage fault conditions, the UTP should be used. To monitor under-voltage fault conditions, the LTP should be used.

Tables 3 and 4 show both the under-voltage and over-voltage trip points, which are automatically selected in software depending on whether the user is monitoring for an over-voltage condition or an under-voltage condition.

Table 3. Trip Point Table Used For Over-Voltage Detection

Fine Range Setting	Coarse Range Setting											
	1	2	3	4	5	6	7	8	9	10	11	12
1	0.790	0.941	1.120	1.333	1.580	1.885	2.244	2.665	3.156	3.758	4.818	5.734
2	0.786	0.936	1.114	1.326	1.571	1.874	2.232	2.650	3.139	3.738	4.792	5.703
3	0.782	0.930	1.108	1.319	1.563	1.864	2.220	2.636	3.123	3.718	4.766	5.674
4	0.778	0.926	1.102	1.312	1.554	1.854	2.209	2.622	3.106	3.698	4.741	5.643
5	0.773	0.921	1.096	1.305	1.546	1.844	2.197	2.607	3.089	3.678	4.715	5.612
6	0.769	0.916	1.090	1.298	1.537	1.834	2.185	2.593	3.072	3.657	4.689	5.581
7	0.765	0.911	1.084	1.290	1.529	1.825	2.173	2.579	3.056	3.637	4.663	5.550
8	0.761	0.906	1.078	1.283	1.520	1.815	2.161	2.565	3.039	3.618	4.638	5.520
9	0.756	0.901	1.072	1.276	1.512	1.805	2.149	2.550	3.022	3.598	4.612	5.489
10	0.752	0.896	1.066	1.269	1.503	1.795	2.137	2.536	3.005	3.578	4.586	5.459
11	0.748	0.891	1.060	1.262	1.495	1.785	2.125	2.522	2.988	3.558	4.561	5.428
12	0.744	0.886	1.054	1.255	1.486	1.774	2.113	2.507	2.971	3.537	4.535	5.397
13	0.739	0.881	1.048	1.248	1.478	1.764	2.101	2.493	2.954	3.517	4.509	5.366
14	0.735	0.876	1.042	1.240	1.470	1.754	2.089	2.479	2.937	3.497	4.483	5.336
15	0.731	0.871	1.036	1.233	1.461	1.744	2.077	2.465	2.920	3.477	4.457	5.305
16	0.727	0.866	1.030	1.226	1.453	1.734	2.064	2.450	2.903	3.457	4.431	5.274
17	0.723	0.861	1.024	1.219	1.444	1.724	2.052	2.436	2.886	3.437	4.406	5.244
18	0.718	0.856	1.018	1.212	1.436	1.714	2.040	2.422	2.869	3.416	4.380	5.213
19	0.714	0.851	1.012	1.205	1.427	1.704	2.028	2.407	2.852	3.396	4.355	5.183
20	0.710	0.846	1.006	1.198	1.419	1.694	2.016	2.393	2.836	3.376	4.329	5.152
21	0.706	0.841	1.000	1.190	1.410	1.684	2.004	2.379	2.819	3.356	4.303	5.121
22	0.701	0.836	0.994	1.183	1.402	1.673	1.992	2.365	2.802	3.336	4.277	5.090
23	0.697	0.831	0.988	1.176	1.393	1.663	1.980	2.350	2.785	3.316	4.251	5.059
24	0.693	0.826	0.982	1.169	1.385	1.653	1.968	2.337	2.768	3.296	4.225	5.030
25	0.689	0.821	0.976	1.162	1.376	1.643	1.956	2.323	2.752	3.276	4.199	4.999
26	0.684	0.816	0.970	1.155	1.369	1.633	1.944	2.309	2.735	3.256	4.174	4.968
27	0.680	0.810	0.964	1.148	1.361	1.623	1.932	2.294	2.718	3.236	4.149	4.937
28	0.676	0.805	0.958	1.140	1.352	1.613	1.920	2.280	2.701	3.216	4.123	4.906
29	0.672	0.800	0.952	1.133	1.344	1.603	1.908	2.266	2.684	3.196	4.097	4.876
30	0.668	0.795	0.946	1.126	—	1.593	1.896	2.251	—	3.176	4.071	4.845
Low-V Sense	75mV											

Table 4. Trip Point Table Used For Under-Voltage Detection

Fine Range Setting	Coarse Range Setting											
	1	2	3	4	5	6	7	8	9	10	11	12
1	0.786	0.936	1.114	1.326	1.571	1.874	2.232	2.650	3.139	3.738	4.792	5.703
2	0.782	0.930	1.108	1.319	1.563	1.864	2.220	2.636	3.123	3.718	4.766	5.674
3	0.778	0.926	1.102	1.312	1.554	1.854	2.209	2.622	3.106	3.698	4.741	5.643
4	0.773	0.921	1.096	1.305	1.546	1.844	2.197	2.607	3.089	3.678	4.715	5.612
5	0.769	0.916	1.090	1.298	1.537	1.834	2.185	2.593	3.072	3.657	4.689	5.581
6	0.765	0.911	1.084	1.290	1.529	1.825	2.173	2.579	3.056	3.637	4.663	5.550
7	0.761	0.906	1.078	1.283	1.520	1.815	2.161	2.565	3.039	3.618	4.638	5.520
8	0.756	0.901	1.072	1.276	1.512	1.805	2.149	2.550	3.022	3.598	4.612	5.489
9	0.752	0.896	1.066	1.269	1.503	1.795	2.137	2.536	3.005	3.578	4.586	5.459
10	0.748	0.891	1.060	1.262	1.495	1.785	2.125	2.522	2.988	3.558	4.561	5.428
11	0.744	0.886	1.054	1.255	1.486	1.774	2.113	2.507	2.971	3.537	4.535	5.397
12	0.739	0.881	1.048	1.248	1.478	1.764	2.101	2.493	2.954	3.517	4.509	5.366
13	0.735	0.876	1.042	1.240	1.470	1.754	2.089	2.479	2.937	3.497	4.483	5.336
14	0.731	0.871	1.036	1.233	1.461	1.744	2.077	2.465	2.920	3.477	4.457	5.305
15	0.727	0.866	1.030	1.226	1.453	1.734	2.064	2.450	2.903	3.457	4.431	5.274
16	0.723	0.861	1.024	1.219	1.444	1.724	2.052	2.436	2.886	3.437	4.406	5.244
17	0.718	0.856	1.018	1.212	1.436	1.714	2.040	2.422	2.869	3.416	4.380	5.213
18	0.714	0.851	1.012	1.205	1.427	1.704	2.028	2.407	2.852	3.396	4.355	5.183
19	0.710	0.846	1.006	1.198	1.419	1.694	2.016	2.393	2.836	3.376	4.329	5.152
20	0.706	0.841	1.000	1.190	1.410	1.684	2.004	2.379	2.819	3.356	4.303	5.121
21	0.701	0.836	0.994	1.183	1.402	1.673	1.992	2.365	2.802	3.336	4.277	5.090
22	0.697	0.831	0.988	1.176	1.393	1.663	1.980	2.350	2.785	3.316	4.251	5.059
23	0.693	0.826	0.982	1.169	1.385	1.653	1.968	2.337	2.768	3.296	4.225	5.030
24	0.689	0.821	0.976	1.162	1.376	1.643	1.956	2.323	2.752	3.276	4.199	4.999
25	0.684	0.816	0.970	1.155	1.369	1.633	1.944	2.309	2.735	3.256	4.174	4.968
26	0.680	0.810	0.964	1.148	1.361	1.623	1.932	2.294	2.718	3.236	4.149	4.937
27	0.676	0.805	0.958	1.140	1.352	1.613	1.920	2.280	2.701	3.216	4.123	4.906
28	0.672	0.800	0.952	1.133	1.344	1.603	1.908	2.266	2.684	3.196	4.097	4.876
29	0.668	0.795	0.946	1.126	1.335	1.593	1.896	2.251	2.667	3.176	4.071	4.845
30	0.664	0.790	0.940	1.119	—	1.583	1.884	2.236	—	3.156	4.045	4.815
Low-V Sense	75mV											

Table 5. Comparator Hysteresis vs. Trip-Point

Trip-point Range (V)		Hysteresis (mV)
Low Limit	High Limit	
0.664	0.79	8
0.79	0.941	10
0.94	1.12	12
1.119	1.333	14
1.326	1.58	17
1.583	1.885	20
1.884	2.244	24
2.236	2.665	28
2.65	3.156	34
3.156	3.758	40
4.045	4.818	51
4.815	5.734	61
75 mV		0 (Disabled)

The window control section of the voltage monitor circuit is an AND gate (with inputs: an inverted COMPA “ANDed” with COMPB signal) and a multiplexer that supports the ability to develop a ‘window’ function without using any of the CPLD resources. Through the use of the multiplexer, voltage monitor’s ‘A’ output may be set to report either the status of the ‘A’ comparator, or the window function of both comparator outputs. The voltage monitor’s ‘A’ output indicates whether the input signal is between or outside the two comparator thresholds. **Important:** This windowing function is only valid in cases where the threshold of the ‘A’ comparator is set to a value higher than that of the ‘B’ comparator. Table 6 shows the operation of window function logic.

Table 6. Voltage Monitor Windowing Logic

Input Voltage	Comp A	Comp B	Window (B and Not A)	Comment
$V_{IN} < \text{Trip-point B} < \text{Trip-point A}$	0	0	0	Outside window, low
$\text{Trip-point B} < V_{IN} < \text{Trip-point A}$	0	1	1	Inside window
$\text{Trip-point B} < \text{Trip-point A} < V_{IN}$	1	1	0	Outside window, high

Note that when the ‘A’ output of the voltage monitor circuit is set to windowing mode, the ‘B’ output continues to monitor the output of the ‘B’ comparator. This can be useful in that the ‘B’ output can be used to augment the windowing function by determining if the input is above or below the windowing range.

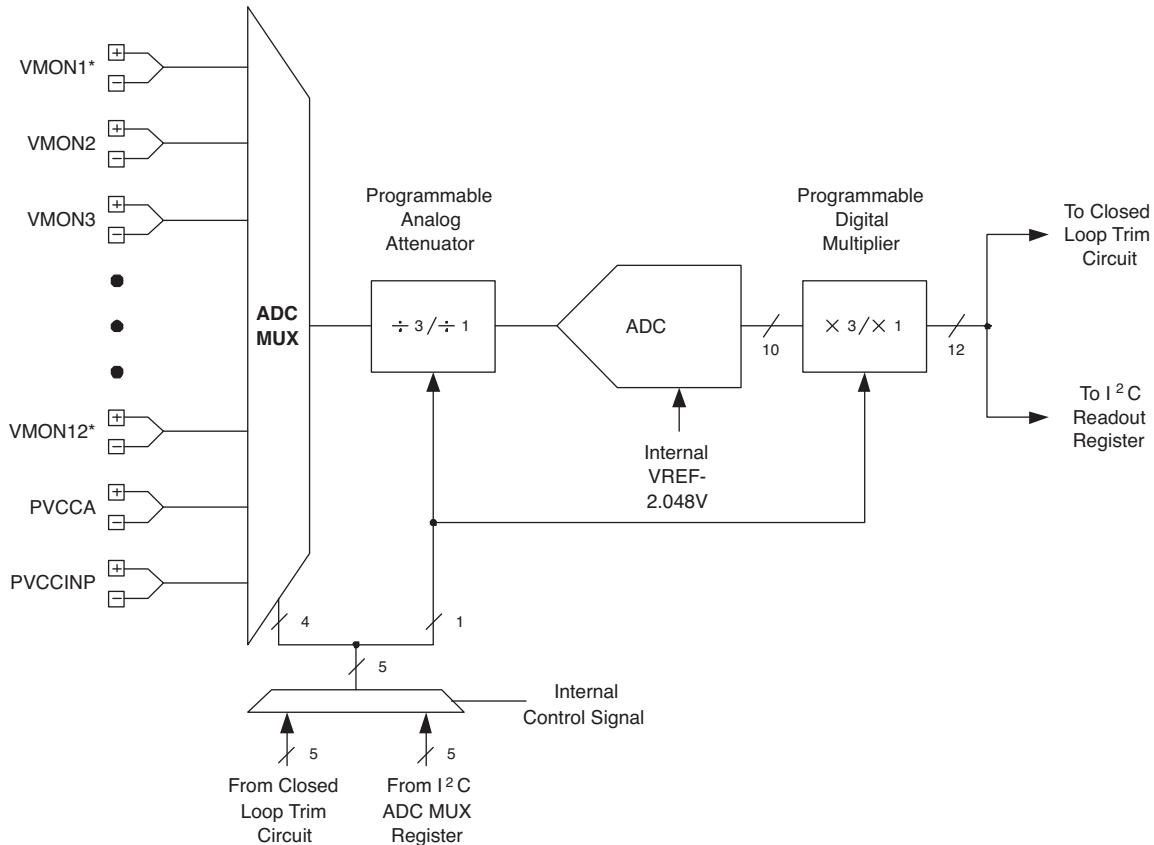
The third section in the Platform Manager’s input voltage monitor is a digital filter. When enabled, the comparator output will be delayed by a filter time constant of 64 µs, and is especially useful for reducing the possibility of false triggering from noise that may be present on the voltages being monitored. When the filter is disabled, the comparator output will be delayed by 16µs. In both cases, enabled or disabled, the filters also provide synchronization of the input signals to the CPLD clock. This synchronous sampling feature effectively eliminates the possibility of race conditions from occurring in any subsequent logic that is implemented in the Platform Manager’s internal CPLD logic.

The comparator status can be read from the I²C interface. For details on the I²C interface, please refer to the I²C/SMBUS Interface section of this data sheet.

VMON Voltage Measurement with the Internal Analog to Digital Converter (ADC)

The Platform Manager has an internal analog to digital converter that can be used for measuring the voltages at the VMON inputs. The ADC is also used in closed loop trimming of DC-DC converters. Close loop trimming is covered later in this document.

Figure 15. ADC Monitoring VMON1 to VMON12



*VMON1 and VMON9 to VMON12 are single-ended inputs for the 128-pin TQFP package option.

Figure 15 shows the ADC circuit arrangement within the Platform Manager device. The ADC can measure all analog input voltages through the multiplexer, ADC MUX. The programmable attenuator between the ADC mux and the ADC can be configured as divided-by-3 or divided-by-1 (no attenuation). The divided-by-3 setting is used to measure voltages from 0V to 6V range and divided-by-1 setting is used to measure the voltages from 0V to 2V range. Note that for the 128-pin TQFP package option, the VMON1 and VMON9 to VMON12 input pins are single-ended inputs, not differential as shown above.

A microcontroller can place a request for any VMON voltage measurement at any time through the I²C bus. Upon the receipt of an I²C command, the ADC will be connected to the I²C selected VMON through the ADC MUX. The ADC output is then latched into the I²C readout registers.

Calculation

The algorithm to convert the ADC code to the corresponding voltage takes into consideration the attenuation bit value. In other words, if the attenuation bit is set, then the 10-bit ADC result is automatically multiplied by 3 to calculate the actual voltage at that V_{MON} input. Thus, the I²C readout register is 12 bits instead of 10 bits. The following formula can always be used to calculate the actual voltage from the ADC code.

Voltage at the VMONx Pins

VMON = ADC code (12 bits¹, converted to decimal) * 2mV

¹Note: ADC_VALUE_HIGH (8 bits), ADC_VALUE_LOW (4 bits) read from I²C/SMBUS interface

Controlling Power Supply Output Voltage by Margin/Trim Block

One of the key features of the Platform Manager is its ability to make adjustments to the power supplies that it may also be monitoring and/or sequencing. This is accomplished through the Trim and Margin Block of the device. The Trim and Margin Block can adjust voltages of up to eight different power supplies through TrimCells as shown in Figure 16. The DC-DC blocks in the figure represent virtually any type of DC power supply that has a trim or voltage adjustment input. This can be an off-the-shelf unit or custom circuit designed around a switching regulator IC.

The interface between the Platform Manager and the DC power supply is represented by a single resistor (R1 to R8) to simplify the diagram. Each of these resistors represents a resistor network.

Other control signals driving the Margin/Trim Block are:

- CPLD_VPS[1:0] – Voltage profile selection signals generated by the CPLD. These control signals are common to all eight TrimCells and are used to select the active voltage profile for all TrimCells together.
- ADC input – Used to determine the trimmed DC-DC converter voltage.
- CPLD_CLT_EN – Only from the CPLD, used to enable closed loop trimming of all TrimCells together.

Next to each DC-DC converter, four voltages are shown. These voltages correspond to the operating voltage profile of the Margin/Trim Block.

When the CPLD_VPS[1:0] = 00, representing Voltage Profile 0: (Voltage Profile 0 is recommended to be used for the normal circuit operation)

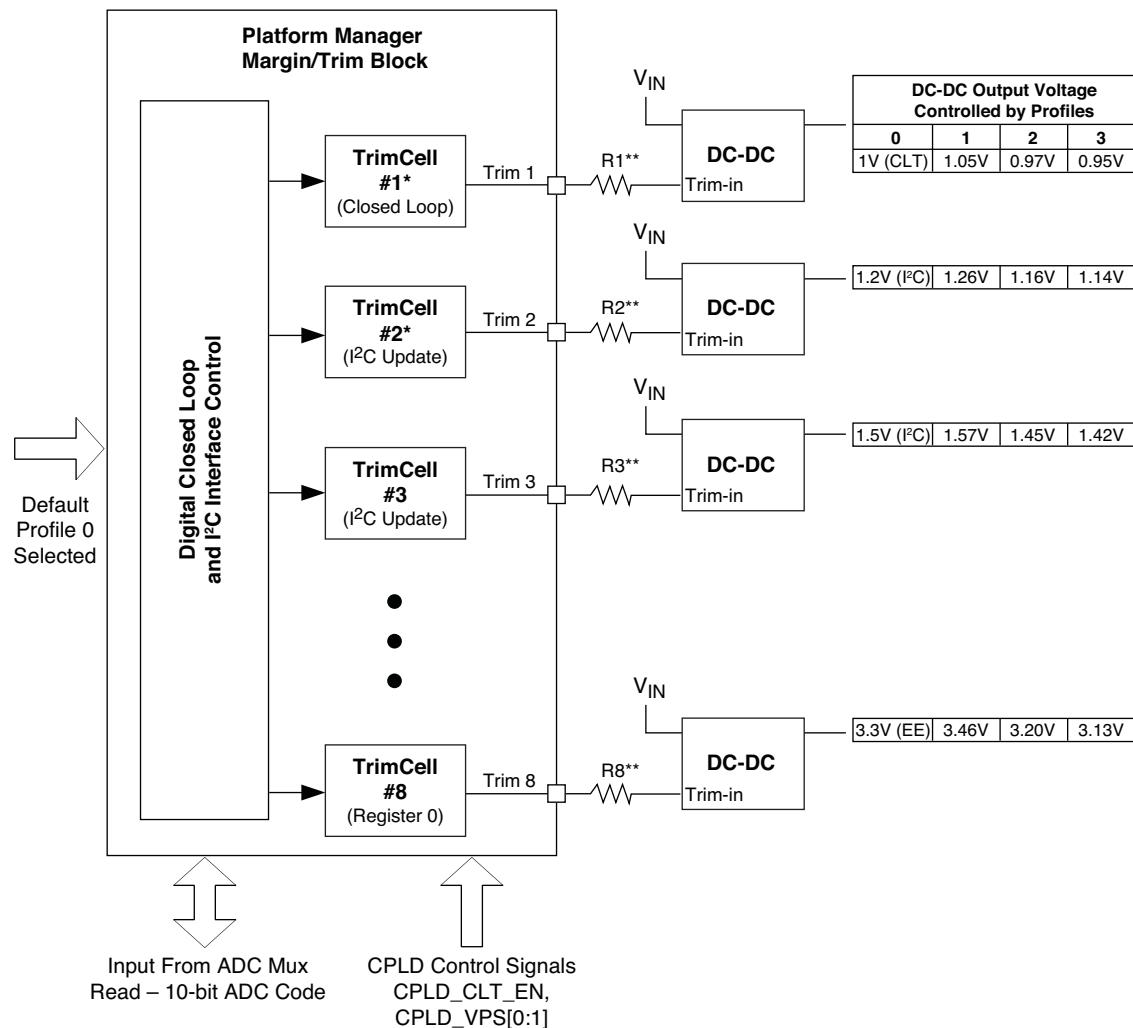
The output voltage of the DC-DC converter controlled by the Trim 1 pin of the Platform Manager will be 1V and that TrimCell is operating in closed loop trim mode. At the same time, the DC-DC converters controlled by Trim 2, Trim 3 and Trim 8 pins output 1.2V, 1.5V and 3.3V respectively.

When the CPLD_VPS[1:0] = 01, representing Voltage Profile 1 being active:

The DC-DC output voltage controlled by Trim 1, 2, 3, and 8 pins will be 1.05V, 1.26V, 1.57V, and 3.46V. These supply voltages correspond to 5% above their respective normal operating voltage (also called as margin high).

Similarly, when CPLD_VPS[1:0] = 11, all DC-DC converters are margined low by 5%.

Figure 16. Platform Manager Trim and Margin Block



There are up to eight TrimCells in the Platform Manager device, enabling simultaneous control of up to eight individual power supplies (six in the 128-pin TQFP package option). Each TrimCell can generate up to four trimming voltages to control the output voltage of the DC-DC converter.

Figure 17. TrimCell Driving a Typical DC-DC Converter

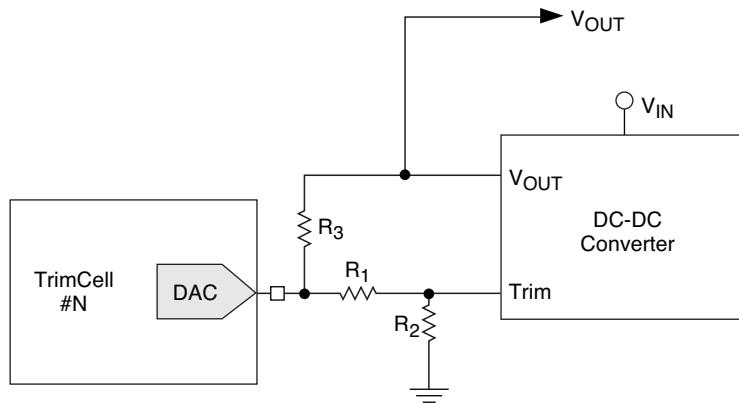
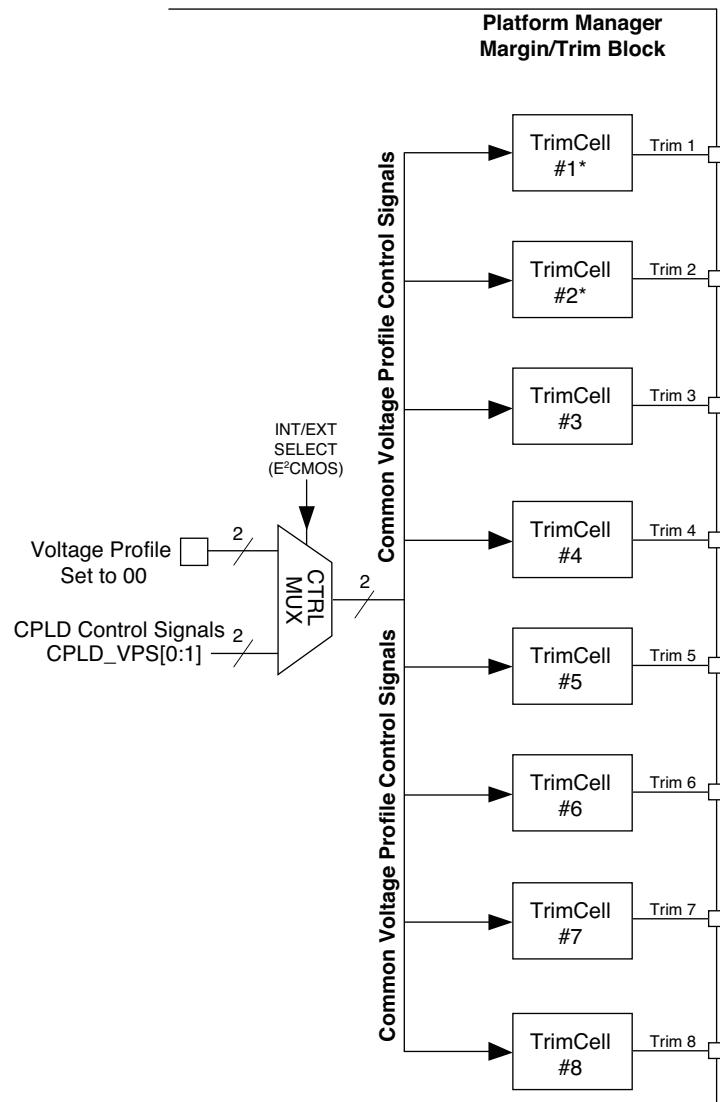


Figure 17 shows the resistor network between the TrimCell #N in the Platform Manager and the DC-DC converter. The values of these resistors depend on the type of DC-DC converter used and its operating voltage range. The method to calculate the values of the resistors R1, R2, and R3 are described in a separate application note.

Voltage Profile Control

The Platform Manager Margin/TrimBlock consists of up to eight TrimCells. Each of these trim cells integrates four output voltage configurations. The operational voltage profile of the TrimCell is determined by two bits called voltage profile selection bits. The TrimBlock provides 2-bit voltage profile selection bits which are shared by all eight TrimCells. The TrimBlock voltage profile can be set to profile zero or can be controlled by the CPLD through signals CPLD_VPS[0:1]. An E²CMOS® configuration bit determines whether the voltage profile control is set to profile 0 or it is controlled by CPLD.

Figure 18. Voltage Profile Control



*TrimCell #1 and TrimCell #2 (Trim 1 and Trim 2) are not available in the 128-pin TQFP package option.

TrimCell Architecture

The TrimCell block diagram is shown in Figure 19. The 8-bit DAC at the output provides the trimming voltage required to set the output voltage of a programmable supply. Each TrimCell can be operated in any one of the four voltage profiles. In each voltage profile the output trimming voltage can be set to a preset value. There are six 8-bit registers in each TrimCell that, depending on the operational mode, set the DAC value. Of these, four DAC values (DAC Register 0 to DAC Register 3) are stored in the E²CMOS memory while the remaining register contents are stored in volatile registers. Two multiplexers (Mode Mux and Profile Mux) control the routing of the code to the DAC. The Profile Mux can be controlled by common TrimCell voltage profile control signals.

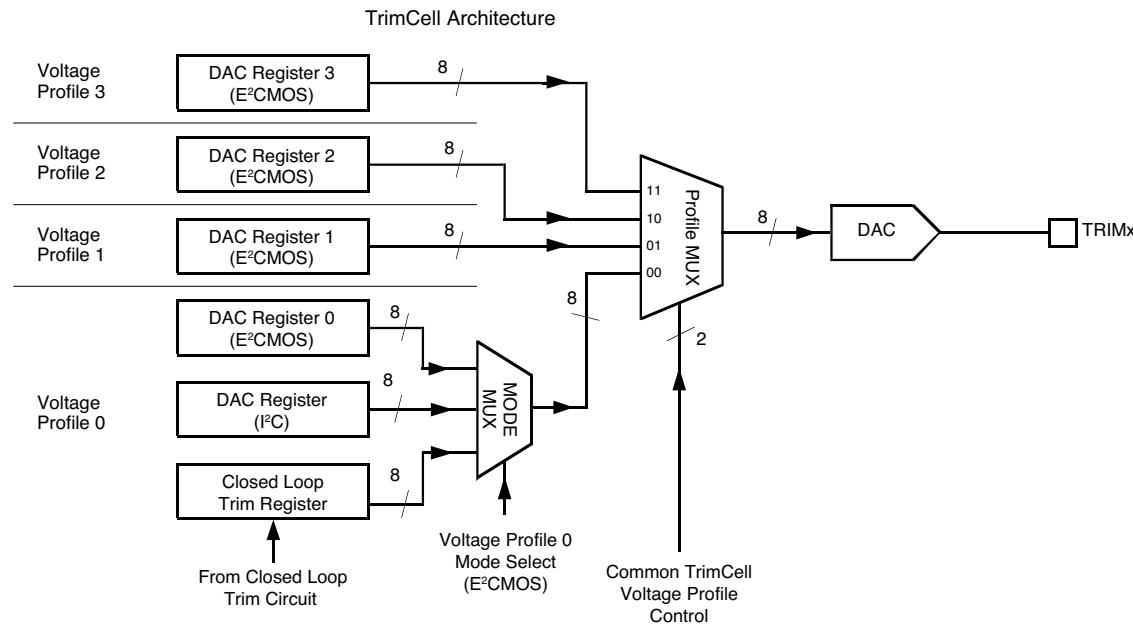
Figure 19. Platform Manager Output TrimCell


Figure 16 shows four power supply voltages next to each DC-DC converter. When the Profile MUX is set to Voltage Profile 3, the DC supply controlled by Trim 1 will be at 0.95V, the DC supply controlled by Trim 2 will be at 1.14V, 1.43V for Trim 3 and 3.14V for Trim 8. When Voltage Profile 0 is selected, Trim 1 will set the supply to 1V, Trim 2 and Trim 3 will be set by the values that have been loaded using I²C at 1.2 and 1.5V, and Trim 8 will be set to 3.3V.

Table 7 summarizes the voltage profile selection and the corresponding DAC output trimming voltage. The voltage profile selection is common to all eight TrimCells.

Table 7. TrimCell Voltage Profile and Operating Modes

CPLD_VPS[1:0]	Selected Voltage Profile	Selected Mode	Trimming Voltage is Controlled by
11	Voltage Profile 3	—	DAC Register 3 (E ² CMOS)
10	Voltage Profile 2	—	DAC Register 2 (E ² CMOS)
01	Voltage Profile 1	—	DAC Register 1 (E ² CMOS)
00	Voltage Profile 0	DAC Register 0 Select	DAC Register 0 (E ² CMOS)
		DAC Register I ² C Select	DAC Register (I ² C)
		Digital Closed Loop Trim	Closed Loop Trim Register

TrimCell Operation in Voltage Profiles 1, 2 and 3: The output trimming voltage is determined by the code stored in the DAC Registers 1, 2, and 3 corresponding to the selected Voltage Profile.

TrimCell Operation in Voltage Profile 0: The Voltage Profile 0 has three operating modes. They are DAC Register 0 Select mode, DAC Register I²C Select mode and Closed Loop Trim mode. The mode selection is stored in the E²CMOS configuration memory. Each of the eight TrimCells can be independently set to different operating modes during Voltage Profile 0 mode of operation.

DAC Register 0 Select Mode: The contents of DAC register 0 are stored in the internal E²CMOS memory. When Voltage Profile 0 is selected, the DAC will be loaded with the value stored in DAC Register 0.

DAC Register I²C Select Mode: This mode is used if the power management arrangement requires an external microcontroller to control the DC-DC converter output voltage. The microcontroller updates the contents of the

DAC Register I²C on the fly to set the trimming voltage to a desired value. The DAC Register I²C is a volatile register and is reset to 80H (DAC at Bipolar zero) upon power-on. The external microcontroller writes the correct DAC code in this DAC Register I²C before enabling the programmable power supply.

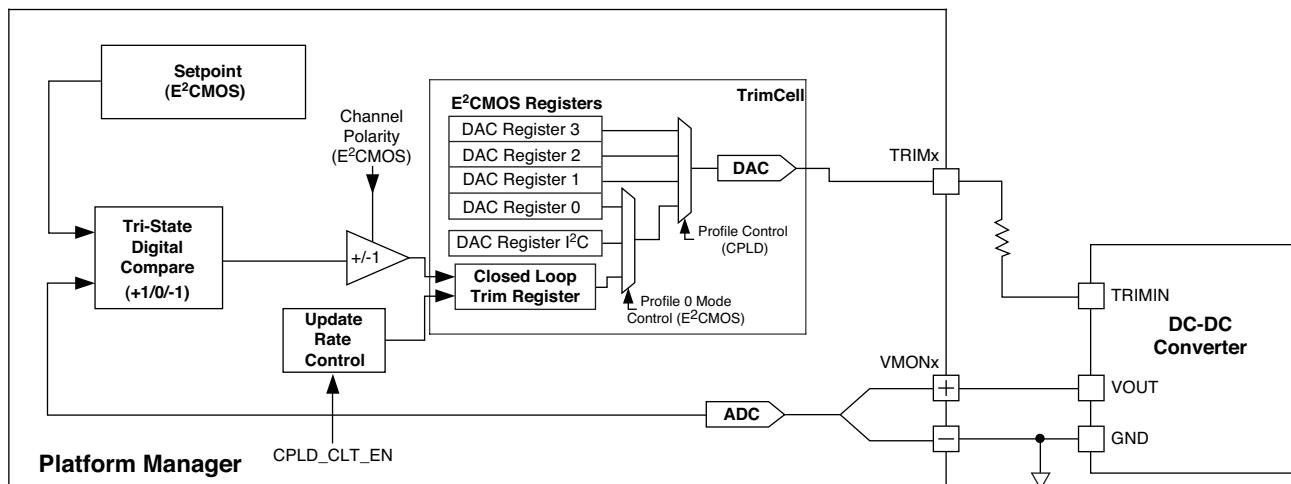
Digital Closed Loop Trim Mode

Closed loop trim mode operation can be used when tight control over the DC-DC converter output voltage at a desired value is required. The closed loop trim mechanism operates by comparing the measured output voltage of the DC-DC converter with the internally stored voltage setpoint. The difference between the setpoint and the actual DC-DC converter voltage generates an error voltage. This error voltage adjusts the DC-DC converter output voltage toward the setpoint. This operation iterates until the setpoint and the DC-DC converter voltage are equal.

Figure 20 shows the closed loop trim operation of a TrimCell. At regular intervals (as determined by the Update Rate Control register) the Platform Manager device initiates the closed loop power supply voltage correction cycle through the following blocks:

- Non-volatile **Setpoint** register stores the desired output voltage
- Internal **ADC** is used to measure the voltage of the DC-DC converter
- **Tri-state comparator** is used to compare the measured voltage from the ADC with the **Setpoint** register contents. The output of the tri-state comparator can be one of the following:
 - +1 if the setpoint voltage is greater than the DC-DC converter voltage
 - -1 if the setpoint voltage is less than the DC-DC converter voltage
 - 0 if the setpoint voltage is equal to the DC-DC converter voltage
- **Channel polarity control** determines the polarity of the error signal
- **Closed loop trim register** is used to compute and store the DAC code corresponding to the error voltage. The contents of the Closed Loop Trim will be incremented or decremented depending on the channel polarity and the tri-state comparator output. If the tri-state comparator output is 0, the closed loop trim register contents are left unchanged.
- The **DAC** in the **TrimCell** is used to generate the analog error voltage that adjusts the attached DC-DC converter output voltage.

Figure 20. Digital Closed Loop Trim Operation



The closed loop trim cycle interval is programmable and is set by the update rate control register. The following table lists the programmable update interval that can be selected by the update rate register.

Table 8. Output DAC Update Rate in Digital Closed Loop Mode

Update Rate Control Value	Update Interval
00	580 µs
01	1.15 ms
10	9.22 ms
11	18.5 ms

There is a one-to-one relationship between the selected TrimCell and the corresponding VMON input for the closed loop operation. For example, if TrimCell 3 is used to control the power supply in the closed loop trim mode, VMON3 must be used to monitor its output power supply voltage.

The closed loop operation can only be started by activating the internally generated CPLD signal, called CPLD_CLT_EN, in PAC-Designer software. The selection of Voltage Profile 0, however, can be either through the fixed default value or through the CPLD signals CPLD_VPS0 and CPLD_VPS1.

Closed Loop Start-up Behavior

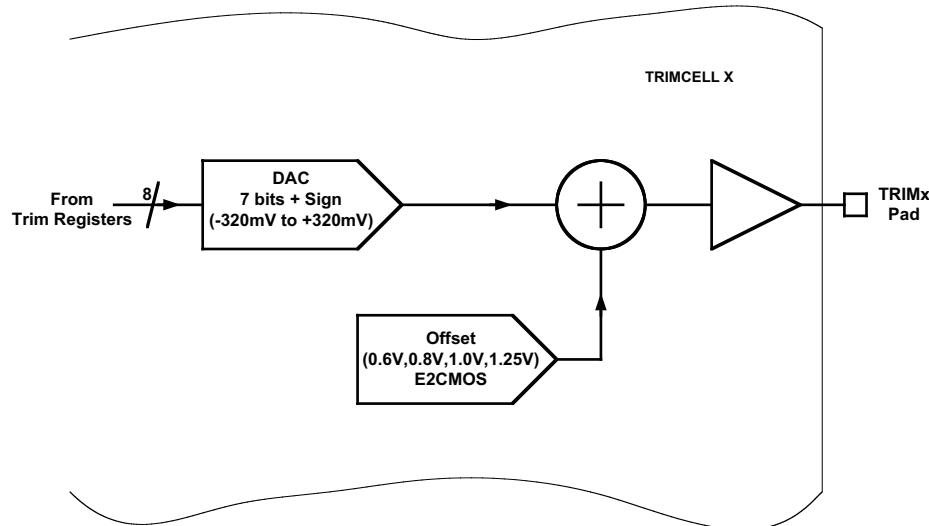
The contents of the closed loop register, upon power-up, will contain a value 80h (Bipolar-zero) value. The DAC output voltage will be equal to the programmed Offset voltage. Usually under this condition, the power supply output will be close to its nominal voltage. If the power supply trimming should start after reaching its desired output voltage, the corresponding DAC code can be loaded into the closed loop trim register through I²C (same address as the DAC register I²C mode) before activating the CPLD_CLT_EN signal.

Details of the Digital to Analog Converter (DAC)

Each trim cell has an 8-bit bipolar DAC to set the trimming voltage (Figure 21). The full-scale output voltage of the DAC is +/- 320 mV. A code of 80H results in the DAC output set at its bi-polar zero value.

The voltage output from the DAC is added to a programmable offset value and the resultant voltage is then applied to the trim output pin. The offset voltage is typically selected to be approximately equal to the DC-DC converter open circuit trim node voltage. This results in maximizing the DC-DC converter output voltage range.

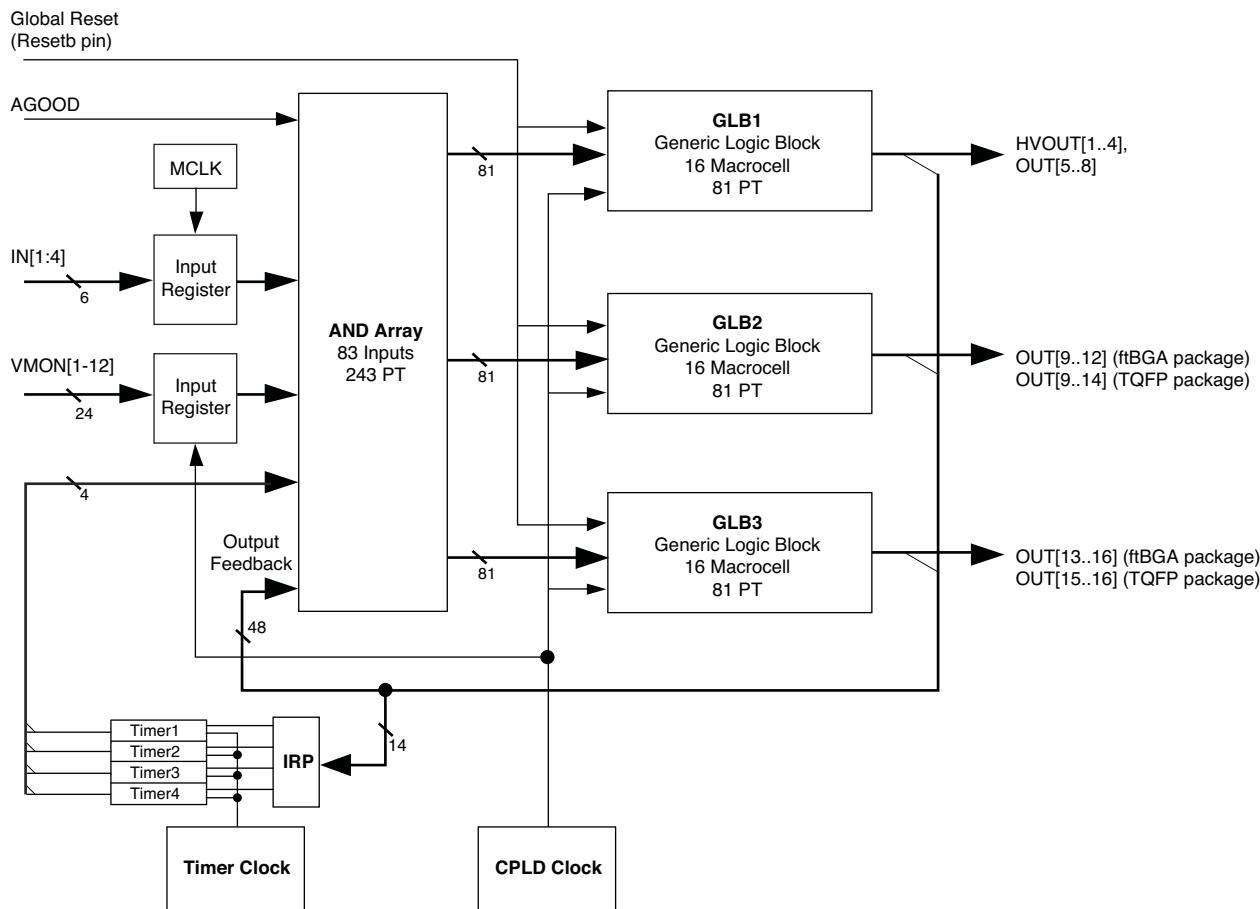
The programmed offset value can be set to 0.6V, 0.8V, 1.0V or 1.25V. This value selection is stored in E²CMOS memory and cannot be changed dynamically.

Figure 21. Offset Voltage is Added to DAC Output Voltage to Derive Trim Pad Voltage


CPLD Block

Figure 22 shows the Platform Manager power management CPLD architecture, which is derived from the Lattice ispMACH® 4000 CPLD. The power management CPLD architecture allows the flexibility in designing various state machines and control functions used for power supply management. The AND array has 83 inputs and generates 243 product terms. These 243 product terms are divided into three groups of 81 for each of the generic logic blocks, GLB1, GLB2, and GLB3. Each GLB is made up of 16 macrocells. In total, there are 48 macrocells in the Platform Manager device. The output signals of the Platform Manager device are derived from GLBs as shown in Figure 22. Additionally, GLB3 generates the timer control.

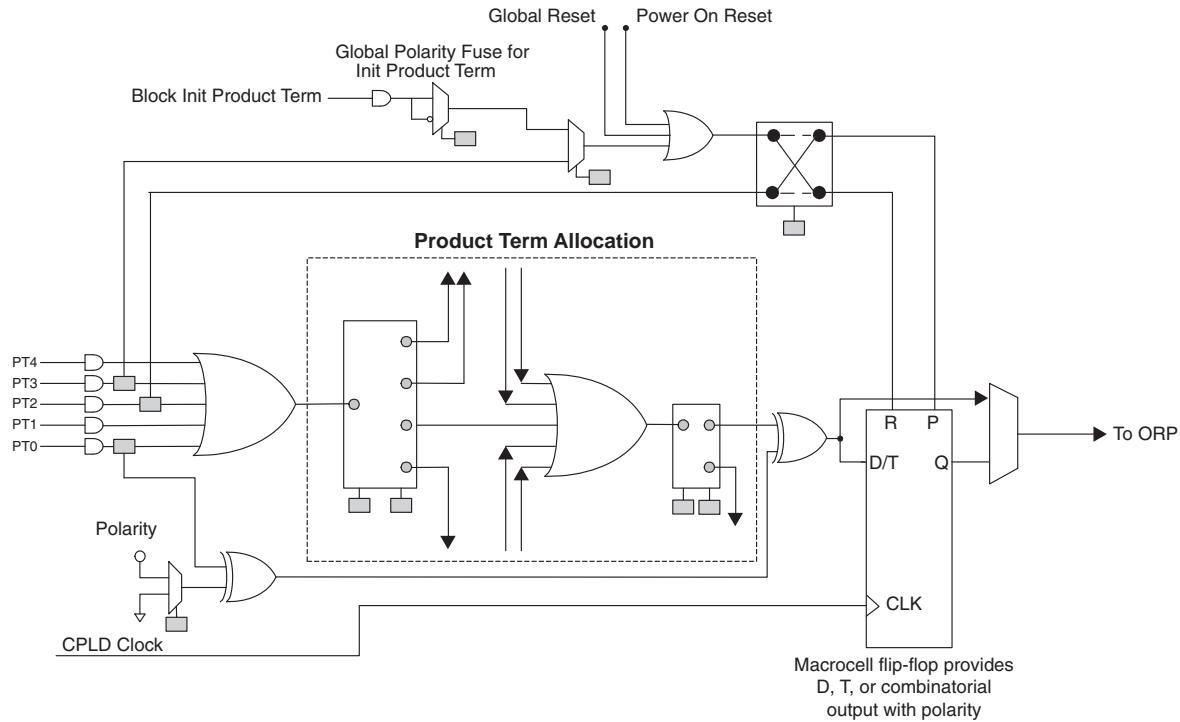
Figure 22. Platform Manager CPLD Architecture



Macrocell Architecture

The macrocell shown in Figure 23 is the heart of the CPLD. The basic macrocell has five product terms that feed the OR gate and the flip-flop. The flip-flop in each macrocell is independently configured. It can be programmed to function as a D-Type or T-Type flip-flop. Combinatorial functions are realized by bypassing the flip-flop. The polarity control and XOR gates provide additional flexibility for logic synthesis. The flip-flop's clock is driven from the common CPLD clock that is generated by dividing the 8 MHz master clock (MCLK) by 32. The macrocell also supports asynchronous reset and preset functions, derived from either product terms, the global reset input, or the power-on reset signal. The resources within the macrocells share routing and contain a product term allocation array. The product term allocation array greatly expands the CPLD's ability to implement complex logical functions by allowing logic to be shared between adjacent blocks and distributing the product terms to allow for wider decode functions. All the digital inputs are registered by MCLK and the VMON comparator outputs are registered by the CPLD Clock to synchronize them to the CPLD logic.

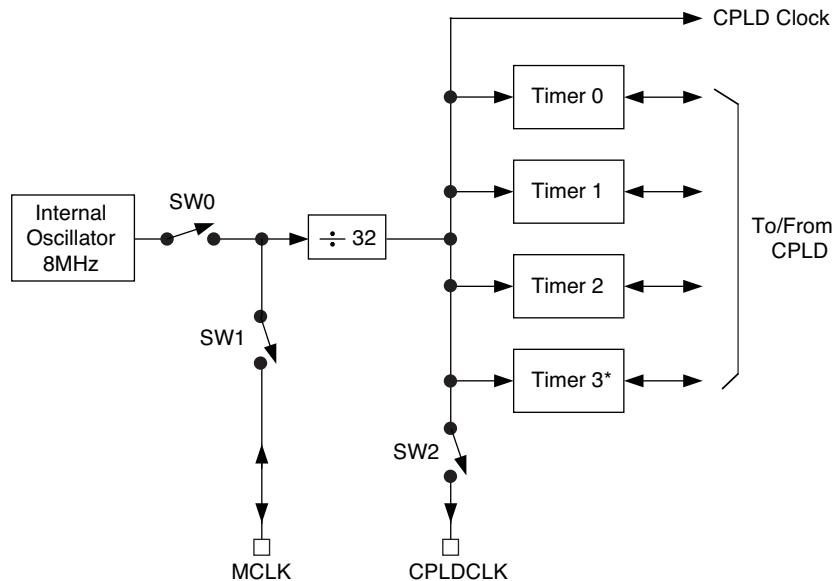
Figure 23. Macrocell Block Diagram



Clock and Timer Functions

Figure 24 shows a block diagram of the Platform Manager's internal clock and timer systems. The master clock operates at a fixed frequency of 8MHz, from which a fixed 250kHz CPLD clock is derived.

Figure 24. Clock and Timer System



*Used as part of FPGA timer functionality.

The internal oscillator runs at a fixed frequency of 8 MHz. This signal is used as a source for the CPLD and timer clocks. It is also used for clocking the comparator outputs and clocking the digital filters in the voltage monitor cir-

cuits, ADC and trim circuits. The Platform Manager can be programmed to operate in two modes: Master mode and Slave mode. Table 9 summarizes the operating modes of Platform Manager.

Table 9. Platform Manager Operating Modes

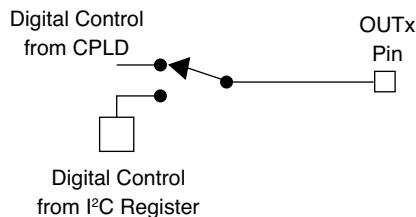
Timer Operating Mode	SW0	SW1	Condition	Comments
Master	Closed	Closed	When more than one Platform Manager is used in a board, one of them should be configured to operate in this mode.	MCLK pin outputs 8MHz clock
Slave	Open	Closed	When more than one Platform Managers is used in a board. Other than the master, the rest of the Platform Managers should be programmed as slaves.	MCLK pin is input

A divide-by-32 prescaler divides the internal 8MHz oscillator (or external clock, if selected) down to 250kHz for the CPLD clock and for the programmable timers. This CPLD clock may be made available on the CPLDCLK pin by closing SW2. Each of the four timers provides independent timeout intervals ranging from 32 µs to 1.96 seconds in 128 steps.

CPLD Digital Outputs

The Platform Manager provides 20 digital outputs, HVOUT[1:4] and OUT[5:16]. Outputs OUT[5:16] are permanently configured as open drain to provide a high degree of flexibility when interfacing to logic signals, LEDs, opto-couplers, and power supply control inputs. The HVOUT[1:4] pins can be configured as either high voltage FET drivers or open drain outputs. Each of these outputs may be controlled either from the CPLD or from the I²C bus. The determination whether a given output is under CPLD or I²C control may be made on a pin-by-pin basis (see Figure 25). For further details on controlling the outputs through I²C, please see the I²C/SMBUS Interface section of this data sheet.

Figure 25. Digital Output Pin Configuration



High Voltage Outputs

In addition to being usable as digital open-drain outputs, the Platform Manager's HVOUT1-HVOUT4 output pins can be programmed to operate as high-voltage FET drivers. Figure 26 shows the details of the HVOUT gate drivers. Each of these outputs may be controlled from the CPLD or from the I²C bus (see Figure 26). For further details on controlling the outputs through I²C, please see the I²C/SMBUS Interface section of this data sheet.

Figure 26. Basic Function Diagram for an Output in High Voltage MOSFET Gate Driver Mode

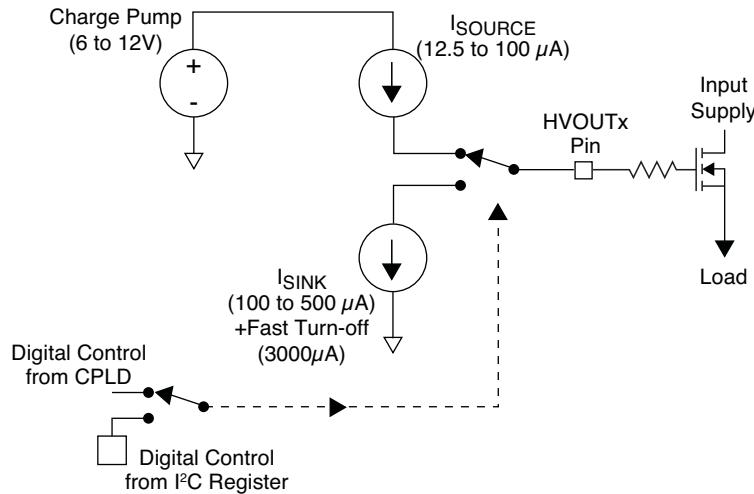


Figure 26 shows the HVOUT circuitry when programmed as a FET driver. In this mode the output either sources current from a charge pump or sinks current. The maximum voltage that the output level at the pin will rise to is also programmable between 6V and 12V. The maximum voltage levels that are required depend on the gate-to-source threshold of the FET being driven and the power supply voltage being switched. The maximum voltage level needs to be sufficient to bias the gate-to-source threshold on and also accommodate the load voltage at the FET's source, since the source pin of the FET to provide a wide range of ramp rates is tied to the supply of the target board. When the HVOUT pin is sourcing current, charging a FET gate, the source current is programmable between 12.5μA and 100μA. When the driver is turned to the off state, the driver will sink current to ground, and this sink current is also programmable between 3000μA and 100μA to control the turn-off rate.

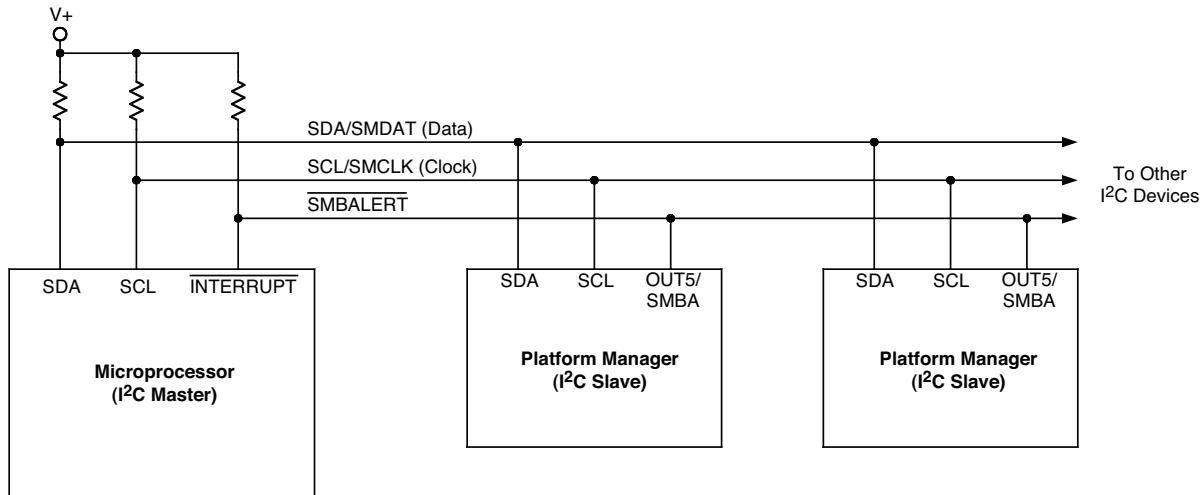
Programmable Output Voltage Levels for HVOUT1- HVOUT4

There are four selectable steps for the output voltage of the FET drivers when in FET driver mode. The voltage that the pin is capable of driving to can be programmed from 6V to 12V in 2V steps.

Power I²C/SMBUS Interface

I²C and SMBus are low-speed serial interface protocols designed to enable communications among a number of devices on a circuit board. The Platform Manager supports a 7-bit addressing of the I²C communications protocol, as well as SMBTimeout and SMBAlert features of the SMBus, enabling it to easily integrated into many types of modern power management systems. Figure 27 shows a typical I²C configuration, in which one or more Platform Managers are slaved to a supervisory microcontroller. SDA is used to carry data signals, while SCL provides a synchronous clock signal. The SMBAlert line is only present in SMBus systems. The 7-bit I²C address is fully programmable through the power JTAG port.

Figure 27. Platform Manager in I²C/SMBus System



In both the I²C and SMBus protocols, the bus is controlled by a single master device at any given time. This master device generates the SCL clock signal and coordinates all data transfers to and from a number of slave devices. The Platform Manager is configured as a slave device, and cannot independently coordinate data transfers. Each slave device on a given I²C bus is assigned a unique address. The Platform Manager implements the 7-bit addressing portion of the standard. Any 7-bit address can be assigned to the Platform Manager device by programming through JTAG. When selecting a device address, one should note that several addresses are reserved by the I²C and/or SMBus standards, and should not be assigned to Platform Manager devices to assure bus compatibility. Table 10 lists these reserved addresses.

Table 10. I²C/SMBus Reserved Slave Device Addresses

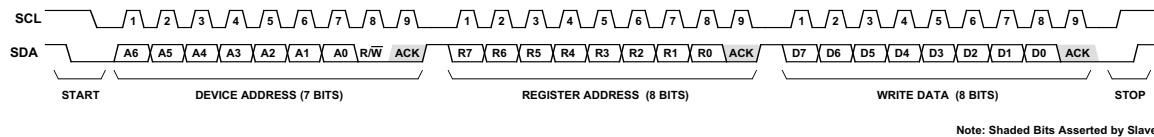
Address	R/W bit	I ² C function Description	SMBus Function
0000 000	0	General Call Address	General Call Address
0000 000	1	Start Byte	Start Byte
0000 001	x	CBUS Address	CBUS Address
0000 010	x	Reserved	Reserved
0000 011	x	Reserved	Reserved
0000 1xx	x	HS-mode master code	HS-mode master code
0001 000	x	NA	SMBus Host
0001 100	x	NA	SMBus Alert Response Address
0101 000	x	NA	Reserved for ACCESS.bus
0110 111	x	NA	Reserved for ACCESS.bus
1100 001	x	NA	SMBus Device Default Address
1111 0xx	x	10-bit addressing	10-bit addressing
1111 1xx	x	Reserved	Reserved

The Platform Manager's I²C/SMBus interface allows data to be both written to and read from the device. A data write transaction (Figure 28) consists of the following operations:

1. Start the bus transaction
2. Transmit the device address (7 bits) along with a low write bit
3. Transmit the address of the register to be written to (8 bits)
4. Transmit the data to be written (8 bits)
5. Stop the bus transaction

To start the transaction, the master device holds the SCL line high while pulling SDA low. Address and data bits are then transferred on each successive SCL pulse, in three consecutive byte frames of nine SCL pulses. Address and data are transferred on the first 8 SCL clocks in each frame, while an acknowledge signal is asserted by the slave device on the 9th clock in each frame. Both data and addresses are transferred in a most-significant-bit-first format. The first frame contains the 7-bit device address, with bit 8 held low to indicate a write operation. The second frame contains the register address to which data will be written, and the final frame contains the actual data to be written. Note that the SDA signal is only allowed to change when the SCL is low, as raising SDA when SCL is high signals the end of the transaction.

Figure 28. I²C Write Operation

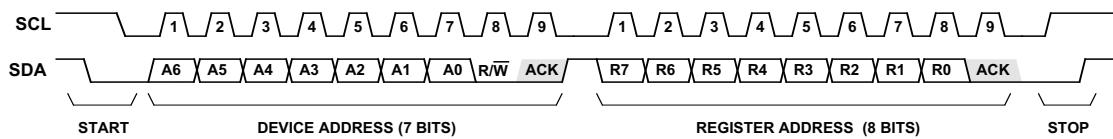


Note: Shaded Bits Asserted by Slave

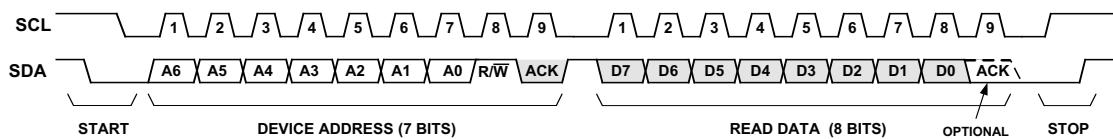
Reading a data byte from the Platform Manager requires two separate bus transactions (Figure 29). The first transaction writes the register address from which a data byte is to be read. Note that since no data is being written to the device, the transaction is concluded after the second byte frame. The second transaction performs the actual read. The first frame contains the 7-bit device address with the R/W bit held High. In the second frame the Platform Manager asserts data out on the bus in response to the SCL signal. Note that the acknowledge signal in the second frame is asserted by the master device and not the Platform Manager.

Figure 29. I²C Read Operation

STEP 1: WRITE REGISTER ADDRESS FOR READ OPERATION



STEP 2: READ DATA FROM THAT REGISTER



Note: Shaded Bits Asserted by Slave

The Platform Manager provides 26 registers that can be accessed through its I²C interface. These registers provide the user with the ability to monitor and control the device's inputs and outputs, and transfer data to and from the device. Table 11 provides a summary of these registers.

Table 11. I²C Control Registers

Register Address	Register Name	Read/Write	Description	Value After POR ^{1,2}
0x00	vmon_status0	R	VMON input status Vmon[4:1]	----- -----
0x01	vmon_status1	R	VMON input status Vmon[8:5]	----- -----
0x02	vmon_status2	R	VMON input status Vmon[12:9]	----- -----
0x03	output_status0	R	Output status OUT[8:5], HVOUT[4:1]	----- -----
0x04	output_status1	R	Output status OUT[12:9] 208-ball ftBGA package	X 12 11 X 10 9 XX
			Output status OUT[14:9] 128-pin TQFP package	14 X X 13 10 9 12 11
0x05	output_status2	R	Output status OUT[16:13] 208-ball ftBGA package	X X X X 16 15 14 13
			Output status OUT[16:15] 128-pin TQFP package	----- 16 15 X X
0x06	input_status	R	Input status IN[4:1]	X X X X -----
0x07	adc_value_low	R	ADC D[3:0] and status	----- XXXX 1
0x08	adc_value_high	R	ADC D[11:4]	----- -----
0x09	adc_mux	R/W	ADC Attenuator and MUX[3:0]	X X X 1 1 1 1
0x0A	UES_byte0	R	UES[7:0]	----- -----
0x0B	UES_byte1	R	UES[15:8]	----- -----
0x0C	UES_byte2	R	UES[23:16]	----- -----
0x0D	UES_byte3	R	UES[31:24]	----- -----
0x0E	gp_output1	R/W	GPOUT[8:1]	0 0 0 1 0 0 0 0
0x0F	gp_output2	R/W	GPOUT[12:9] 208-ball ftBGA package	X 12 11 X 10 9 XX
			GPOUT[14:9] 128-pin TQFP package	14 X X 13 10 9 12 11
0x10	gp_output3	R/W	GPOUT[16:13] 208-ball ftBGA package	X X X X 16 15 14 13
			GPOUT[16:15] 128-pin TQFP package	----- 16 15 X X
0x11	input_value	R/W	CPLD Input Register [6:2]	X X 0 0 0 0 X
0x12	reset	W	Resets device on write	N/A
0x13	trim1_trim	R/W	Trim DAC 1 [7:0] ³	1 0 0 0 0 0 0 0
0x14	trim2_trim	R/W	Trim DAC 2 [7:0] ³	1 0 0 0 0 0 0 0
0x15	trim3_trim	R/W	Trim DAC 3 [7:0]	1 0 0 0 0 0 0 0
0x16	trim4_trim	R/W	Trim DAC 4 [7:0]	1 0 0 0 0 0 0 0
0x17	trim5_trim	R/W	Trim DAC 5 [7:0]	1 0 0 0 0 0 0 0
0x18	trim6_trim	R/W	Trim DAC 6 [7:0]	1 0 0 0 0 0 0 0
0x19	trim7_trim	R/W	Trim DAC 7 [7:0]	1 0 0 0 0 0 0 0
0x1A	trim8_trim	R/W	Trim DAC 8 [7:0]	1 0 0 0 0 0 0 0

1. "X" = Undefined output states can be observed.

2. "—" = State depends on device configuration or input status. For words 0x04 and 0x05, specific outputs corresponding to bit positions are called out. In all other cases, bits correspond to the order called out in the Description column.

3. Trim DAC 1 and Trim DAC 2 are not available in the 128-pin TQFP package option.

Several registers are provided for monitoring the status of the analog inputs. The three registers VMON_STATUS[0:2] provide the ability to read the status of the VMON output comparators. The ability to read both the 'a' and 'b' comparators from each VMON input is provided through the VMON input registers. Note that if

a VMON input is configured to window comparison mode, then the corresponding VMONxA register bit will reflect the status of the window comparison.

Figure 30. VMON Status Registers

0x00 - VMON_STATUS0 (Read Only)

VMON4B	VMON4A	VMON3B	VMON3A	VMON2B	VMON2A	VMON1B	VMON1A
b7	b6	b5	b4	b3	b2	b1	b0

0x01 - VMON_STATUS1 (Read Only)

VMON8B	VMON8A	VMON7B	VMON7A	VMON6B	VMON6A	VMON5B	VMON5A
b7	b6	b5	b4	b3	b2	b1	b0

0x02 - VMON_STATUS2 (Read Only)

VMON12B	VMON12A	VMON11B	VMON11A	VMON10B	VMON10A	VMON9B	VMON9A
b7	b6	b5	b4	b3	b2	b1	b0

It is also possible to directly read the value of the voltage present on any of the VMON inputs by using the Platform Manager's ADC. Three registers provide the I²C interface to the ADC (Figure 31).

Figure 31. ADC Interface Registers

0x07 - ADC_VALUE_LOW (Read Only)

D3	D2	D1	D0	1	1	1	DONE
b7	b6	b5	b4	b3	b2	b1	b0

0x08 - ADC_VALUE_HIGH (Read Only)

D11	D10	D9	D8	D7	D6	D5	D4
b7	b6	b5	b4	b3	b2	b1	b0

0x09 - ADC_MUX (Read/Write)

X	X	X	ATTEN	SEL3	SEL2	SEL1	SEL0
b7	b6	b5	b4	b3	b2	b1	b0

To perform an A/D conversion, one must set the input attenuator and channel selector. Two input ranges may be set using the attenuator, 0 to 2.048V and 0 to 6.144V. Table 12 shows the input attenuator settings.

Table 12. ADC Input Attenuator Control

ATTEN (ADC_MUX.4)	Resolution	Full-Scale Range
0	2mV	2.048 V
1	6mV	6.144 V

The input selector may be set to monitor any one of the twelve VMON inputs, the PVCCA input, or the PVCCINP input. Table 13 shows the codes associated with each input selection.

Table 13. V_{MON} Address Selection Table

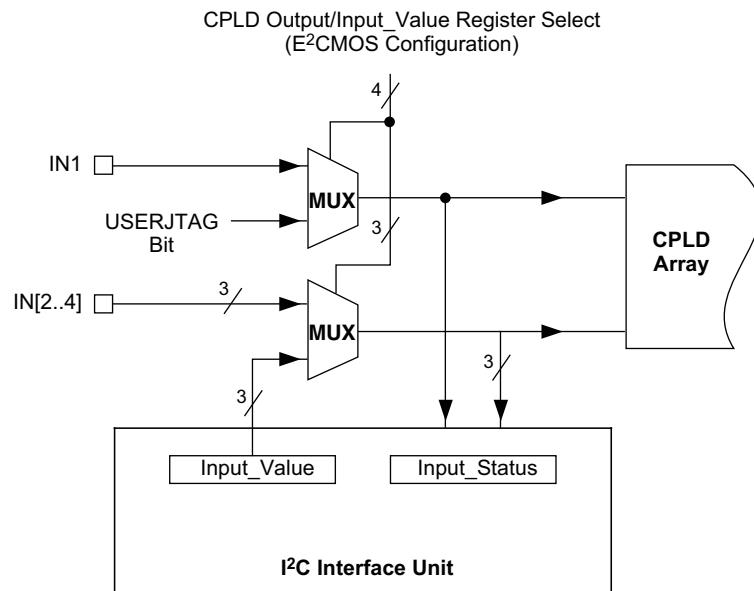
Select Word				Input Channel
SEL3 (ADC_MUX.3)	SEL2 (ADC_MUX.2)	SEL1 (ADC_MUX.1)	SEL0 (ADC_MUX.0)	
0	0	0	0	VMON1
0	0	0	1	VMON2
0	0	1	0	VMON3
0	0	1	1	VMON4
0	1	0	0	VMON5
0	1	0	1	VMON6
0	1	1	0	VMON7
0	1	1	1	VMON8
1	0	0	0	VMON9
1	0	0	1	VMON10
1	0	1	0	VMON11
1	0	1	1	VMON12
1	1	0	0	PVCCA
1	1	0	1	PVCCINP

Writing a value to the ADC_MUX register to set the input attenuator and selector will automatically initiate a conversion. When the conversion is in process, the DONE bit (ADC_VALUE_LOW.0) will be reset to 0. When the conversion is complete, this bit will be set to 1. When the conversion is complete, the result may be read out of the ADC by performing two I²C read operations; one for ADC_VALUE_LOW, and one for ADC_VALUE_HIGH. It is recommended that the I²C master load a second conversion command only after the completion of the current conversion command (Waiting for the DONE bit to be set to 1). An alternative would be to wait for a minimum specified time (see T_{CONVERT} value in the specifications) and disregard checking the DONE bit.

Note that if the I²C clock rate falls below 50kHz (see F_{I2C} note in specifications), the only way to insure a valid ADC conversion is to wait the minimum specified time (T_{CONVERT}), as the operation of the DONE bit at clock rates lower than that cannot be guaranteed. In other words, if the I²C clock rate is less than 50kHz, the DONE bit may or may not assert even though a valid conversion result is available.

To insure every ADC conversion result is valid, preferred operation is to clock I²C at more than 50kHz and verify DONE bit status or wait for the full T_{CONVERT} time period between subsequent ADC convert commands. If an I²C request is placed before the current conversion is complete, the DONE bit will be set to 1 only after the second request is complete.

The status of the digital input lines may also be monitored and controlled through I²C commands. Figure 32 shows the I²C interface to the IN[1:4] digital input lines. The input status may be monitored by reading the INPUT_STATUS register, while input values to the CPLD array may be set by writing to the INPUT_VALUE register. To be able to set an input value for the CPLD array, the input multiplexer associated with that bit needs to be set to the I²C register setting in E²CMOS memory otherwise the CPLD will receive its input from the INx pin.

Figure 32. I²C Digital Input Interface

0x06 - INPUT_STATUS (Read Only)

X	X	X	X	IN4	IN3	IN2	IN1
b7	b6	b5	b4	b3	b2	b1	b0

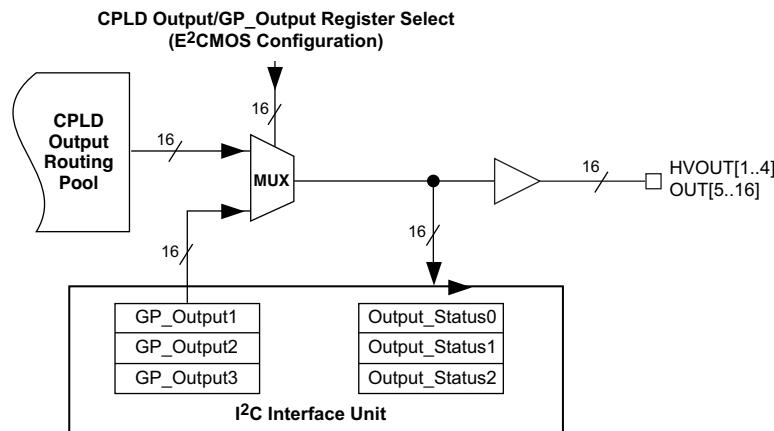
0x11 - INPUT_VALUE (Read/Write)

X	X	I6*	I5*	I4	I3	I2	X
b7	b6	b5	b4	b3	b2	b1	b0

*I5 and I6 are internal inputs to the CPLD that can only be configured by writing them via the I²C interface (no external pin connection).

The CPLD digital outputs may also be monitored and controlled through the I²C interface, as shown in Figure 33. The status of any given digital output may be read by reading the contents of the associated OUTPUT_STATUS[2:0] register. Note that in the case of the outputs, the status reflected by these registers reflects the logic signal used to drive the pin, and does not sample the actual level present on the output pin. For example, if an output is set high but is not pulled up, the output status bit corresponding with that pin will read '1', but a high output signal will not appear on the pin. Digital inputs I5 and I6 are only accessible via the I²C interface. In other words, there are no external pin connections to these two inputs.

Digital outputs may also be optionally controlled directly by the I²C bus instead of by the CPLD array. The outputs may be driven either from the CPLD ORP or from the contents of the GP_OUTPUT[2:0] registers with the choice user-settable in E²CMOS memory. Each output may be independently set to output from the CPLD or from the GP_OUTPUT registers.

Figure 33. I²C Output Monitor and Control Logic

0x03 - OUTPUT_STATUS0 (Read Only)

OUT8	OUT7	OUT6	OUT5	HVOUT4	HVOUT3	HVOUT2	HVOUT1
b7	b6	b5	b4	b3	b2	b1	b0

0x04 - OUTPUT_STATUS1 (Read Only), 208-ball ftBGA package option

X	OUT12	OUT11	X	OUT10	OUT9	X	X
b7	b6	b5	b4	b3	b2	b1	b0

0x05 - OUTPUT_STATUS2 (Read Only), 208-ball ftBGA package option

X	X	X	X	OUT16	OUT15	OUT14	OUT13
b7	b6	b5	b4	b3	b2	b1	b0

0x04 - OUTPUT_STATUS1 (Read Only), 128-pin TQFP package option

OUT14	X	X	OUT13	OUT10	OUT9	OUT11	OUT12
b7	b6	b5	b4	b3	b2	b1	b0

0x05 - OUTPUT_STATUS2 (Read Only), 128-pin TQFP package option

X	X	X	X	OUT16	OUT15	X	X
b7	b6	b5	b4	b3	b2	b1	b0

0x0E - GP_OUTPUT1 (Read/Write)

GP8	GP7	GP6	GP5_ENb	GP4	GP3	GP2	GP1
b7	b6	b5	b4	b3	b2	b1	b0

0x0F - GP_OUTPUT2 (Read/Write), 208-ball ftBGA package option

X	GP12	GP11	X	GP10	GP9	X	X
b7	b6	b5	b4	b3	b2	b1	b0

0x10 - GP_OUTPUT3 (Read/Write), 208-ball ftBGA package option

X	X	X	X	GP16	GP15	GP14	GP13
b7	b6	b5	b4	b3	b2	b1	b0

0x0F - GP_OUTPUT2 (Read/Write), 128-pin TQFP package option

GP14	X	X	GP13	GP10	GP9	GP11	GP12
b7	b6	b5	b4	b3	b2	b1	b0

0x10 - GP_OUTPUT3 (Read/Write), 128-pin TQFP package option

X	X	X	X	GP16	GP15	X	X
b7	b6	b5	b4	b3	b2	b1	b0

The UES word may also be read through the I²C interface, with the register mapping shown in Figure 34.

Figure 34. I²C Register Mapping for UES Bits

0x0A - UES_BYTE0 (Read Only)

UES7	UES6	UES5	UES4	UES3	UES2	UES1	UES0
b7	b6	b5	b4	b3	b2	b1	b0

0x0B - UES_BYTE1 (Read Only)

UES15	UES14	UES13	UES12	UES11	UES10	UES9	UES8
b7	b6	b5	b4	b3	b2	b1	b0

0x0C - UES_BYTE2 (Read Only)

UES23	UES22	UES21	UES20	UES19	UES18	UES17	UES16
b7	b6	b5	b4	b3	b2	b1	b0

0x0D - UES_BYTE3 (Read Only)

UES31	UES30	UES29	UES28	UES27	UES26	UES25	UES24
b7	b6	b5	b4	b3	b2	b1	b0

The I²C interface also provides the ability to initiate reset operations. The Platform Manager may be reset by issuing a write of any value to the I²C RESET register (Figure 35). Note: The execution of the I²C reset command is equivalent to toggling the Resetb pin of the device. Refer to the Resetb Signal, RESET Command via JTAG or I²C section of this data sheet for further information.

Figure 35. I²C Reset Register

0x12 - RESET (Write Only)

X	X	X	X	X	X	X	X
b7	b6	b5	b4	b3	b2	b1	b0

The Platform Manager also provides the user with the ability to program the trim values over the I²C interface, by writing the appropriate binary word to the associated trim register (Figure 36).

Figure 36. I²C Trim Registers

0x13 - TRIM1_TRIM (Read/Write)*

D7	D6	D5	D4	D3	D2	D1	D0
b7	b6	b5	b4	b3	b2	b1	b0

0x14 - TRIM2_TRIM (Read/Write)*

D7	D6	D5	D4	D3	D2	D1	D0
b7	b6	b5	b4	b3	b2	b1	b0

0x15 - TRIM3_TRIM (Read/Write)

D7	D6	D5	D4	D3	D2	D1	D0
b7	b6	b5	b4	b3	b2	b1	b0

0x16 - TRIM4_TRIM (Read/Write)

D7	D6	D5	D4	D3	D2	D1	D0
b7	b6	b5	b4	b3	b2	b1	b0

0x17 - TRIM5_TRIM (Read/Write)

D7	D6	D5	D4	D3	D2	D1	D0
b7	b6	b5	b4	b3	b2	b1	b0

0x18 - TRIM6_TRIM (Read/Write)

D7	D6	D5	D4	D3	D2	D1	D0
b7	b6	b5	b4	b3	b2	b1	b0

0x19 - TRIM7_TRIM (Read/Write)

D7	D6	D5	D4	D3	D2	D1	D0
b7	b6	b5	b4	b3	b2	b1	b0

0x1A - TRIM8_TRIM (Read/Write)

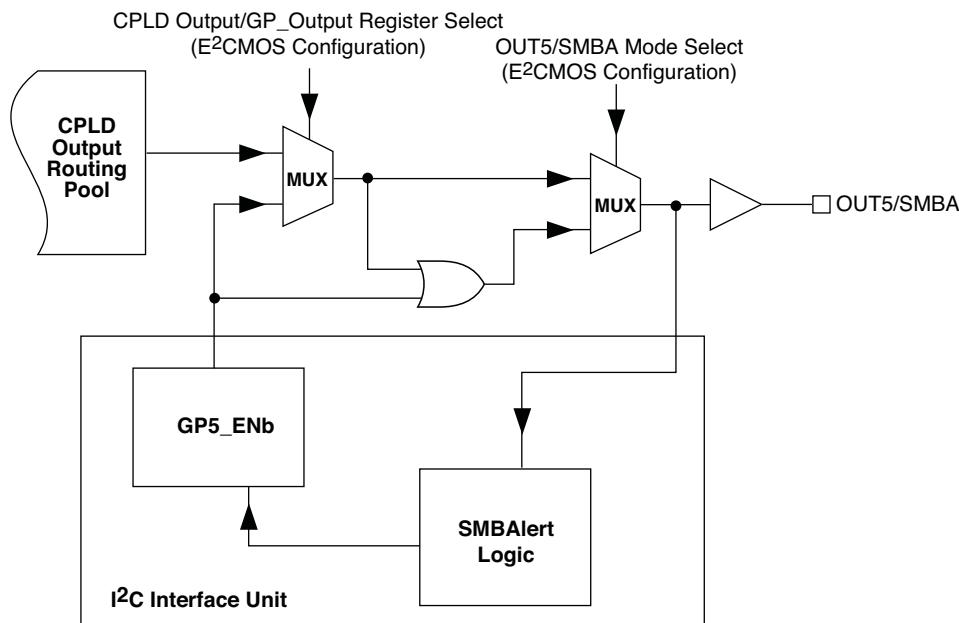
D7	D6	D5	D4	D3	D2	D1	D0
b7	b6	b5	b4	b3	b2	b1	b0

*0x13 Trim 1 and 0x14 Trim 2 I²C registers are not available with 128-pin TQFP package option.

SMBus SMBAlert Function

The Platform Manager provides an SMBus SMBAlert function so that it can request service from the bus master when it is used as part of an SMBus system. This feature is supported as an alternate function of OUT5. When the SMBAlert feature is enabled, OUT5 is controlled by a combination of the CPLD ORP and the GP5_ENb bit (Figure 37). Note: To enable the SMBAlert feature, the SMB_Mode (E^2CMOS bit) should be set in software.

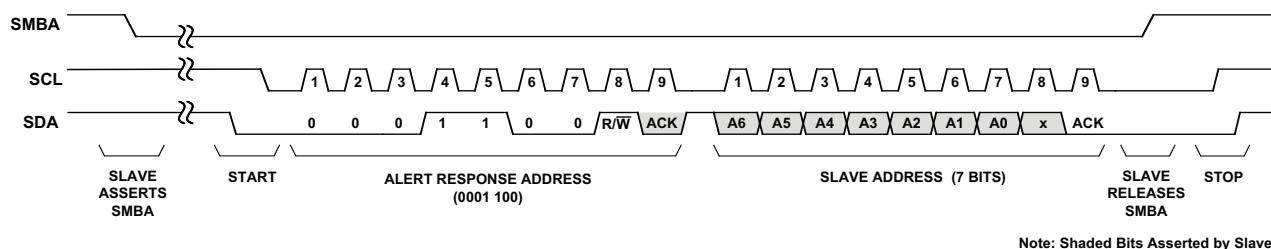
Figure 37. Platform Manager SMBAlert Logic



The typical flow for an SMBAlert transaction is as follows (Figure 38):

1. GP5_ENb bit is forced (Via I²C write) to Low
2. Platform Manager CPLD logic pulls OUT5/SMBA Low
3. Master responds to interrupt from SMBA line
4. Master broadcasts a read operation using the SMBus Alert Response Address (ARA)
5. Platform Manager responds to read request by transmitting its device address
6. If transmitted device address matches Platform Manager address, it sets GP5_ENb bit high.
This releases OUT5/SMBA.

Figure 38. SMBAlert Bus Transaction



After OUT5/SMBA has been released, the bus master (typically a microcontroller) may opt to perform some service functions in which it may send data to or read data from the Platform Manager. As part of the service functions, the bus master will typically need to clear whatever condition initiated the SMBAlert request, and will also need to reset GP5_ENb to re-enable the SMBAlert function. For further information on the SMBus, the user should consult the SMBus Standard.

Designs using the SMBAlert feature are required to set the device's I²C/SMBus address to the lowest of all the addresses on that I²C/SMBus.

RESETb Signal, RESET Command via JTAG or I²C

Activating the RESETb signal (Logic 0 applied to the RESETb pin) or issuing a reset instruction via JTAG or I²C will force the outputs to the following states independent of how these outputs have been configured in the PINS window:

- OUT5-16 will go high-impedance.
- HVOUT pins programmed for open drain operation will go high-impedance.
- HVOUT pins programmed for FET driver mode operation will pull down.

At the conclusion of the RESET event, these outputs will go to the states defined by the PINS window, and if a sequence has been programmed into the device, it will be re-started at the first step. The analog calibration will be re-done and consequently, the VMONs, ADCs, and DACs will not be operational until 2.5 milliseconds (max.) after the conclusion of the RESET event.

CAUTION: Activating the RESETb signal or issuing a RESET command through I²C or JTAG during the Platform Manager device operation, results in the device aborting all operations and returning to the power-on reset state. The status of the power supplies which are being enabled by the Platform Manager will be determined by the state of the outputs shown above.

FPGA Architecture Details

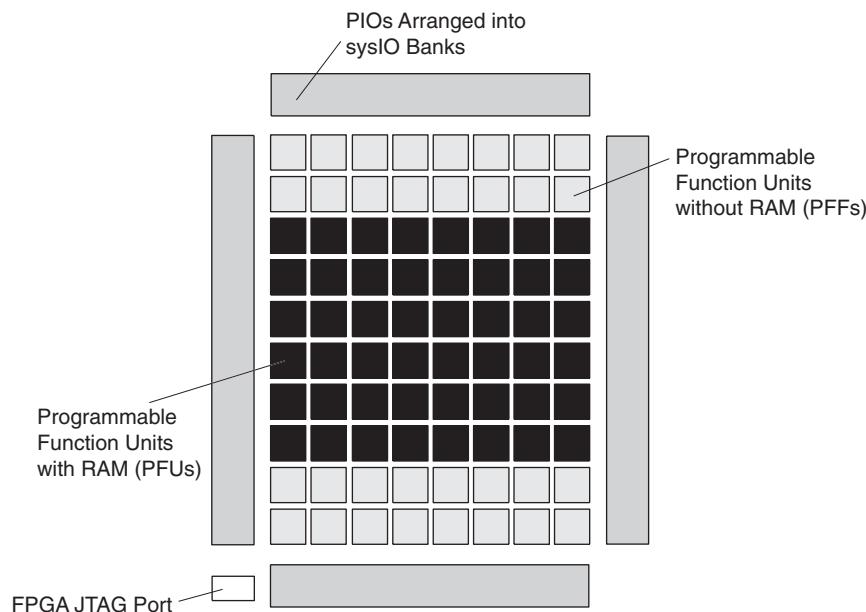
The Platform Manager FPGA architecture contains an array of logic blocks surrounded by Programmable I/O (PIO). Figure 39 shows the block diagrams of the FPGA block.

The logic blocks are arranged in a two-dimensional grid with rows and columns. The PIO cells are located at the periphery of the device, arranged into banks. The PIOs utilize a flexible I/O buffer referred to as a sysIO interface that supports operation with a variety of interface standards. The blocks are connected with many vertical and horizontal routing channel resources. The place and route software tool automatically allocates these routing resources.

There are two kinds of logic blocks, the Programmable Functional Unit (PFU) and the Programmable Functional unit without RAM (PFF). The PFU contains the building blocks for logic, arithmetic, RAM, ROM, and register functions. The PFF block contains building blocks for logic, arithmetic, ROM, and register functions. Both the PFU and PFF blocks are optimized for flexibility, allowing complex designs to be implemented quickly and effectively. Logic blocks are arranged in a two-dimensional array. Only one type of block is used per row.

The FPGA JTAG port supports programming and configuration of the FPGA as well as access to the user logic.

Figure 39. Top View of the FPGA Section

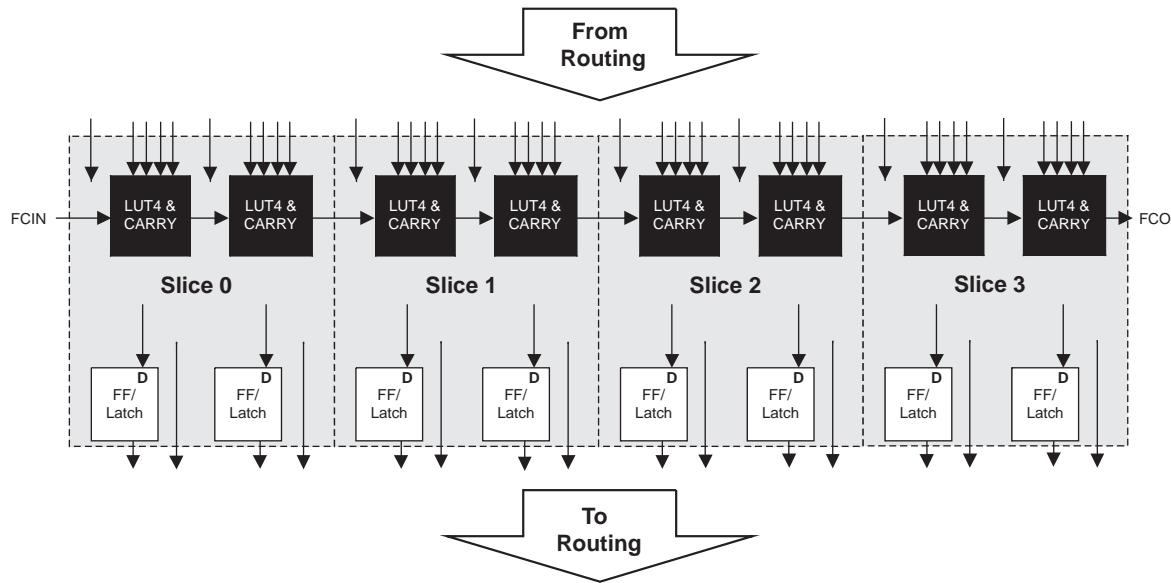


PFU Blocks

The core of the FPGA section consists of PFU and PFF blocks. The PFUs can be programmed to perform Logic, Arithmetic, Distributed RAM, and Distributed ROM functions. PFF blocks can be programmed to perform Logic, Arithmetic, and Distributed ROM functions. Except where necessary, the remainder of this data sheet will use the term PFU to refer to both PFU and PFF blocks.

Each PFU block consists of four interconnected slices, numbered 0 to 3 as shown in Figure 40. There are 53 inputs and 25 outputs associated with each PFU block.

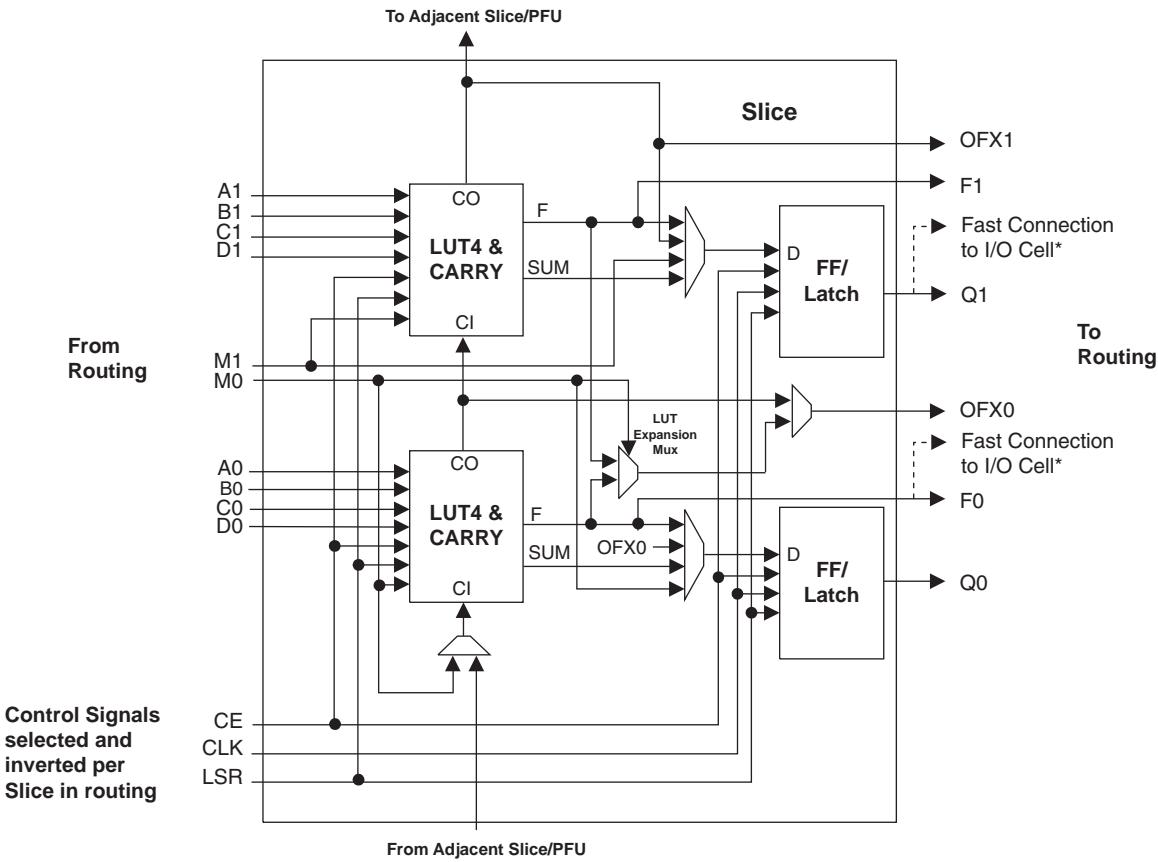
Figure 40. PFU Diagram



Slice

Each slice contains two LUT4 lookup tables feeding two registers (programmed to be in FF or Latch mode), and some associated logic that allows the LUTs to be combined to perform functions such as LUT5, LUT6, LUT7, and LUT8. There is control logic to perform set/reset functions (programmable as synchronous/asynchronous), clock select, chip-select, and wider RAM/ROM functions. Figure 41 shows an overview of the internal logic of the slice. The registers in the slice can be configured for positive/negative and edge/level clocks.

There are 14 input signals: 13 signals from routing and one from the carry-chain (from the adjacent slice/PFU). There are 7 outputs: 6 to the routing and one to the carry-chain (to the adjacent slice/PFU). Table 14 lists the signals associated with each slice.

Figure 41. Slice Diagram

Notes:

Some inter-Slice signals are not shown.

* Only PFUs at the edges have fast connections to the I/O cell.

Table 14. Slice Signal Descriptions

Function	Type	Signal Names	Description
Input	Data signal	A0, B0, C0, D0	Inputs to LUT4
Input	Data signal	A1, B1, C1, D1	Inputs to LUT4
Input	Multi-purpose	M0/M1	Multipurpose Input
Input	Control signal	CE	Clock Enable
Input	Control signal	LSR	Local Set/Reset
Input	Control signal	CLK	System Clock
Input	Inter-PFU signal	FCIN	Fast Carry In ¹
Output	Data signals	F0, F1	LUT4 output register bypass signals
Output	Data signals	Q0, Q1	Register Outputs
Output	Data signals	OFX0	Output of a LUT5 MUX
Output	Data signals	OFX1	Output of a LUT6, LUT7, LUT8 ² MUX depending on the slice
Output	Inter-PFU signal	FCO	Fast Carry Out ¹

1. See Figure 40 for connection details.

2. Requires two PFUs.

Modes of Operation

Each slice is capable of four modes of operation: Logic, Ripple, RAM, and ROM. The slice in the PFF is capable of all modes except RAM. Table 15 lists the modes and the capability of the slice blocks.

Table 15. Slice Modes

	Logic	Ripple	RAM	ROM
PFU Slice	LUT 4x2 or LUT 5x1	2-bit Arithmetic Unit	SP 16x2	ROM 16x1 x 2
PFF Slice	LUT 4x2 or LUT 5x1	2-bit Arithmetic Unit	N/A	ROM 16x1 x 2

Logic Mode: In this mode, the LUTs in each slice are configured as 4-input combinatorial lookup tables (LUT4). A LUT4 can have 16 possible input combinations. Any logic function with four inputs can be generated by programming this lookup table. Since there are two LUT4s per slice, a LUT5 can be constructed within one slice. Larger lookup tables such as LUT6, LUT7, and LUT8 can be constructed by concatenating other slices.

Ripple Mode: Ripple mode allows the efficient implementation of small arithmetic functions. In ripple mode, the following functions can be implemented by each slice:

- Addition 2-bit
- Subtraction 2-bit
- Add/Subtract 2-bit using dynamic control
- Up counter 2-bit
- Down counter 2-bit
- Ripple mode multiplier building block
- Comparator functions of A and B inputs
 - A greater-than-or-equal-to B
 - A not-equal-to B
 - A less-than-or-equal-to B

Two additional signals, Carry Generate and Carry Propagate, are generated per slice in this mode, allowing fast arithmetic functions to be constructed by concatenating slices.

RAM Mode: In this mode, distributed RAM can be constructed using each LUT block as a 16x2-bit memory. Through the combination of LUTs and slices, a variety of different memories can be constructed.

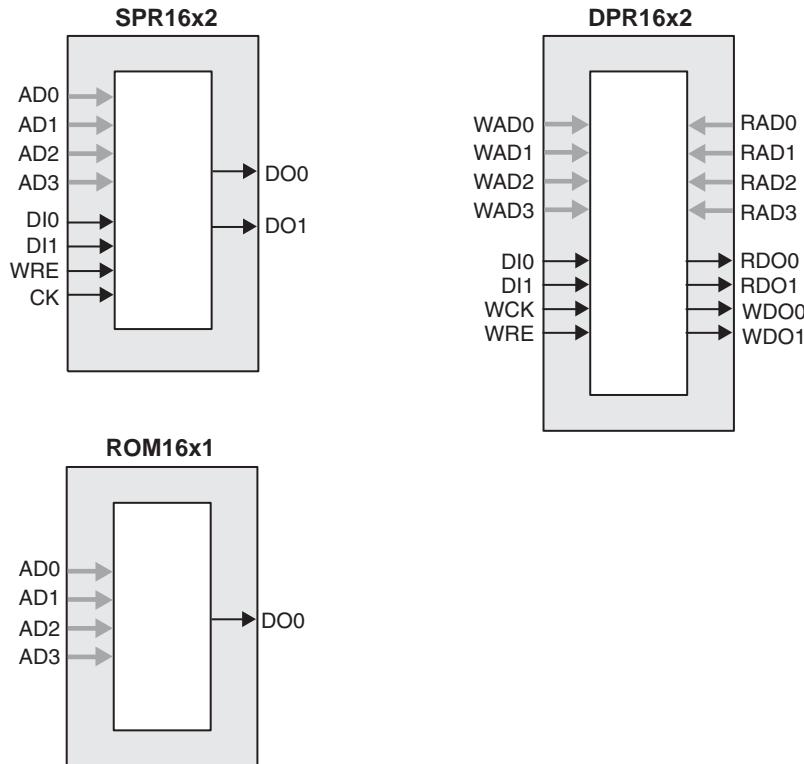
The Platform Manager design tool supports the creation of a variety of different size memories. Where appropriate, the software will construct these using distributed memory primitives that represent the capabilities of the PFU. Table 16 shows the number of slices required to implement different distributed RAM primitives. Figure 42 shows the distributed memory primitive block diagrams. Dual port memories involve the pairing of two slices. One slice functions as the read-write port, while the other companion slice supports the read-only port. For more information on RAM mode in the FPGA section, please see details of additional technical documentation at the end of this data sheet.

Table 16. Number of Slices Required For Implementing Distributed RAM

	SPR16x2	DPR16x2
Number of Slices	1	2

Note: SPR = Single Port RAM, DPR = Dual Port RAM

Figure 42. Distributed Memory Primitives



ROM Mode: The ROM mode uses the same principal as the RAM modes, but without the Write port. Pre-loading is accomplished through the programming interface during configuration.

PFU Modes of Operation

Slices can be combined within a PFU to form larger functions. Table 17 tabulates these modes and documents the functionality possible at the PFU level.

Table 17. PFU Modes of Operation

Logic	Ripple	RAM	ROM
LUT 4x8 or MUX 2x1 x 8	2-bit Add x 4	SPR16x2 x 4 DPR16x2 x 2	ROM16x1 x 8
LUT 5x4 or MUX 4x1 x 4	2-bit Sub x 4	SPR16x4 x 2 DPR16x4 x 1	ROM16x2 x 4
LUT 6x2 or MUX 8x1 x 2	2-bit Counter x 4	SPR16x8 x 1	ROM16x4 x 2
LUT 7x1 or MUX 16x1 x 1	2-bit Comp x 4		ROM16x8 x 1

Routing

There are many resources provided in the FPGA to route signals individually or as buses with related control signals. The routing resources consist of switching circuitry, buffers and metal interconnect (routing) segments.

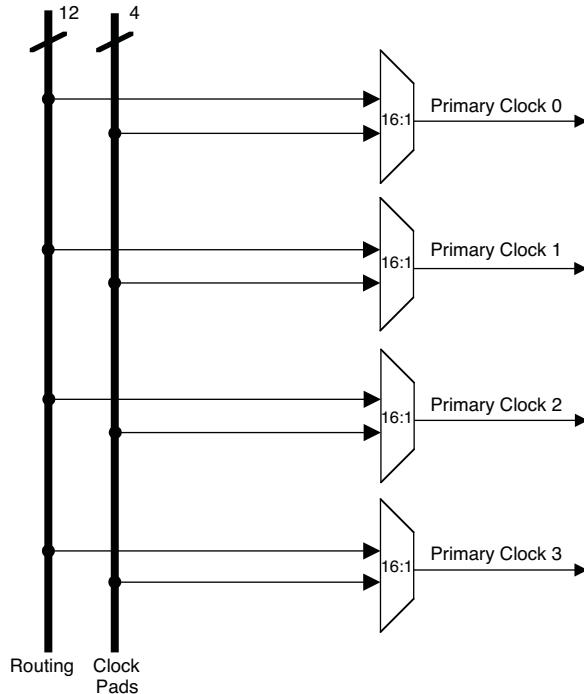
The inter-PFU connections are made with three different types of routing resources: x1 (spans two PFUs), x2 (spans three PFUs) and x6 (spans seven PFUs). The x1, x2, and x6 connections provide fast and efficient connections in the horizontal and vertical directions.

The Platform Manager design tool takes the output of the synthesis tool and places and routes the design. Generally, the place and route tool is completely automatic, although an interactive routing editor is available to optimize the design.

Clock/Control Distribution Network

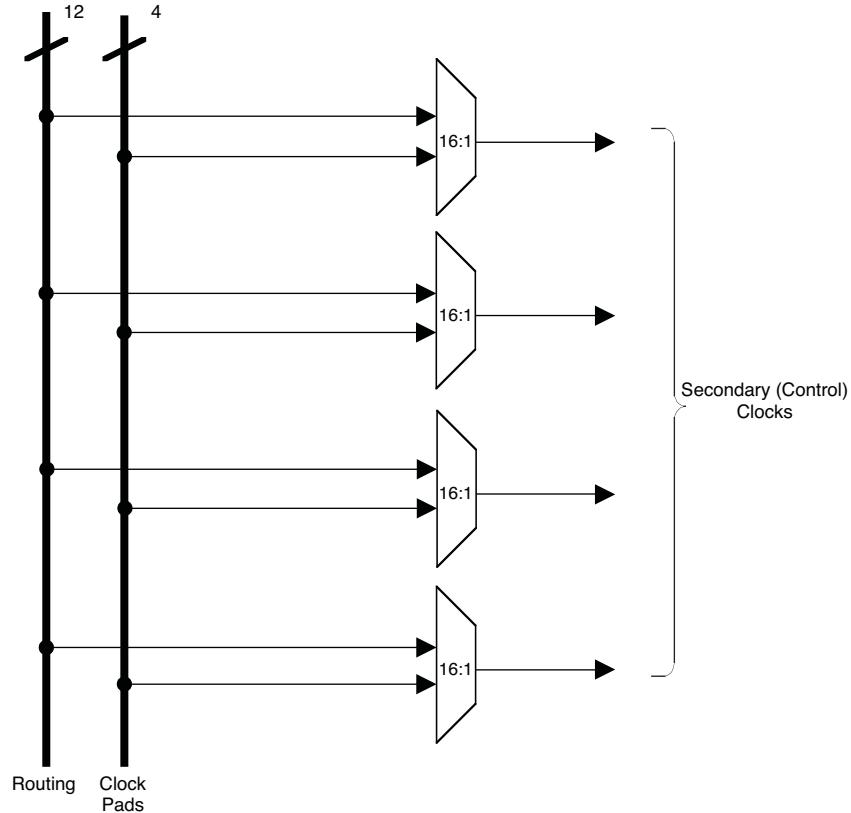
The FPGA section provides global signals that are available to all PFUs. These signals consist of four primary clocks and four secondary clocks. Primary clock signals are generated from four 16:1 muxes as shown in Figure 43. The available clock sources are four dual function clock pins and 12 internal routing signals.

Figure 43. FPGA Primary Clocks



Four secondary clocks are generated from four 16:1 muxes as shown in Figure 44. Four of the secondary clock sources come from dual function clock pins and 12 come from internal routing.

Figure 44. FPGA Secondary Clocks



PIO Groups

FPGA PIO cells are assembled into two different types of PIO groups, those with four PIO cells and those with six PIO cells. PIO groups with four I/Os are placed on the left and right sides of the device while PIO groups with six I/Os are placed on the top and bottom. The individual PIO cells are connected to their respective sysIO buffers and pads.

Two adjacent PIOs can be joined to provide a complementary output driver pair. The I/O pin pairs are labeled as "T" and "C" to distinguish between the true and complement pins.

Figure 45. Group of Four Programmable I/O Cells

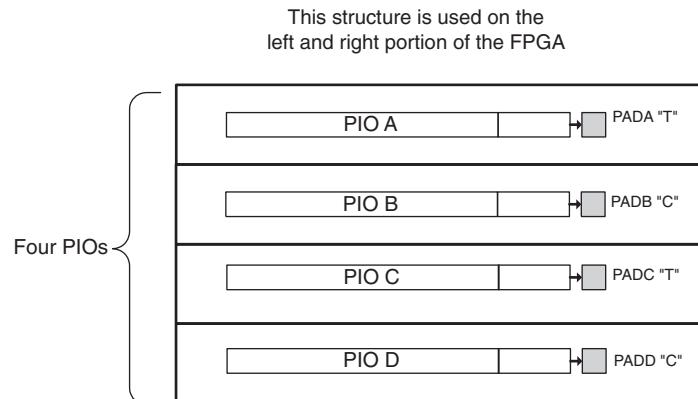
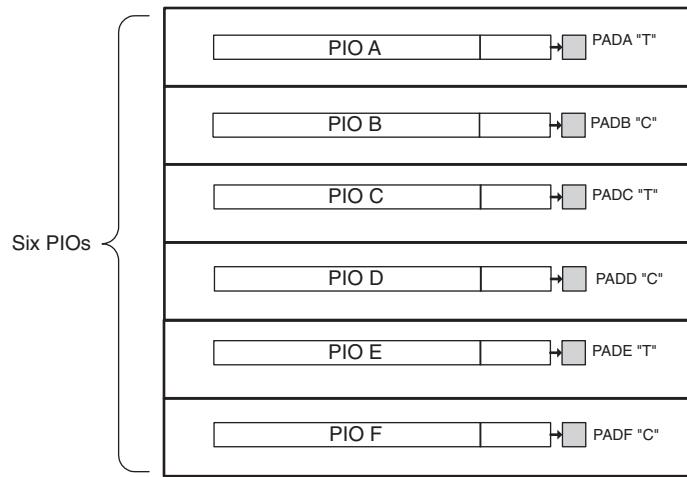


Figure 46. Group of Six Programmable I/O Cells

This structure is used on the top and bottom portion of the devices

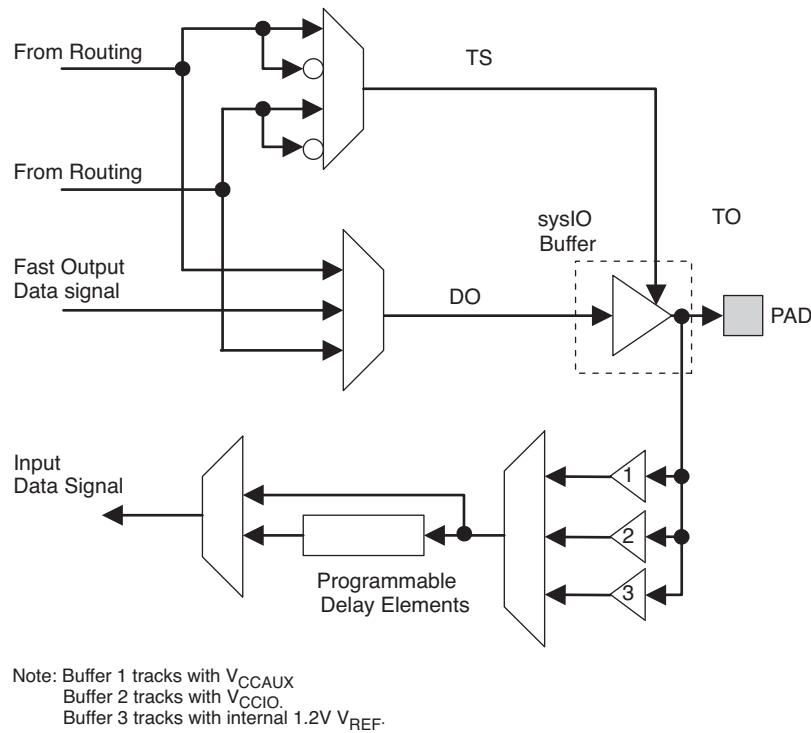


PIO

The PIO blocks provide the interface between the sysIO buffers and the internal PFU array blocks. These blocks receive output data from the PFU array and a fast output data signal from adjacent PFUs. The output data and fast output data signals are multiplexed and provide a single signal to the I/O pin via the sysIO buffer. Figure 47 shows the FPGA PIO logic.

The PIO receives an input signal from the pin via the sysIO buffer and provides this signal to the core of the FPGA fabric. In addition there are programmable elements that can be utilized by the design tools to avoid positive hold times.

Figure 47. PIO Block Diagram



sysIO Buffer

Each I/O is associated with a flexible buffer referred to as a sysIO buffer. These buffers are arranged around the periphery of the device in groups referred to as banks. The sysIO buffers allow users to implement the wide variety of standards that are found in today's systems including LVCMOS, TTL, BLVDS, LVDS and LVPECL.

FPGA output buffers and ratioed input buffers (LVTTL and LVCMOS) are powered using V_{CCIO} . In addition to the bank V_{CCIO} supplies, the FPGA fabric has a V_{CC} core logic power supply, and a V_{CCAUX} supply that powers up a variety of internal circuits.

Top and Bottom sysIO Buffer Pairs

The sysIO buffer pairs in the top and bottom banks of the device consist of two single-ended output drivers and two sets of single-ended input buffers (for ratioed or absolute input levels). The I/O pairs on the top and bottom of the devices also support differential input buffers.

Left and Right sysIO Buffer Pairs

The sysIO buffer pairs in the left and right banks of the device consist of two single-ended output drivers and two sets of single-ended input buffers (supporting ratioed and absolute input levels). The devices also have a differential driver per output pair. The referenced input buffer can also be configured as a differential input buffer. In these banks the two pads in the pair are described as "true" and "comp", where the true pad is associated with the positive side of the differential I/O, and the comp (complementary) pad is associated with the negative side of the differential I/O.

Typical I/O Behavior During Power-up

The internal power-on-reset (POR) signal is deactivated when V_{CC} and V_{CCAUX} have reached satisfactory levels. After the POR signal is deactivated, the FPGA core logic becomes active. It is the user's responsibility to ensure that all V_{CCIO} banks are active with valid input logic levels to properly control the output logic states of all the I/O

banks that are critical to the application. The default configuration of the I/O pins in a blank device is tri-state with a weak pull-up to V_{CCIO} . The I/O pins will maintain the blank configuration until V_{CC} , V_{CCAUX} and V_{CCIO} have reached satisfactory levels at which time the I/Os will take on the user-configured settings.

The V_{CC} and V_{CCAUX} supply the power to the FPGA core fabric, whereas the V_{CCIO} supplies power to the I/O buffers. In order to simplify system design while providing consistent and predictable I/O behavior, the I/O buffers should be powered up along with the FPGA core fabric. Therefore, V_{CCIO} supplies should be powered up together with the V_{CC} and V_{CCAUX} supplies. (V_{CC} and V_{CCAUX} must be physically tied together for proper operation).

Supported Standards

The FPGA sysIO buffer supports both single-ended and differential standards. Single-ended standards can be further subdivided into LVCMOS and LVTTL. The buffer supports the LVTTL, LVCMOS 1.2, 1.5, 1.8, 2.5, and 3.3V standards. In the LVCMOS and LVTTL modes, the buffer has individually configurable options for drive strength, bus maintenance (weak pull-up, weak pull-down, bus-keeper latch or none) and open drain. BLVDS and LVPECL output emulation is also supported.

Tables 18 and 19 show the I/O standards (together with their supply and reference voltages) supported by the FPGA I/Os. For further information on utilizing the sysIO buffer to support a variety of standards please see the details of additional technical documentation at the end of this data sheet. Note: I/O bank 2 pins do not support LVCMOS12, LVCMOS15 or LVCMOS18 standards.

Table 18. Supported Input Standards

Input Standard	V _{CCIO} (Typ.)				
	3.3V	2.5V	1.8V ¹	1.5V ¹	1.2V ¹
Single Ended Interfaces					
LVTTL	X	X	X	X	X
LVCMOS33	X	X	X	X	X
LVCMOS25	X	X	X	X	X
LVCMOS18			X		
LVCMOS15				X	
LVCMOS12	X	X	X	X	X

1. Not supported by I/O Bank 2 (V_{CCIO2}).

Table 19. Supported Output Standards

Output Standard	Drive	V _{CCIO} (Typ.)
Single-ended Interfaces		
LVTTL	4mA, 8mA, 12mA, 16mA	3.3
LVCMOS33	4mA, 8mA, 12mA, 14mA	3.3
LVCMOS25	4mA, 8mA, 12mA, 14mA	2.5
LVCMOS18 ¹	4mA, 8mA, 12mA, 14mA	1.8
LVCMOS15 ¹	4mA, 8mA	1.5
LVCMOS12 ¹	2mA, 6mA	1.2
LVCMOS33, Open Drain	4mA, 8mA, 12mA, 14mA	—
LVCMOS25, Open Drain	4mA, 8mA, 12mA, 14mA	—
LVCMOS18, Open Drain ¹	4mA, 8mA, 12mA, 14mA	—
LVCMOS15, Open Drain ¹	4mA, 8mA	—
LVCMOS12, Open Drain ¹	2mA, 6mA	—

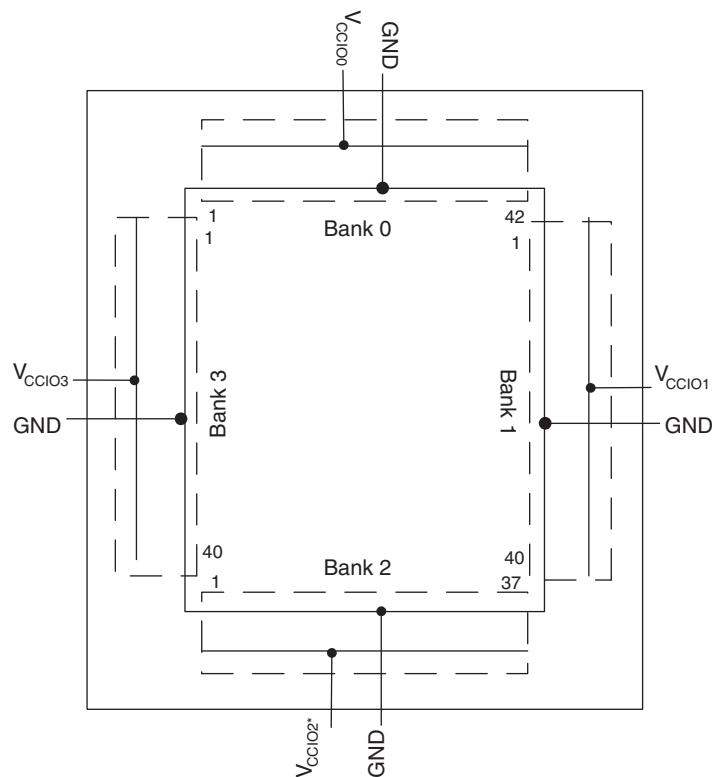
1. Not supported by I/O Bank 2 (V_{CCIO2}).

sysIO Buffer Banks

The FPGA I/O section has four banks (one bank per side).

Each sysIO buffer bank is capable of supporting multiple I/O standards. Each bank has its own I/O supply voltage (V_{CCIO}) which allows it to be completely independent from the other banks. Figure 48 shows the sysIO banks organization around the FPGA fabric.

Figure 48. FPGA I/O Banks



* V_{CCIO2} is restricted to either 2.5V or 3.3V operation.

Hot Socketing

The FPGA I/Os have been carefully designed to ensure predictable behavior during power-up and power-down. Leakage into I/O pins is controlled to within specified limits. This allows for easy integration with the rest of the system. These capabilities make the FPGA I/Os ideal for many multiple power supply and hot-swap applications.

Sleep Mode

The Platform Manager FPGA section has a sleep mode that allows standby current to be reduced dramatically during periods of system inactivity. Entry and exit to Sleep mode is controlled by the SLEEPN pin (see Pin Description Table).

During Sleep mode, the FPGA logic is non-operational, register contents are not maintained, and I/Os are tri-stated. Do not enter Sleep mode during device programming or configuration operation. In Sleep mode, power supplies are in their normal operating range, eliminating the need for external switching of power supplies. Table 20 compares the characteristics of Normal, Off and Sleep modes. Sleep mode does not shut down the power management section of the Platform Manager. If Sleep mode is not used, ensure that the SLEEPN pin is tied high via an external pull-up to VCC.

Table 20. Characteristics of Normal, Off and Sleep Modes

Characteristic	Normal	Off	Sleep
SLEEPN Pin	High	—	Low
Static I_{CC}	Typical <10mA	0	Typical <100µA
I/O Leakage	<10µA	<1mA	<10µA
Power Supplies VCC/VCCIO/VCCAUX	Normal Range	0	Normal Range
Logic Operation	User-defined	Non-operational	Non-operational
I/O Operation	User-defined	Tri-state	Tri-state
JTAG and Programming circuitry	Operational	Non-operational	Non-operational

SLEEPN Pin Characteristics

The SLEEPN pin behaves as an LVCMS input with the voltage standard appropriate to the VCC supply for the device. This pin also has a weak pull-up, along with a Schmidt trigger and glitch filter to prevent false triggering. An external pull-up to VCC is recommended when Sleep Mode is not used to ensure the device stays in normal operation mode. Typically, the device enters sleep mode several hundred nanoseconds after SLEEPN is held at a valid low and restarts normal operation as specified in the Sleep Mode Timing table. The AC and DC specifications portion of this data sheet shows a detailed timing diagram. Note that Sleep mode does not shut down the power management section of the Platform Manager.

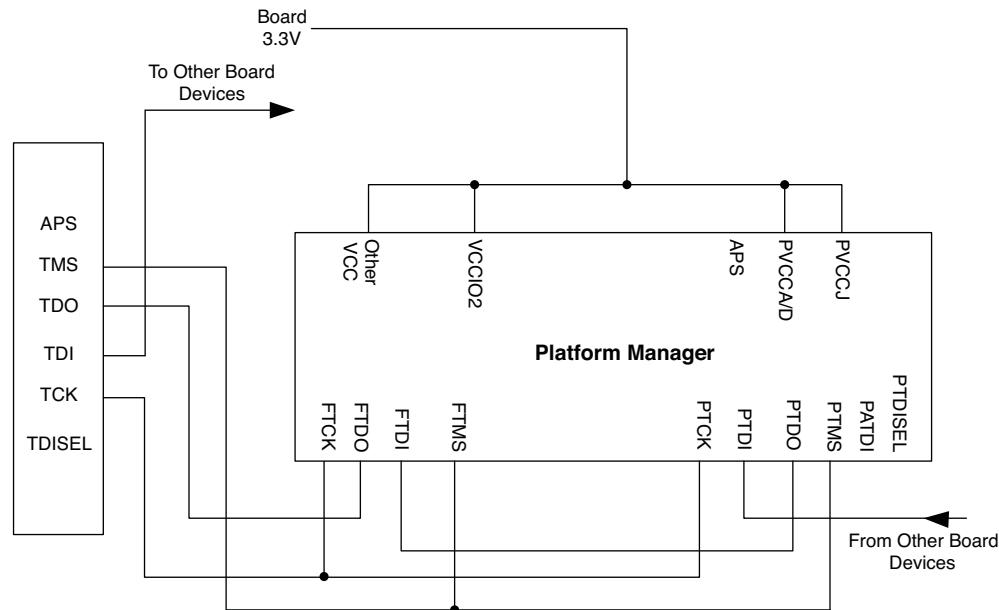
Oscillator

The FPGA section has an internal CMOS oscillator. The oscillator can be routed as an input clock to the clock tree or to general routing resources. The oscillator frequency can be divided by internal logic. There is a dedicated programming bit to enable/disable the oscillator. The oscillator frequency ranges from 18MHz to 26MHz.

In-System Programming – Power Management Section

The Platform Manager is an in-system programmable device. This is accomplished by integrating all E² configuration memory and control logic internally. Programming is performed through a 4-wire, IEEE 1149.1 compliant serial JTAG interface at normal logic levels. Once a device is programmed, all configuration information is stored internally, in non-volatile E²CMOS memory cells. The specifics of the IEEE 1149.1 serial interface and all Platform Manager instructions are described in the JTAG interface section of this data sheet.

Figure 49. Platform Manager JTAG Interconnection Configuration Diagram



Programming Platform Manager: Alternate Method

Some applications require that the Platform Manager be programmed before turning the power on to the entire circuit board. To meet such application needs, the Platform Manager provides an alternate programming method which enables the programming of the Platform Manager device through the JTAG chain with a separate power supply applied just to the programming section of the Platform Manager device with the main power supply of the board turned off.

Three special purpose pins, APS, PATDI and PTDISEL, enable programming of the un-programmed Platform Manager under such circumstances. The APS pin provides power to the programming circuitry of the Platform Manager device (when PVCCD and PVCCA are unpowered). The PVCCJ pin must be powered to enable the JTAG port. The PATDI pin provides an alternate connection to the JTAG header while bypassing all the un-powered devices in the JTAG chain. PTDISEL pin enables switching between the PATDI and the standard JTAG signal PTDI. When the internally pulled-up PTDISEL = 1, standard PTDI pin is enabled and when the PTDISEL = 0, PATDI is enabled.

In order to use this feature the JTAG signals of the Platform Manager are connected to the header as shown in Figure 50. *Note: The Platform Manager should be the last device in the JTAG chain.*

After programming, the APS pin **MUST** be left floating when the PVCCD and PVCCA pins are powered.

Alternate PTDI Selection Via JTAG Command

When the PTDISEL pin held high and four consecutive IDCODE instructions are issued, Platform Manager responds by making its active JTAG data input the PATDI pin. When PATDI is selected, data on its PTDI pin is ignored until the JTAG state machine returns to the Test-Logic-Reset state.

This method of selecting PATDI takes advantage of the fact that a JTAG device with an IDCODE register will automatically load its unique IDCODE instruction into the Instruction Register after a Test-Logic-Reset. This JTAG capability permits blind interrogation of devices so that their location in a serial chain can be identified without having to know anything about them in advance. A blind interrogation can be made using only the PTMS and PTCK control pins, which means PTDI and PTDO are not required for performing the operation. Figure 50 illustrates the logic for selecting whether the PTDI or PATDI pin is the active data input to Platform Manager.

Figure 50. Platform Manager Alternate PTDI Configuration Diagram

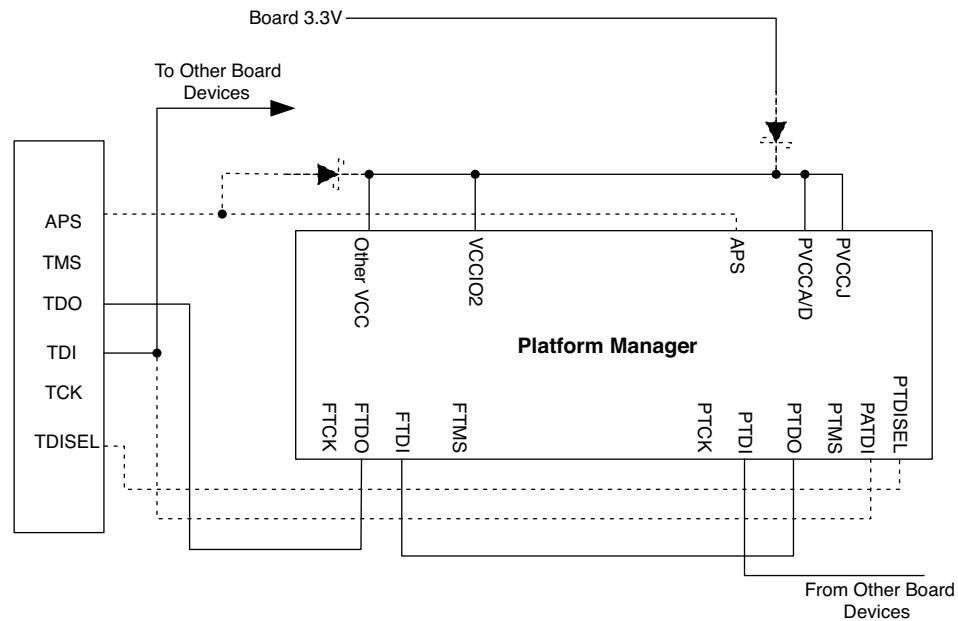


Figure 51. Power Manager PTDI/PATDI Pin Selection Diagram

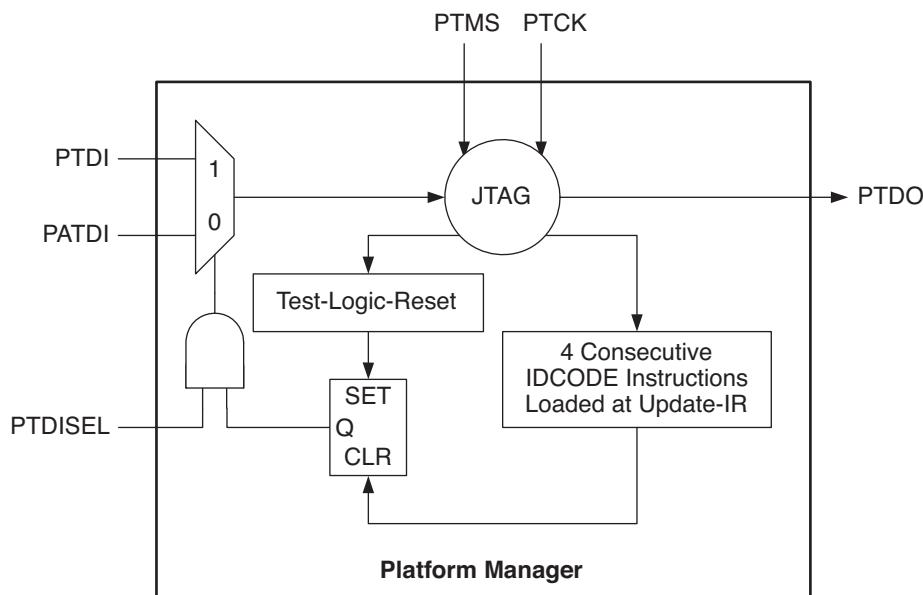


Table 21 shows in truth table form the same conditions required to select either PTDI or PATDI as in the logic diagram found in Figure 50.

Table 21. Platform Manager PATDI/PTDI Selection Table

PTDISEL Pin	JTAG State Machine Test-Logic-Reset	4 Consecutive IDCODE Commands Loaded at Update-IR	Active JTAG Data Input Pin
H	No	Yes	PATDI (PTDI Disabled)
H	Yes	No	PTDI (PTDI Disabled)
L	X	X	PATDI (PTDI Disabled)

Please refer to the Lattice application note AN6068, [Programming the ispPAC-POWR1220AT8 in a JTAG Chain Using the ATDI Pin](#). The application note includes specific SVF code examples and information on the use of Lattice design tools to verify device operation in alternate PTDI mode.

APS Power Supply Pin

Because the APS pin directly powers the internal programming circuitry, the Platform Manager device can be programmed by applying power to the APS pin (without powering the entire device through the PVCCD and PVCCA pins). In addition, to enable the internal JTAG interface circuitry, power should be applied to the PVCCJ pin.

When the Platform Manager is powered by the APS pin, no power should be applied to the PVCCD and PVCCA pins. Additionally, other than JTAG I/O pins, all digital output pins are in Hi-Z state, HVOUT pins configured as MOSFET driver are driven low, and all other inputs are ignored.

To switch the power supply back to PVCCD and PVCCA pins, one should turn the APS supply and PVCCJ off before turning the regular supplies on. When PVCCD and PVCCA are turned back on for normal operation, APS **MUST** either be left floating or be grounded. Do not leave APS connected to a supply during normal operation.

User Electronic Signature

A user electronic signature (UES) feature is included in the E²CMOS memory of the Platform Manager. This consists of 32 bits that can be configured by the user to store unique data such as ID codes, revision numbers or inventory control data. The specifics of this feature are discussed in the IEEE 1149.1 serial interface section of this data sheet.

Electronic Security

An electronic security “fuse” (ESF) bit is provided in every Platform Manager device to prevent unauthorized read-out of the E²CMOS configuration bit patterns. Once programmed, this cell prevents further access to the functional user bits in the device. This cell can only be erased by reprogramming the device, so the original configuration cannot be examined once programmed. Usage of this feature is optional. The specifics of this feature are discussed in the IEEE 1149.1 serial interface section of this data sheet.

Production Programming Support

Once a final configuration is determined, an ASCII format JEDEC file can be created using the PAC-Designer software. Devices can then be ordered through the usual supply channels with the user's specific configuration already preloaded into the devices. By virtue of its standard interface, compatibility is maintained with existing production programming equipment, giving customers a wide degree of freedom and flexibility in production planning.

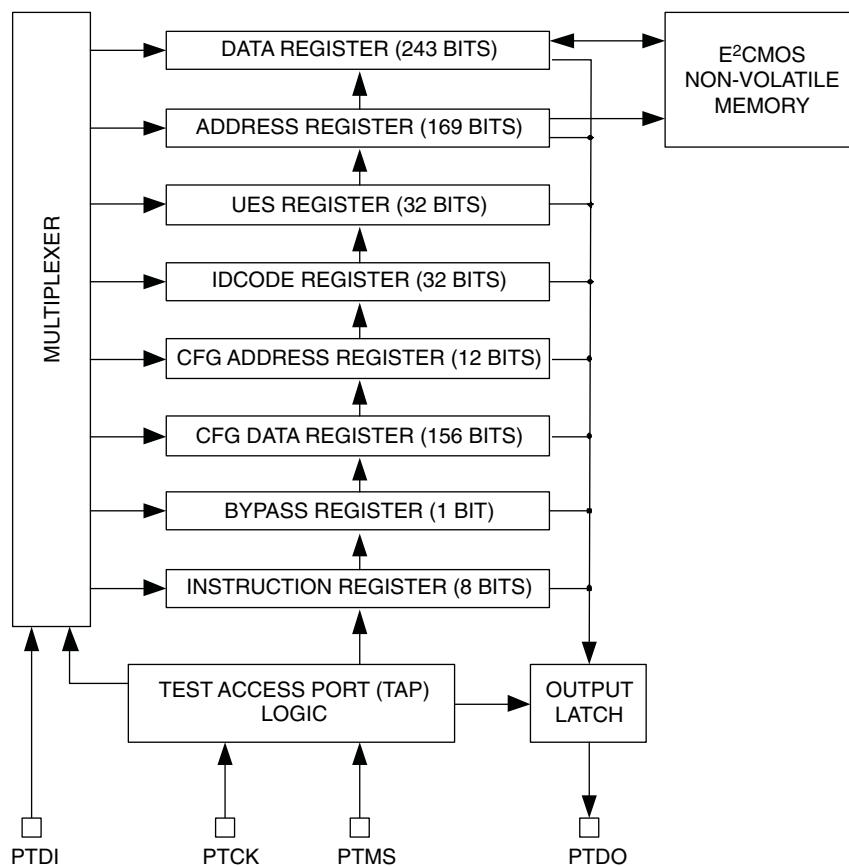
Power Management JTAG Interface

Serial Port Programming Interface Communication with the Platform Manager is facilitated via an IEEE 1149.1 test access port (TAP). It is used by the Platform Manager as a serial programming interface. A brief description of the Platform Manager JTAG interface follows. For complete details of the reference specification, refer to the publication, Standard Test Access Port and Boundary-Scan Architecture, IEEE Std 1149.1-1990 (which now includes IEEE Std 1149.1a-1993).

Overview

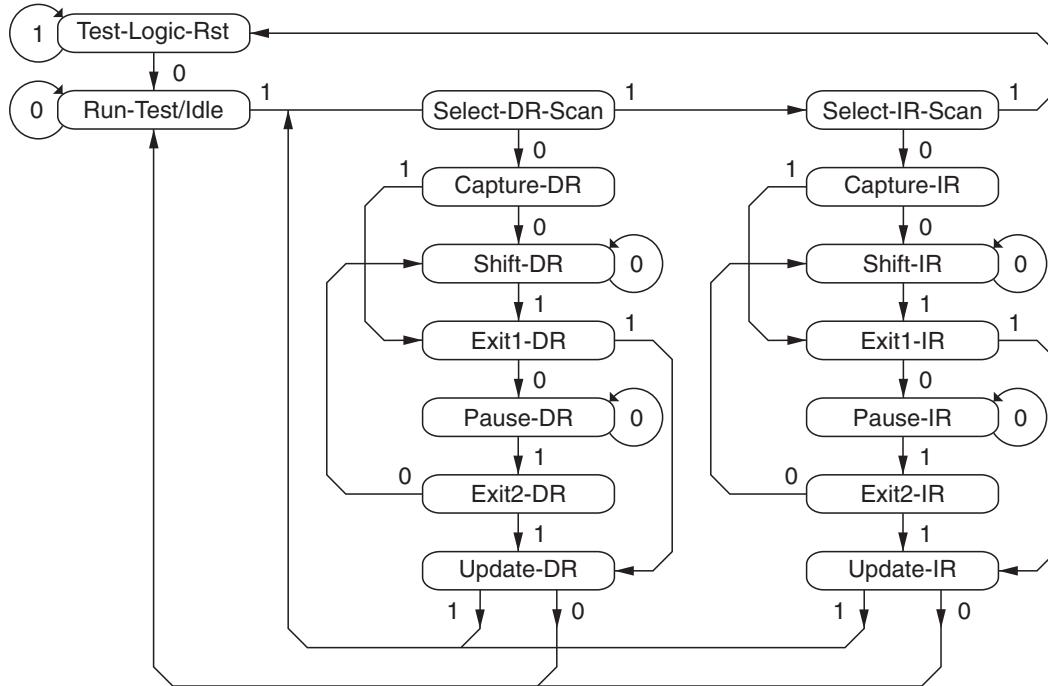
An IEEE 1149.1 test access port (TAP) provides the control interface for serially accessing the digital I/O of the Platform Manager. The TAP controller is a state machine driven with mode and clock inputs. Given in the correct sequence, instructions are shifted into an instruction register, which then determines subsequent data input, data output, and related operations. Device programming is performed by addressing the configuration register, shifting data in, and then executing a program configuration instruction, after which the data is transferred to internal E²CMOS cells. It is these non-volatile cells that store the configuration or the Platform Manager. A set of instructions are defined that access all data registers and perform other internal control operations. For compatibility between compliant devices, two data registers are mandated by the IEEE 1149.1 specification. Others are functionally specified, but inclusion is strictly optional. Finally, there are provisions for optional data registers defined by the manufacturer. The two required registers are the bypass and boundary-scan registers. Figure 52 shows how the instruction and various data registers are organized in an Platform Manager.

Figure 52. Platform Manager CPLD TAP Registers



TAP Controller Specifics

The TAP is controlled by the Test Clock (PTCK) and Test Mode Select (PTMS) inputs. These inputs determine whether an Instruction Register or Data Register operation is performed. Driven by the PTCK input, the TAP consists of a small 16-state controller design. In a given state, the controller responds according to the level on the PTMS input as shown in Figure 53. Test Data In (PTDI) and PTMS are latched on the rising edge of PTCK, with Test Data Out (PTDO) becoming valid on the falling edge of PTCK. There are six steady states within the controller: Test-Logic-Reset, Run-Test/Idle, Shift-Data-Register, Pause-Data-Register, Shift-Instruction-Register and Pause-Instruction-Register. But there is only one steady state for the condition when PTMS is set high: the Test-Logic-Reset state. This allows a reset of the test logic within five PTCKs or less by keeping the PTMS input high. Test-Logic-Reset is the power-on default state.

Figure 53. TAP States


Note: The value shown adjacent to each state transition in this figure represents the signal present at PTMS at the time of a rising edge at PTCK.

When the correct logic sequence is applied to the PTMS and PTCK inputs, the TAP will exit the Test-Logic-Reset state and move to the desired state. The next state after Test-Logic-Reset is Run-Test/Idle. Until a data or instruction shift is performed, no action will occur in Run-Test/Idle (steady state = idle). After Run-Test/Idle, either a data or instruction shift is performed. The states of the Data and Instruction Register blocks are identical to each other differing only in their entry points. When either block is entered, the first action is a capture operation. For the Data Registers, the Capture-DR state is very simple: it captures (parallel loads) data onto the selected serial data path (previously chosen with the appropriate instruction). For the Instruction Register, the Capture-IR state will always load the IDCODE instruction. It will always enable the ID Register for readout if no other instruction is loaded prior to a Shift-DR operation. This, in conjunction with mandated bit codes, allows a "blind" interrogation of any device in a compliant IEEE 1149.1 serial chain. From the Capture state, the TAP transitions to either the Shift or Exit1 state. Normally the Shift state follows the Capture state so that test data or status information can be shifted out or new data shifted in. Following the Shift state, the TAP either returns to the Run-Test/Idle state via the Exit1 and Update states or enters the Pause state via Exit1. The Pause state is used to temporarily suspend the shifting of data through either the Data or Instruction Register while an external operation is performed. From the Pause state, shifting can resume by reentering the Shift state via the Exit2 state or be terminated by entering the Run-Test/Idle state via the Exit2 and Update states. If the proper instruction is shifted in during a Shift-IR operation, the next entry into Run-Test/Idle initiates the test mode (steady state = test). This is when the device is actually programmed, erased or verified. All other instructions are executed in the Update state.

Test Instructions

Like data registers, the IEEE 1149.1 standard also mandates the inclusion of certain instructions. It outlines the function of three required and six optional instructions. Any additional instructions are left exclusively for the manufacturer to determine. The instruction word length is not mandated other than to be a minimum of two bits, with only the BYPASS and EXTEST instruction code patterns being specifically called out (all ones and all zeroes respectively). The Platform Manager contains the required minimum instruction set as well as one from the optional instruction set. In addition, there are several proprietary instructions that allow the device to be configured and verified. Table 22 lists the instructions supported by the Platform Manager JTAG Test Access Port (TAP) controller:

Table 22. Power Management Section TAP Instruction Table

Instruction	Command Code	Comments
BULK_ERASE	0000 0011	Bulk erase device
BYPASS	1111 1111	Bypass – Connect PTDO to PTDI
DISCHARGE	0001 0100	Fast VPP discharge
ERASE_DONE_BIT	0010 0100	Erases ‘Done’ bit only
EXTTEST	0000 0000	Bypass – Connect PTDO to PTDI
IDCODE	0001 0110	Read contents of manufacturer ID code (32 bits)
OUTPUTS_HIGHZ	0001 1000	Force all outputs to High-Z state, FET outputs pulled low
SAMPLE/PRELOAD	00011100	Sample/Preload. Default to bypass.
PROGRAM_DISABLE	0001 1110	Disable program mode
PROGRAM_DONE_BIT	0010 1111	Program the Done bit
PROGRAM_ENABLE	0001 0101	Enable program mode
PROGRAM_SECURITY	0000 1001	Program security fuse
RESET	0010 0010	Reset device (refer to the RESETb signal, RESET Command Via JTAG or I ² C section of this data sheet)
IN1_RESET_JTAG_BIT	0001 0010	Reset the JTAG bit associated with IN1 pin to 0
IN1_SET_JTAG_BIT	0001 0011	Set the JTAG bit associated with IN1 pin to 1
CFG_ADDRESS	0010 1011	Select non-CPLD address register
CFG_DATA_SHIFT	0010 1101	Non-CPLD data shift
CFG_ERASE	0010 1001	Erase just the non-CPLD configuration
CFG_PROGRAM	0010 1110	Non-CPLD program
CFG_VERIFY	0010 1000	Verify non-CPLD fuse map data
CPLD_ADDRESS_SHIFT	0000 0001	CPLD_Address register (169 bits)
CPLD_DATA_SHIFT	0000 0010	CPLD_Data register (243 bits)
CPLD_INIT_ADDR_FOR_PROG_INCR	0010 0001	Initialize the address register for auto increment
CPLD_PROG_INCR	0010 0111	Program column register to E ² CMOS and auto increment address register
CPLD_PROGRAM	0000 0111	Program CPLD data register to E ² CMOS
CPLD_VERIFY	0000 1010	Verify CPLD column data
CPLD_VERIFY_INCR	0010 1010	Load column register from ECMOS ² and auto increment address register
UES_PROGRAM	0001 1010	Program UES bits into E ² CMOS
UES_READ	0001 0111	Read contents of UES register from E ² CMOS (32 bits)

BYPASS is one of the three required instructions. It selects the Bypass Register to be connected between PTDI and PTDO and allows serial data to be transferred through the device without affecting the operation of the Platform Manager. The IEEE 1149.1 standard defines the bit code of this instruction to be all ones (11111111).

The required **SAMPLE/PRELOAD** instruction dictates the Boundary-Scan Register be connected between PTDI and PTDO. The Platform Manager has no boundary scan register, so for compatibility it defaults to the BYPASS mode whenever this instruction is received. The bit code for this instruction is defined by Lattice as shown in Table 22.

The **EXTTEST** (external test) instruction is required and would normally place the device into an external boundary test mode while also enabling the boundary scan register to be connected between PTDI and PTDO. Again, since the Platform Manager has no boundary scan logic, the device is put in the BYPASS mode to ensure specification compatibility. The bit code of this instruction is defined by the 1149.1 standard to be all zeros (00000000).

The optional **IDCODE** (identification code) instruction is incorporated in the Platform Manager and leaves it in its functional mode when executed. It selects the Device Identification Register to be connected between PTDI and PTDO. The Identification Register is a 32-bit shift register containing information regarding the IC manufacturer, device type and version code (Figure 54). Access to the Identification Register is immediately available, via a TAP data scan operation, after power-up of the device, or by issuing a Test-Logic-Reset instruction. The bit code for this instruction is defined by Lattice as shown in Table 22.

Figure 54. Platform Manager ID Code

MSB	LSB
0100 0000 0001 0100 0100 / 0000 0100 001 / 1	
<u>0101 0000 0001 0100 0100 / 0000 0100 001 / 1</u>	
Part Number (20 bits) 40144h = LPTM10-1247-3 50144h = LPTM10-12107-3	JEDEC Manufacturer Identity Code for Lattice Semiconductor (11 bits)
	Constant 1 (1 bit) per 1149.1-1990

Platform Manager Specific Instructions

There are 25 unique instructions specified by Lattice for the Platform Manager. These instructions are primarily used to interface to the various user registers and the E²C MOS non-volatile memory. Additional instructions are used to control or monitor other features of the device. A brief description of each unique instruction is provided in detail below, and the bit codes are found in Table 22.

CPLD_ADDRESS_SHIFT – This instruction is used to set the address of the CPLD AND/ARCH arrays for subsequent program or read operations. This instruction also forces the outputs into the OUTPUTS_HIGHZ.

CPLD_DATA_SHIFT – This instruction is used to shift CPLD data into the register prior to programming or reading. This instruction also forces the outputs into the OUTPUTS_HIGHZ.

CPLD_INIT_ADDR_FOR_PROG_INCR – This instruction prepares the CPLD address register for subsequent CPLD_PROG_INCR or CPLD_VERIFY_INCR instructions.

CPLD_PROG_INCR – This instruction programs the CPLD data register for the current address and increments the address register for the next set of data.

CPLD_PROGRAM – This instruction programs the selected CPLD AND/ARCH array column. The specific column is preselected by using CPLD_ADDRESS_SHIFT instruction. The programming occurs at the second rising edge of the PTCK in Run-Test-Idle JTAG state. The device must already be in programming mode (PROGRAM_ENABLE instruction). This instruction also forces the outputs into the OUTPUTS_HIGHZ.

PROGRAM_SECURITY – This instruction is used to program the electronic security fuse (ESF) bit. Programming the ESF bit protects proprietary designs from being read out. The programming occurs at the second rising edge of the PTCK in Run-Test-Idle JTAG state. The device must already be in programming mode (PROGRAM_ENABLE instruction). This instruction also forces the outputs into the OUTPUTS_HIGHZ.

CPLD_VERIFY – This instruction is used to read the content of the selected CPLD AND/ARCH array column. This specific column is preselected by using CPLD_ADDRESS_SHIFT instruction. This instruction also forces the outputs into the OUTPUTS_HIGHZ.

DISCHARGE – This instruction is used to discharge the internal programming supply voltage after an erase or programming cycle and prepares Platform Manager for a read cycle. This instruction also forces the outputs into the OUTPUTS_HIGHZ.

CFG_ADDRESS – This instruction is used to set the address of the CFG array for subsequent program or read operations. This instruction also forces the outputs into the OUTPUTS_HIGHZ.

CFG_DATA_SHIFT – This instruction is used to shift data into the CFG register prior to programming or reading. This instruction also forces the outputs into the OUTPUTS_HIGHZ.

CFG_ERASE – This instruction will bulk erase the CFG array. The action occurs at the second rising edge of PTCK in Run-Test-Idle JTAG state. The device must already be in programming mode (PROGRAM_ENABLE instruction). This instruction also forces the outputs into the OUTPUTS_HIGHZ.

CFG_PROGRAM – This instruction programs the selected CFG array column. This specific column is preselected by using CFG_ADDRESS instruction. The programming occurs at the second rising edge of the PTCK in Run-Test-Idle JTAG state. The device must already be in programming mode (PROGRAM_ENABLE instruction). This instruction also forces the outputs into the OUTPUTS_HIGHZ.

CFG_VERIFY – This instruction is used to read the content of the selected CFG array column. This specific column is preselected by using CFG_ADDRESS instruction. This instruction also forces the outputs into the OUTPUTS_HIGHZ.

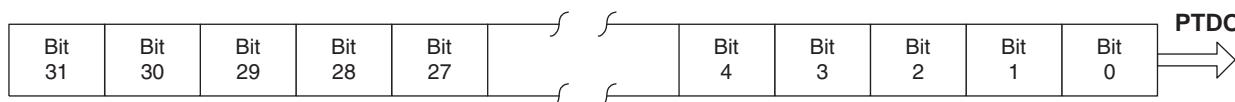
BULK_ERASE – This instruction will bulk erase all E²CMOS bits (CFG, CPLD, UES, and ESF) in the Platform Manager. The device must already be in programming mode (PROGRAM_ENABLE instruction). This instruction also forces the outputs into the OUTPUTS_HIGHZ.

OUTPUTS_HIGHZ – This instruction turns off all of the open-drain output transistors. Pins that are programmed as FET drivers will be placed in the active low state. This instruction is effective after Update-Instruction-Register JTAG state.

PROGRAM_ENABLE – This instruction enables the programming mode of the Platform Manager. This instruction also forces the outputs into the OUTPUTS_HIGHZ.

IDCODE – This instruction connects the output of the Identification Code Data Shift (IDCODE) Register to PTDO (Figure 55), to support reading out the identification code.

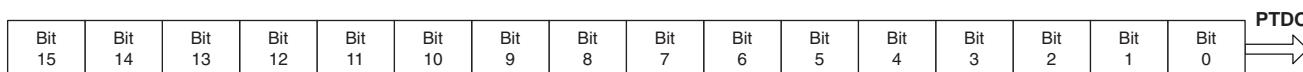
Figure 55. IDCODE Register



PROGRAM_DISABLE – This instruction disables the programming mode of the Platform Manager. The Test-Logic-Reset JTAG state can also be used to cancel the programming mode of the Platform Manager.

UES_READ – This instruction both reads the E²CMOS bits into the UES register and places the UES register between the PTDI and PTDO pins (as shown in Figure 56), to support programming or reading of the user electronic signature bits.

Figure 56. UES Register



UES_PROGRAM – This instruction will program the content of the UES Register into the UES E²CMOS memory. The device must already be in programming mode (PROGRAM_ENABLE instruction). This instruction also forces the outputs into the OUTPUTS_HIGHZ.

ERASE_DONE_BIT – This instruction clears the 'Done' bit, which prevents the Platform Manager sequence from starting.

PROGRAM_DONE_BIT – This instruction sets the 'Done' bit, which enables the Platform Manager sequence to start.

RESET – This instruction resets the CPLD sequence and output macrocells.

IN1_RESET_JTAG_BIT – This instruction clears the JTAG Register logic input 'IN1.' The CPLD input has to be configured to take input from the JTAG Register in order for this command to have effect on the sequence.

IN1_SET_JTAG_BIT – This instruction sets the JTAG Register logic input 'IN1.' The CPLD input has to be configured to take input from the JTAG Register in order for this command to have effect on the sequence.

CPLD_VERIFY_INCR – This instruction reads out the CPLD data register for the current address and increments the address register for the next read.

Notes:

In all of the descriptions above, OUTPUTS_HIGHZ refers both to the instruction and the state of the digital output pins, in which the open-drains are tri-stated and the FET drivers are pulled low.

Before any of the above programming instructions are executed, the respective E²CMOS bits need to be erased using the corresponding erase instruction.

FPGA Section Configuration and Testing

The following section describes the configuration and testing features of the FPGA section of the Platform Manager device.

IEEE 1149.1-Compliant Boundary Scan Testability

The FPGA section has boundary scan cells that are accessed through an IEEE 1149.1 compliant test access port (TAP). This allows functional testing of the circuit board, on which the device is mounted, through a serial scan path that can access all critical logic nodes. Internal registers are linked internally, allowing test data to be shifted in and loaded directly onto test nodes, or test data to be captured and shifted out for verification. The test access port consists of dedicated I/Os: PTDI, PTDO, PTCK and PTMS. The test access port shares its power supply with one of the VCCIO2 banks and can operate with LVCMOS3.3 or 2.5.

For more details on boundary scan test, please see information regarding additional technical documentation at the end of this data sheet.

FPGA Section Configuration

The FPGA section contains a test access port that can be used for device configuration and programming.

The non-volatile memory of the FPGA section can be configured in two different modes:

- In IEEE 1532 mode via the IEEE 1149.1 port. In this mode, the device is off-line and I/Os are controlled by BSCAN registers.
- In background mode via the IEEE 1149.1 port. This allows the device to remain operational in user mode while reprogramming takes place.

The SRAM configuration memory can be configured in three different ways:

- At power-up via internal non-volatile memory.
- After a refresh command is issued via the IEEE 1149.1 port.
- In IEEE 1532 mode via the IEEE 1149.1 port.

Figure 57 provides a pictorial representation of the different programming modes available in the FPGA section of the Platform Manager. On power-up, the SRAM is ready to be configured with IEEE 1149.1 serial TAP port using IEEE 1532 protocols.

Leave Alone I/O

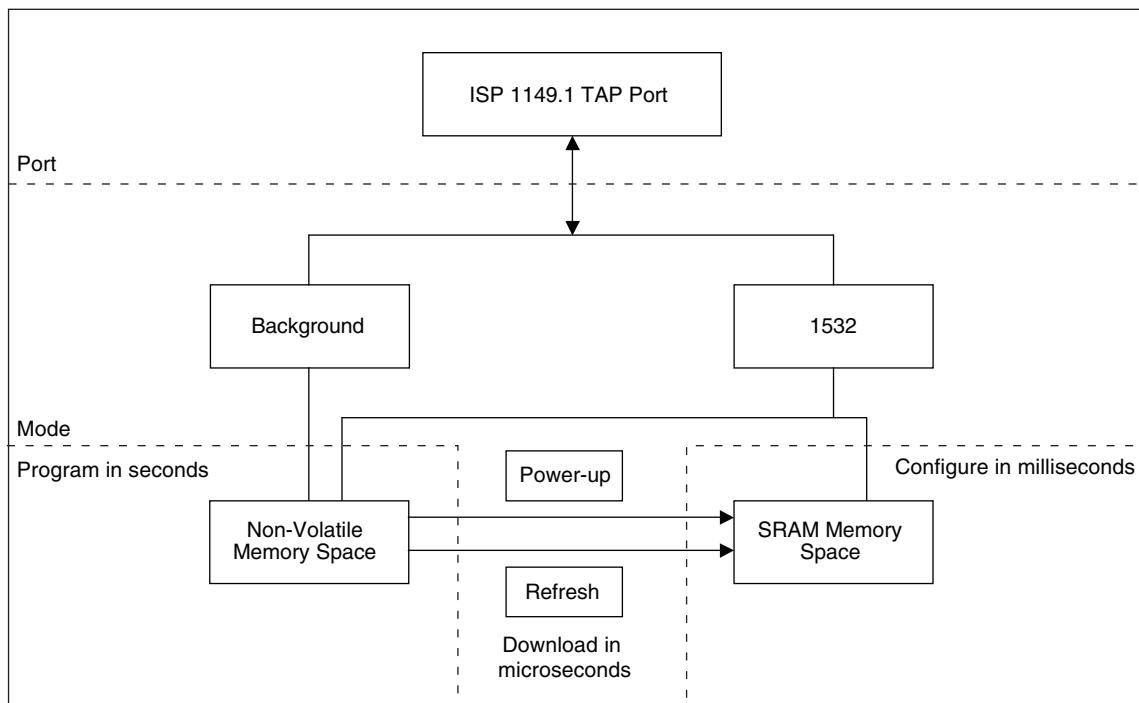
When using IEEE 1532 mode for non-volatile memory programming, SRAM configuration, or issuing a refresh command, users may specify I/Os as high, low, tri-stated or held at current value. This provides excellent flexibility for implementing systems where reconfiguration or reprogramming occurs on-the-fly.

Security

The FPGA section contains security bits that, when set, prevent the readback of the SRAM configuration and non-volatile memory spaces. Once set, the only way to clear the security bits is to erase the memory space.

For more information on device configuration, please see details of additional technical documentation at the end of this data sheet.

Figure 57. FPGA Section Configuration and Programming



Pin Descriptions and Logic Signal Connections

Ball/Pin Function	208-Ball ftBGA	128-Pin TQFP	Bank	Dual Function	Differential
GND	A1, A16, T1, T16	13, 54, 78, 109			
GNDIO0	A4, G8, G9	105, 127	0		
GNDIO1	A13, B13, C13, D13, A8	73, 95	1		
GNDIO2	T4, J10, J9	57, 64	2		
GNDIO3	H1, J8, J7	9, 32	3		
PGND		96, 128			
PGNDA	F14, L14				
PGNDD	E14, K14, D11, D14, J13, N12				
RESERVED	J14	58			
PB2A	R2		2		T
PB2C	T2		2		T
PB2D	T3		2		C
PB3B	P3	39	2		C
PB3C	R3		2		T
PB3D	P4		2		C
PB4A	R4	43	2		T
PB4D	T5		2		C
PB4F	R5		2		C
PB5B	P5	51	2	PCLK2_1 ¹	C
PB5C	P6		2		T
PB5D	N6		2		C
PB6B	R6	53	2	PCLK2_0 ¹	C
PB6C	T6		2		T
PB7A	T7		2		T
PB7B	R7		2		C
PB7C	N7		2		T
PB7E	P7		2		T
PB8A	R8	56	2		T
PB8C	N8		2		T
PB8D	P8		2		C
PB9A	T9		2		T
PB9C	R9		2		T
PB9D	P9		2		C
SLEEPN ²	N9	60	2		
PB9F	N10		2		C
PL10A	P1	24	3		T
PL10B	R1		3		C
PL10C		26	3		T
PL10D	P2		3		C
PL11A	K3	27	3		T
PL11B	L3		3		C
PL11C	M3	28	3		T
PL11D	N3		3		C

Pin Descriptions and Logic Signal Connections (Cont.)

Ball/Pin Function	208-Ball ftBGA	128-Pin TQFP	Bank	Dual Function	Differential
PL2A	F1		3		T
PL2B	F2	3	3		C
PL3A	F3		3		T
PL3B	G2		3		C
PL3D	G3	6	3		C
PL4A	G1		3		T
PL4B		8	3		C
PL4D	H2		3		C
PL5A	G4		3		T
PL5B	H4		3	GSRN	C
PL5C	J1		3		T
PL5D	K1		3		C
PL6A	K2		3		T
PL6D	J2		3		C
PL7A	H3		3		T
PL7B	J3		3		C
PL7D	J4		3		C
PL8A	L1		3		T
PL8C	M1		3	TSALL	T
PL8D	L2		3		C
PL9A		21	3		T
PL9C	M2	23	3		T
PL9D	N2		3		C
PR10A	B9		1		T
PR10C	C9		1		T
PR11A	D9		1		T
PR11C	D10		1		T
PR2B	C6	91	1		C
PR2D	B6	89	1		C
PR3B	B5		1		C
PR3D	A5	87	1		C
PR4B	D7	85	1		C
PR4D	C7		1		C
PR6C	B7		1		T
PR6D	A7		1		C
PR7B	D8		1		C
PR8A	C8		1		T
PR8C	B8		1		T
PR9B	A9		1		C
PT2B	F4	123	0		C
PT2C	E3		0		T
PT2E	E4		0		T
PT2F	E2	121	0		C
PT3B	E1		0		C

Pin Descriptions and Logic Signal Connections (Cont.)

Ball/Pin Function	208-Ball ftBGA	128-Pin TQFP	Bank	Dual Function	Differential
PT3C	D3	119	0		T
PT3E	D2		0		T
PT3F	D1	115	0		C
PT4B	C3		0		C
PT4C	C2		0		T
PT4E	B1		0		T
PT5A	B2		0		T
PT5B	A2	112	0	PCLK0_0 ¹	C
PT6A	D4		0		T
PT6B	D5	110	0	PCLK0_1 ¹	C
PT6C	C4		0		T
PT7A	B3	108	0		T
PT7E	A3	106	0		T
PT8A	B4		0		T
PT8C		104	0		T
PT9A	D6	102	0		T
PT9C		100	0		T
PT9E	C5	98	0		T
FTCK	L4	37			
FTDI	N4	46			
FTDO	M4	44			
FTMS	K4	34			
VCC ³	H8, H9	17, 48, 82, 114			
VCCAUX ³	N5	50, 113			
VCCIO0	G7, H7, C1	97, 125	0		
VCCIO1	G10, H10, A6	66, 93	1		
VCCIO2	K9, T8, K10	33, 62	2		
VCCIO3	K8, N1, K7	1, 30	3		
APS	M14	49			
PVCCA ⁴	H13	76			
PVCCD ⁴	N14, D12, P14	16, 47, 120			
PVCCINP	G14	7			
PVCCJ	N11	41			
CPLDCLK	C11	122			
MCLK	B11	124			
RESETB	C12	116			
RESERVED	H14	75			
SCL	B12	117			
SDA	A12	118			
IN1	A11	126			
IN2	C10	2			
IN3	B10	4			
IN4	A10	5			
HVOUT1	F13	111			

Pin Descriptions and Logic Signal Connections (Cont.)

Ball/Pin Function	208-Ball ftBGA	128-Pin TQFP	Bank	Dual Function	Differential
HVOUT2	E13	107			
HVOUT3	L13	55			
HVOUT4	K13	52			
SMBA_OUT5	G13	10			
OUT6	T10	11			
OUT7	R10	12			
OUT8	T11	14			
OUT9	T12	19			
OUT10	R11	20			
OUT11	R12	15			
OUT12	P10	18			
OUT13	T13	22			
OUT14	P11	25			
OUT15	T14	29			
OUT16	R13	31			
PATDI ^{5,8}	R14	36			
PTCK	M13	45			
PTDI ^{6,8}	P13	38			
PTDISEL ^{7,8}	T15	40			
PTDO	N13	42			
PTMS	P12	35			
TRIM1	A14				
TRIM2	A15				
TRIM3	B14	103			
TRIM4	B15	101			
TRIM5	B16	99			
TRIM6	C14	94			
TRIM7	C15	92			
TRIM8	C16	90			
VMON1GS	R15				
VMON1	R16	59			
VMON2GS	P15	61			
VMON2	P16	63			
VMON3GS	N15	65			
VMON3	N16	67			
VMON4GS	M15	68			
VMON4	M16	69			
VMON5GS	L15	70			
VMON5	L16	71			
VMON6GS	K15	72			
VMON6	K16	74			
VMON7GS	J15	77			
VMON7	J16	79			
VMON8GS	H15	80			

Pin Descriptions and Logic Signal Connections (Cont.)

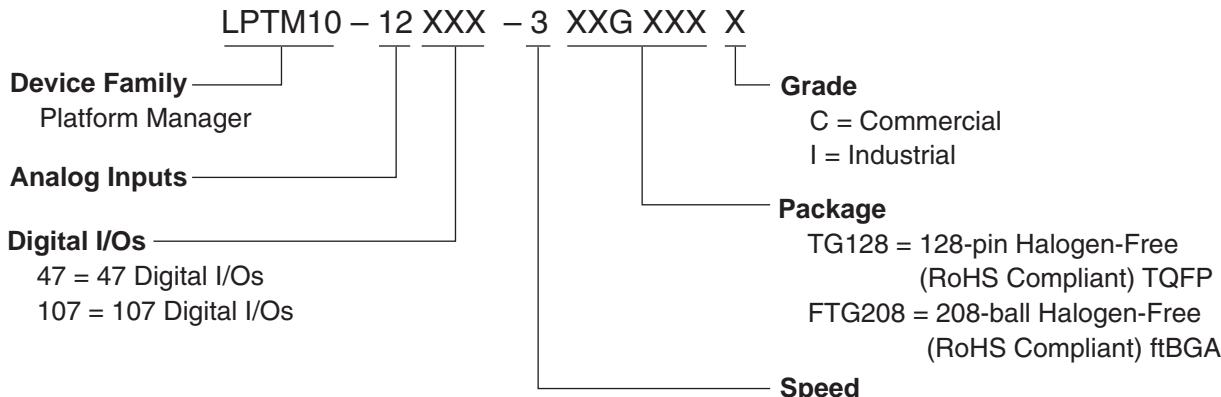
Ball/Pin Function	208-Ball ftBGA	128-Pin TQFP	Bank	Dual Function	Differential
VMON8	H16	81			
VMON9GS	G15				
VMON9	G16	83			
VMON10GS	F15				
VMON10	F16	84			
VMON11GS	E15				
VMON11	E16	86			
VMON12GS	D15				
VMON12	D16	88			

1. Primary clock inputs are single-ended.
2. Ensure that SLEEPN is tied to VCC via an external pull-up when the function will not be used or the Platform Manager FPGA section will not function correctly.
3. VCC and VCCAUX pins must be physically tied together for proper device operation.
4. PVCCA and PVCCD pins must be physically tied together for proper device operation.
5. PTDI pin is the alternate JTAG Test Data In, PTDISEL Pin = 0.
6. PTDI pin is the main JTAG Test Data In, PTDISEL Pin = 1.
7. This pin selects the JTAG Test Data Input pin PTDI/PATDI.
8. This pin has an internal pull-up.

Thermal Management

Thermal management is recommended as part of any sound FPGA design methodology. To assess the thermal characteristics of a system, Lattice specifies a maximum allowable junction temperature in all device data sheets. Designers must complete a thermal analysis of their specific design to ensure that the device and package do not exceed the junction temperature limits. Refer to the [Thermal Management](#) document to find the device/package specific thermal values.

Part Number Description



Ordering Information

Halogen-Free (RoHS Compliant) Packaging

Part Number	Package	Pins/Balls	Temp.
LPTM10-1247-3TG128C	TQFP	128	COM
LPTM10-1247-3TG128I	TQFP	128	IND
LPTM10-12107-3FTG208C	ftBGA	208	COM
LPTM10-12107-3FTG208I	ftBGA	208	IND

For Further Information

For further information, refer to the following MachXO-specific literature which also applies to Platform Manager:

- TN1086, [MachXO JTAG Programming and Configuration User's Guide](#)
- TN1090, [Power Estimation and Management for MachXO™ Devices](#)
- TN1091, [MachXO sysIO Usage Guide](#)
 - Power Calculator tool included with the Platform Manager design tools, or as a standalone download from www.latticesemi.com/software
- TN1223, Using Platform Manager Successfully
 - Guidelines for practical circuits using Platform Manager

Technical Support Assistance

Hotline: 1-800-LATTICE (North America)
 +1-503-268-8001 (Outside North America)
 e-mail: isppacs@latticesemi.com
 Internet: www.latticesemi.com

Revision History

Date	Version	Change Summary
October 2010	01.0	Initial release.
December 2010	01.1	Typographical changes and clarifications.
February 2012	01.2	Added footnotes 5-8 to Pin Descriptions and Logic Signal Connections table.
February 2012	01.3	Updated document with new corporate logo.